

# MPC5777C

## MPC5777C Microcontroller Data Sheet

### Features

- This document provides electrical specifications, pin assignments, and package diagram information for the MPC5777C series of microcontroller units (MCUs).
- For functional characteristics and the programming model, see the MPC5777C Reference Manual.

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# 1 Introduction

## 1.1 Features summary

On-chip modules available within the family include the following features:

- Three dual issue, 32-bit CPU core complexes (e200z7), two of which run in lockstep
  - Power Architecture embedded specification compliance
  - Instruction set enhancement allowing variable length encoding (VLE), optional encoding of mixed 16-bit and 32-bit instructions, for code size footprint reduction
  - On the two computational cores: Signal processing extension (SPE1.1) instruction support for digital signal processing (DSP)
  - Single-precision floating point operations
  - On the two computational cores: 16 KB I-Cache and 16 KB D-Cache
  - Hardware cache coherency between cores
- 16 hardware semaphores
- 3-channel CRC module
- 8 MB on-chip flash memory
  - Supports read during program and erase operations, and multiple blocks allowing EEPROM emulation
- 512 KB on-chip general-purpose SRAM including 64 KB standby RAM
- Two multichannel direct memory access controllers (eDMA)
  - 64 channels per eDMA
- Dual core Interrupt Controller (INTC)
- Dual phase-locked loops (PLLs) with stable clock domain for peripherals and frequency modulation (FM) domain for computational shell
- Crossbar Switch architecture for concurrent access to peripherals, flash memory, or RAM from multiple bus masters with End-To-End ECC
- External Bus Interface (EBI) for calibration and application use
- System Integration Unit (SIU)
- Error Injection Module (EIM) and Error Reporting Module (ERM)
- Four protected port output (PPO) pins
- Boot Assist Module (BAM) supports serial bootload via CAN or SCI
- Three second-generation Enhanced Time Processor Units (eTPUs)
  - 32 channels per eTPU
  - Total of 36 KB code RAM
  - Total of 9 KB parameter RAM

- Enhanced Modular Input/Output System (eMIOS) supporting 32 unified channels with each channel capable of single action, double action, pulse width modulation (PWM) and modulus counter operation
- Two Enhanced Queued Analog-to-Digital Converter (eQADC) modules with:
  - Two separate analog converters per eQADC module
  - Support for a total of 70 analog input pins, expandable to 182 inputs with off-chip multiplexers
  - Interface to twelve hardware Decimation Filters
  - Enhanced "Tap" command to route any conversion to two separate Decimation Filters
- Four independent 16-bit Sigma-Delta ADCs (SDADCs)
- 10-channel Reaction Module
- Ethernet (FEC)
- Two PSI5 modules
- Two SENT Receiver (SRX) modules supporting 12 channels
- Zipwire: SIPI and LFAST modules
- Five Deserial Serial Peripheral Interface (DSPI) modules
- Five Enhanced Serial Communication Interface (eSCI) modules
- Four Controller Area Network (FlexCAN) modules
- Two M\_CAN modules that support FD
- Fault Collection and Control Unit (FCCU)
- Clock Monitor Units (CMUs)
- Tamper Detection Module (TDM)
- Cryptographic Services Engine (CSE)
  - Complies with *Secure Hardware Extension (SHE) Functional Specification Version 1.1* security functions
  - Includes software selectable enhancement to key usage flag for MAC verification and increase in number of memory slots for security keys
- PASS module to support security features
- Nexus development interface (NDI) per IEEE-ISTO 5001-2003 standard, with some support for 2010 standard
- Device and board test support per Joint Test Action Group (JTAG) IEEE 1149.1 and 1149.7
- On-chip voltage regulator controller (VRC) that derives the core logic supply voltage from the high-voltage supply
- On-chip voltage regulator for flash memory
- Self Test capability

## 1.2 Block diagram

The following figure shows a top-level block diagram of the MPC5777C. The purpose of the block diagram is to show the general interconnection of functional modules through the crossbar switch.

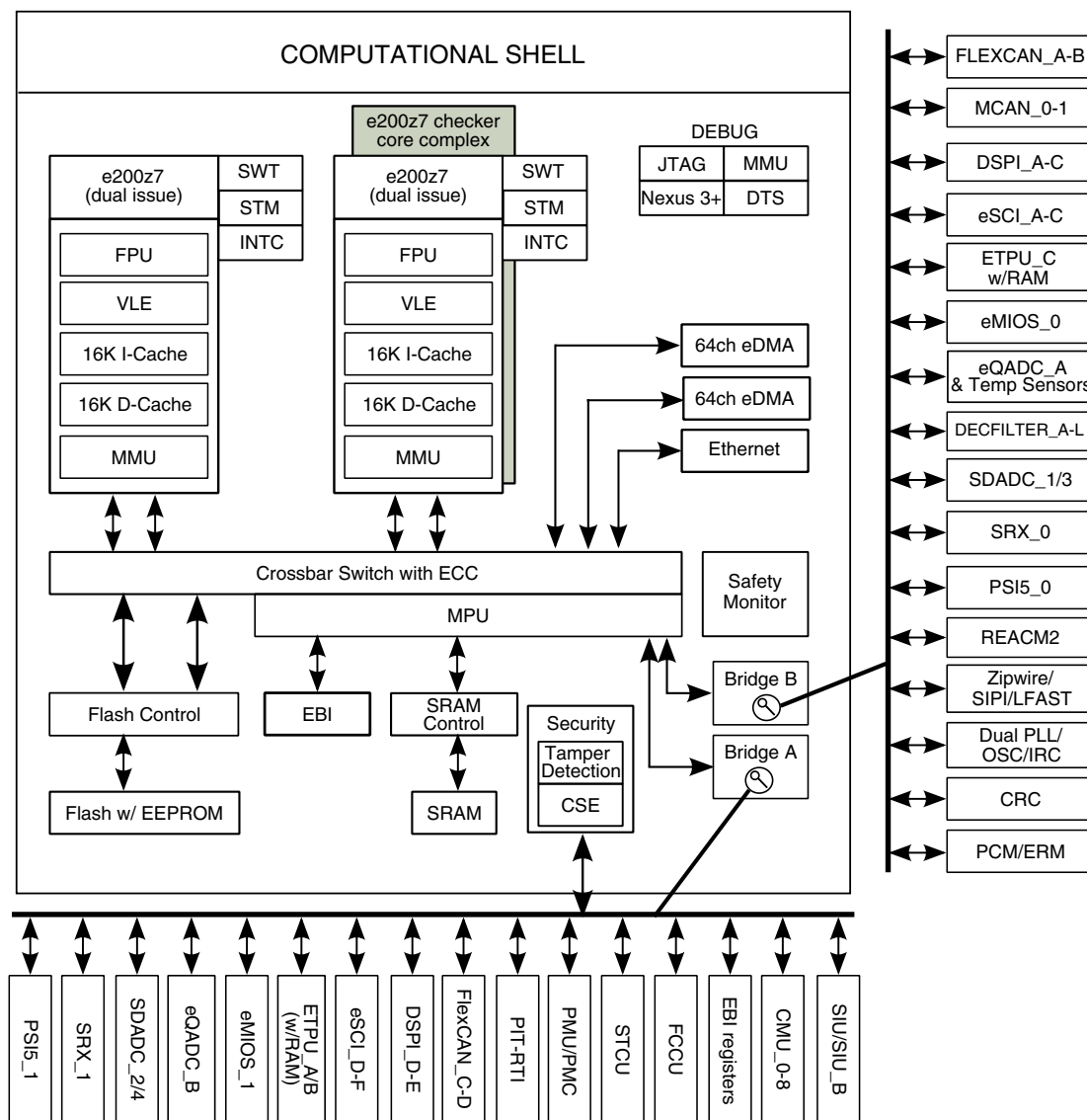


Figure 1. MPC5777C block diagram

## 2 Pinouts

### 2.1 416-ball MAPBGA pin assignments

Figure 2 shows the 416-ball MAPBGA pin assignments.

Pinouts

|    | 1       | 2        | 3        | 4         | 5               | 6         | 7     | 8     | 9          | 10         | 11         | 12         | 13      | 14      | 15      | 16      | 17         | 18         | 19        | 20        | 21     | 22     | 23      | 24      | 25      | 26      |    |
|----|---------|----------|----------|-----------|-----------------|-----------|-------|-------|------------|------------|------------|------------|---------|---------|---------|---------|------------|------------|-----------|-----------|--------|--------|---------|---------|---------|---------|----|
| A  | VSS     | VDD      | RSTOUT   | ANAO_SDA0 | ANA4            | ANA8      | ANA11 | ANA15 | VDDA_SD    | REFBYPCA25 | VRL_SD     | VRH_SD     | AN28    | AN32    | AN36    | VDDA_EQ | REFBYPCB25 | VRL_EQ     | VRH_EQ    | ANB7_SDD7 | ANB11  | ANB14  | ANB17   | ANB21   | ANB23   | VSS     | A  |
| B  | VDDEH1  | VSS      | VDD      | TEST      | ANA1_SDA1       | ANA5      | ANA10 | ANA14 | VDDA_MISC  | VSSA_SD    | REFBYPCA75 | AN24       | AN27    | AN29    | AN33    | VDDA_EQ | VSSA_EQ    | REFBYPCB75 | ANB6_SDD6 | ANB8      | ANB10  | ANB15  | ANB18   | ANB22   | VSS     | TCRCLKC | B  |
| C  | ETPUA30 | ETPUA31  | VSS      | VDD       | ANA2_SDA2       | ANA6      | ANA9  | ANA13 | ANA17_SDB1 | ANA19_SDB3 | ANA21_SDC1 | ANA23_SDC3 | AN26    | AN30    | AN34    | AN37    | AN38       | ANB0_SDD0  | ANB4_SDD4 | ANB5_SDD5 | ANB12  | ANB16  | ANB19   | VSS     | ETPUC0  | ETPUC1  | C  |
| D  | ETPUA27 | ETPUA28  | ETPUA29  | VSS       | VDD             | ANA3_SDA3 | ANA7  | ANA12 | ANA16_SDB0 | ANA18_SDB2 | ANA20_SDC0 | ANA22_SDC2 | AN25    | AN31    | AN35    | AN39    | ANB1_SDD1  | ANB2_SDD2  | ANB3_SDD3 | ANB9      | ANB13  | ANB20  | VSS     | SEN72_A | ETPUC2  | ETPUC3  | D  |
| E  | ETPUA23 | ETPUA24  | ETPUA25  | ETPUA26   |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | VDDEH7  | ETPUC4  | ETPUC5  | ETPUC6  | E  |
| F  | ETPUA19 | ETPUA20  | ETPUA21  | ETPUA22   |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | ETPUC7  | ETPUC8  | ETPUC9  | ETPUC10 | F  |
| G  | ETPUA15 | ETPUA16  | ETPUA17  | ETPUA18   |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | ETPUC11 | ETPUC12 | ETPUC13 | ETPUC14 | G  |
| H  | ETPUA11 | ETPUA12  | ETPUA14  | ETPUA13   |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | ETPUC15 | ETPUC16 | ETPUC17 | ETPUC18 | H  |
| J  | ETPUA7  | ETPUA8   | ETPUA9   | ETPUA10   |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | ETPUC19 | ETPUC20 | ETPUC21 | ETPUC22 | J  |
| K  | ETPUA3  | ETPUA4   | ETPUA5   | ETPUA6    |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | ETPUC23 | ETPUC24 | ETPUC25 | ETPUC26 | K  |
| L  | TCRCLKA | ETPUA0   | ETPUA1   | ETPUA2    |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | ETPUC27 | ETPUC28 | ETPUC29 | ETPUC30 | L  |
| M  | NC      | TXDA     | RXDA     | VSTBY     |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | ETPUC31 | ETPU815 | ETPU814 | VDDEH7  | M  |
| N  | RXDB    | BOOTCFG1 | WKPCFG   | VDD       |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | VDDEH6  | ETPU811 | ETPU812 | ETPU813 | N  |
| P  | TXDB    | PLLCFG1  | PLLCFG2  | VDDEH1    |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | ETPU87  | ETPU88  | ETPU89  | ETPU810 | P  |
| R  | JCOMP   | RESET    | PLLCFG0  | RDY       |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | ETPU83  | ETPU84  | ETPU85  | ETPU86  | R  |
| T  | VDDE2   | MCKO     | MSE01    | EVTI      |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | TCRCLK8 | ETPU80  | ETPU81  | ETPU82  | T  |
| U  | EVT0    | MSE00    | MDO0     | MDO1      |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | ETPU819 | ETPU818 | ETPU817 | ETPU816 | U  |
| V  | MDO2    | MDO3     | MDO4     | MDO5      |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | ETPU826 | ETPU822 | ETPU821 | ETPU820 | V  |
| W  | MDO6    | MDO7     | MDO8     | VDDE2     |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | REGSEL  | ETPU825 | ETPU824 | ETPU823 | W  |
| Y  | MDO9    | MDO10    | MDO11    | MDO15     |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | ETPU829 | ETPU828 | ETPU827 | REGCTL  | Y  |
| AA | MDO12   | MDO13    | MDO14    | NC        |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | VDOPMC  | ETPU830 | VDOPWR  | VSS5YN  | AA |
| AB | TDO     | TCK      | TMS      | VDD       |                 |           |       |       |            |            |            |            |         |         |         |         |            |            |           |           |        |        | VDD     | ETPU831 | VSSPWR  | EXTAL   | AB |
| AC | VDDE2   | TDI      | VDD      | VSS       | FEC_TXCLKREFCLK | PCSA1     | PCSA2 | PCSB4 | PCSB1      | VDDEH3     | VDDEH4     | VDD        | EMIOS8  | EMIOS14 | EMIOS18 | EMIOS22 | EMIOS27    | EMIOS31    | CNRX8     | CNRXD     | VDDEH5 | PCSC1  | VSSPMC  | VDD     | VDDEH6  | XTAL    | AC |
| AD | ENGCLK  | VDD      | VSS      | FEC_TXD0  | FEC_TXD1        | PCSA5     | SOUTA | SCKA  | PCSB0      | PCSB3      | EMIOS2     | EMIOS5     | EMIOS9  | EMIOS15 | EMIOS19 | EMIOS23 | EMIOS26    | EMIOS30    | CNTX8     | CNTXD     | SCKC   | RXDC   | PCSC3   | VSS     | VDD     | VDDFLA  | AD |
| AE | VDD     | VSS      | FEC_RXDV | FEC_TX_EN | PCSA4           | PCSA0     | PCSA3 | SCKB  | SINB       | EMIOS0     | EMIOS3     | EMIOS6     | EMIOS10 | EMIOS13 | EMIOS17 | EMIOS21 | EMIOS25    | EMIOS29    | CNRXA     | CNRXC     | PCSC0  | SINC   | PCSC2   | PCSC5   | VSS     | VDD     | AE |
| AF | VSS     | VDDE2A   | FEC_RXD0 | FEC_RXD1  | VDDEH3A         | PCSB5     | SINA  | PCSB2 | SOUTB      | EMIOS1     | EMIOS4     | EMIOS7     | EMIOS11 | EMIOS12 | EMIOS16 | EMIOS20 | EMIOS24    | EMIOS28    | CNTXA     | CNTXC     | SOUTC  | VDDEH4 | TXDC    | PCSC4   | VDDEH5  | VSS     | AF |
|    | 1       | 2        | 3        | 4         | 5               | 6         | 7     | 8     | 9          | 10         | 11         | 12         | 13      | 14      | 15      | 16      | 17         | 18         | 19        | 20        | 21     | 22     | 23      | 24      | 25      | 26      |    |

Figure 2. MPC5777C 416-ball MAPBGA (full diagram)

2.2 516-ball MAPBGA pin assignments

Figure 3 shows the 516-ball MAPBGA pin assignments.

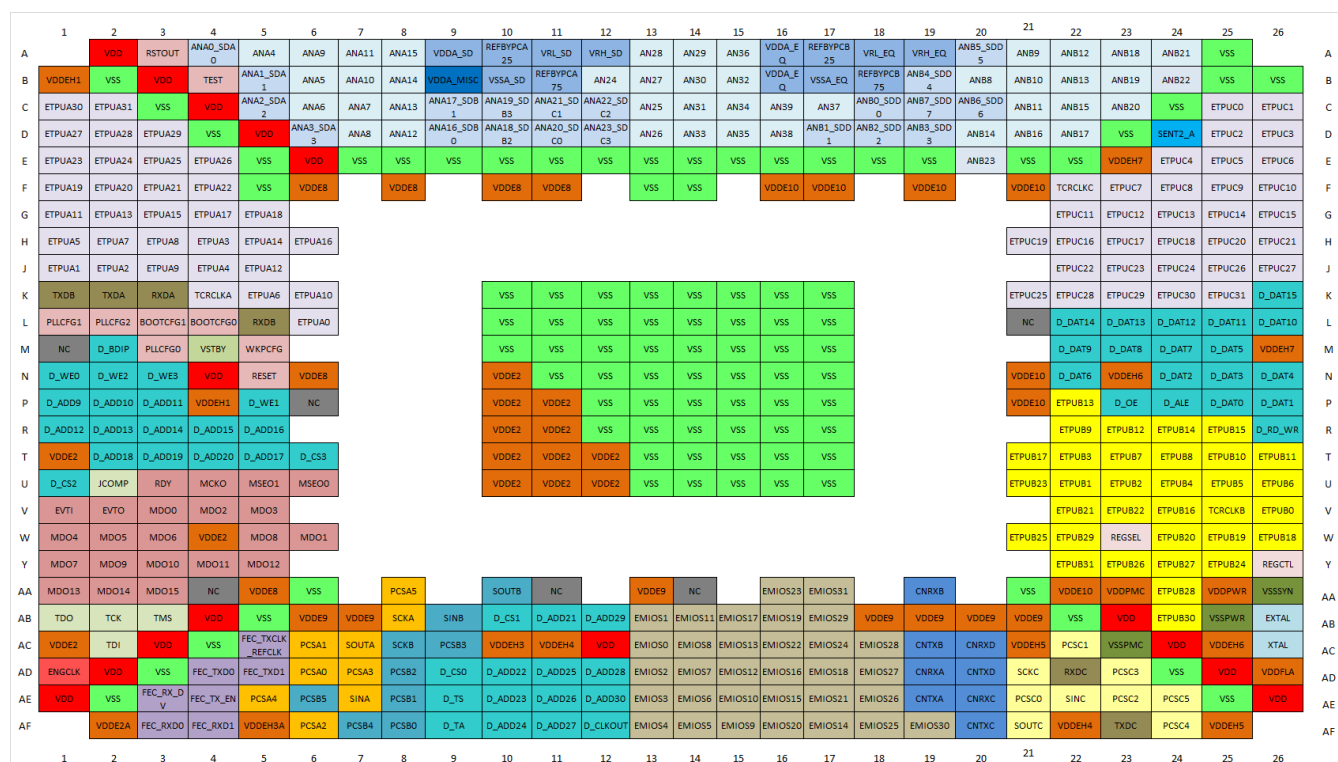


Figure 3. MPC5777C 516-ball MAPBGA (full diagram)

### 3 Electrical characteristics

The following information includes details about power considerations, DC/AC electrical characteristics, and AC timing specifications.

#### 3.1 Absolute maximum ratings

Absolute maximum specifications are stress ratings only. Functional operation at these maxima is not guaranteed.

#### CAUTION

Stress beyond listed maxima may affect device reliability or cause permanent damage to the device.

See [Operating conditions](#) for functional operation specifications.

Table 1. Absolute maximum ratings

| Symbol                                | Parameter                                                   | Conditions <sup>1</sup>                                 | Value |       | Unit  |
|---------------------------------------|-------------------------------------------------------------|---------------------------------------------------------|-------|-------|-------|
|                                       |                                                             |                                                         | Min   | Max   |       |
| Cycle                                 | Lifetime power cycles                                       | —                                                       | —     | 1000k | —     |
| V <sub>DD</sub>                       | 1.2 V core supply voltage <sup>2, 3, 4</sup>                | —                                                       | −0.3  | 1.5   | V     |
| V <sub>DDEHx</sub>                    | I/O supply voltage (medium I/O pads) <sup>5</sup>           | —                                                       | −0.3  | 6.0   | V     |
| V <sub>DDEx</sub>                     | I/O supply voltage (fast I/O pads) <sup>5</sup>             | —                                                       | −0.3  | 6.0   | V     |
| V <sub>DDPMC</sub>                    | Power Management Controller supply voltage <sup>5</sup>     | —                                                       | −0.3  | 6.0   | V     |
| V <sub>DDFLA</sub>                    | Decoupling pin for flash regulator <sup>6</sup>             | —                                                       | −0.3  | 4.5   | V     |
| V <sub>STBY</sub>                     | RAM standby supply voltage <sup>5</sup>                     | —                                                       | −0.3  | 6.0   | V     |
| V <sub>SSA_SD</sub>                   | SDADC ground voltage                                        | Reference to V <sub>SS</sub>                            | −0.3  | 0.3   | V     |
| V <sub>SSA_EQ</sub>                   | eQADC ground voltage                                        | Reference to V <sub>SS</sub>                            | −0.3  | 0.3   | V     |
| V <sub>DDA_EQA/B</sub>                | eQADC supply voltage                                        | Reference to V <sub>SSA_EQ</sub>                        | −0.3  | 6.0   | V     |
| V <sub>DDA_SD</sub>                   | SDADC supply voltage                                        | Reference to V <sub>SSA_SD</sub>                        | −0.3  | 6.0   | V     |
| V <sub>RL_SD</sub>                    | SDADC ground reference                                      | Reference to V <sub>SS</sub>                            | −0.3  | 0.3   | V     |
| V <sub>RL_EQ</sub>                    | eQADC ground reference                                      | Reference to V <sub>SS</sub>                            | −0.3  | 0.3   | V     |
| V <sub>RH_EQ</sub>                    | eQADC alternate reference                                   | Reference to V <sub>RL_EQ</sub>                         | −0.3  | 6.0   | V     |
| V <sub>RH_SD</sub>                    | SDADC alternate reference                                   | Reference to V <sub>RL_SD</sub>                         | −0.3  | 6.0   | V     |
| V <sub>REFBYPC</sub>                  | eQADC reference decoupling capacitor pins                   | REFBYPCA25, REFBYPCA75, REFBYPCB25, REFBYPC75           | −0.3  | 6.0   | V     |
| V <sub>DDA_MISC</sub>                 | TRNG and IRC supply voltage                                 | —                                                       | −0.3  | 6.0   | V     |
| V <sub>DDPWR</sub>                    | SMPS driver supply pin                                      | —                                                       | −0.3  | 6.0   | V     |
| V <sub>SSPWR</sub>                    | SMPS driver supply pin                                      | Reference to V <sub>SS</sub>                            | −0.3  | 0.3   | V     |
| V <sub>SS</sub> − V <sub>SSA_EQ</sub> | V <sub>SSA_EQ</sub> differential voltage                    | —                                                       | −0.3  | 0.3   | V     |
| V <sub>SS</sub> − V <sub>SSA_SD</sub> | V <sub>SSA_SD</sub> differential voltage                    | —                                                       | −0.3  | 0.3   | V     |
| V <sub>SS</sub> − V <sub>RL_EQ</sub>  | V <sub>RL_EQ</sub> differential voltage                     | —                                                       | −0.3  | 0.3   | V     |
| V <sub>SS</sub> − V <sub>RL_SD</sub>  | V <sub>RL_SD</sub> differential voltage                     | —                                                       | −0.3  | 0.3   | V     |
| V <sub>IN</sub>                       | I/O input voltage range <sup>7</sup>                        | —                                                       | −0.3  | 6.0   | V     |
|                                       |                                                             | Relative to V <sub>DDEx</sub> /V <sub>DDEHx</sub>       | —     | 0.3   | V     |
|                                       |                                                             | Relative to V <sub>SS</sub>                             | −0.3  | —     | V     |
| I <sub>INJD</sub>                     | Maximum DC injection current for digital pad                | Per pin, applies to all digital pins                    | −5    | 5     | mA    |
| I <sub>INJA</sub>                     | Maximum DC injection current for analog pad                 | Per pin, applies to all analog pins                     | −5    | 5     | mA    |
| I <sub>MAXSEG</sub> <sup>8, 9</sup>   | Maximum current per I/O power segment                       | —                                                       | −120  | 120   | mA    |
| T <sub>STG</sub>                      | Storage temperature range and non-operating times           | —                                                       | −55   | 175   | °C    |
| STORAGE                               | Maximum storage time, assembled part programmed in ECU      | No supply; storage temperature in range −40 °C to 60 °C | —     | 20    | years |
| T <sub>SDR</sub>                      | Maximum solder temperature <sup>10</sup><br>Pb-free package | —                                                       | —     | 260   | °C    |

Table continues on the next page...

**Table 1. Absolute maximum ratings (continued)**

| Symbol | Parameter                                | Conditions <sup>1</sup> | Value |     | Unit |
|--------|------------------------------------------|-------------------------|-------|-----|------|
|        |                                          |                         | Min   | Max |      |
| MSL    | Moisture sensitivity level <sup>11</sup> | —                       | —     | 3   | —    |

1. Voltages are referred to  $V_{SS}$  if not specified otherwise
2. Allowed 1.45 V – 1.5 V for 60 seconds cumulative time at maximum  $T_J = 150\text{ }^{\circ}\text{C}$ ; remaining time as defined in note 3 and note 4
3. Allowed 1.375 V – 1.45 V for 10 hours cumulative time at maximum  $T_J = 150\text{ }^{\circ}\text{C}$ ; remaining time as defined in note 4
4. 1.32 V – 1.375 V range allowed periodically for supply with sinusoidal shape and average supply value below 1.275 V at maximum  $T_J = 150\text{ }^{\circ}\text{C}$
5. Allowed 5.5 V – 6.0 V for 60 seconds cumulative time with no restrictions, for 10 hours cumulative time device in reset,  $T_J = 150\text{ }^{\circ}\text{C}$ ; remaining time at or below 5.5 V
6. Allowed 3.6 V – 4.5 V for 60 seconds cumulative time with no restrictions, for 10 hours cumulative time device in reset,  $T_J = 150\text{ }^{\circ}\text{C}$ ; remaining time at or below 3.6 V
7. The maximum input voltage on an I/O pin tracks with the associated I/P supply maximum. For the injection current condition on a pin, the voltage will be equal to the supply plus the voltage drop across the internal ESD diode from I/O pin to supply. The diode voltage varies greatly across process and temperature, but a value of 0.3V can be used for nominal calculations.
8. The sum of all controller pins (including both digital and analog) must not exceed 200 mA. A  $V_{DDEX}/V_{DDEHx}$  power segment is defined as one or more GPIO pins located between two  $V_{DDEX}/V_{DDEHx}$  supply pins.
9. The average current values given in [I/O pad current specifications](#) should be used to calculate total I/O segment current.
10. Solder profile per IPC/JEDEC J-STD-020D
11. Moisture sensitivity per JEDEC test method A112

## 3.2 Electromagnetic interference (EMI) characteristics

Test reports with EMC measurements to IC-level IEC standards are available on request.

To find application notes that provide guidance on designing your system to minimize interference from radiated emissions, go to [nxp.com](http://nxp.com) and perform a keyword search for "radiated emissions."

## 3.3 Electrostatic discharge (ESD) characteristics

**Table 2. ESD Ratings<sup>1, 2</sup>**

| Symbol    | Parameter                          | Conditions      | Value | Unit |
|-----------|------------------------------------|-----------------|-------|------|
| $V_{HBM}$ | ESD for Human Body Model (HBM)     | All pins        | 2000  | V    |
| $V_{CDM}$ | ESD for Charged Device Model (CDM) | Corner pins     | 750   | V    |
|           |                                    | Non-corner pins | 500   |      |

1. All ESD testing is in conformity with CDF-AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits.
2. A device will be defined as a failure if after exposure to ESD pulses the device no longer meets the device specification requirements.

### 3.4 Operating conditions

The following table describes the operating conditions for the device, and for which all specifications in the data sheet are valid, except where explicitly noted.

If the device operating conditions are exceeded, the functionality of the device is not guaranteed.

**Table 3. Device operating conditions**

| Symbol                                             | Parameter                                                                      | Conditions                               | Value              |     |                      | Unit |
|----------------------------------------------------|--------------------------------------------------------------------------------|------------------------------------------|--------------------|-----|----------------------|------|
|                                                    |                                                                                |                                          | Min                | Typ | Max                  |      |
| Frequency                                          |                                                                                |                                          |                    |     |                      |      |
| f <sub>SYS</sub>                                   | Device operating frequency <sup>1</sup>                                        | —                                        | —                  | —   | 264/300 <sup>2</sup> | MHz  |
| f <sub>PLATF</sub>                                 | Platform operating frequency                                                   | —                                        | —                  | —   | 132/150 <sup>3</sup> | MHz  |
| f <sub>ETPU</sub>                                  | eTPU operating frequency                                                       | —                                        | —                  | —   | 200/240 <sup>4</sup> | MHz  |
| f <sub>EBI</sub>                                   | EBI operating frequency                                                        | —                                        | —                  | —   | 66                   | MHz  |
| f <sub>PER</sub>                                   | Peripheral block operating frequency                                           | —                                        | —                  | —   | 132/150 <sup>3</sup> | MHz  |
| f <sub>FM_PER</sub>                                | Frequency-modulated peripheral block operating frequency                       | —                                        | —                  | —   | 132/150 <sup>3</sup> | MHz  |
| t <sub>CYC</sub>                                   | Platform clock period                                                          | —                                        | —                  | —   | 1/f <sub>PLATF</sub> | ns   |
| t <sub>CYC_ETPU</sub>                              | eTPU clock period                                                              | —                                        | —                  | —   | 1/f <sub>ETPU</sub>  | ns   |
| t <sub>CYC_PER</sub>                               | Peripheral clock period                                                        | —                                        | —                  | —   | 1/f <sub>PER</sub>   | ns   |
| Temperature                                        |                                                                                |                                          |                    |     |                      |      |
| T <sub>J</sub>                                     | Junction operating temperature range                                           | Packaged devices                         | −40.0              | —   | 150.0                | °C   |
| T <sub>A</sub> (T <sub>L</sub> to T <sub>H</sub> ) | Ambient operating temperature range                                            | Packaged devices                         | −40.0              | —   | 125.0 <sup>5</sup>   | °C   |
| Voltage                                            |                                                                                |                                          |                    |     |                      |      |
| V <sub>DD</sub>                                    | External core supply voltage <sup>6, 7</sup>                                   | LVD/HVD enabled                          | 1.2                | —   | 1.32                 | V    |
|                                                    |                                                                                | LVD/HVD disabled <sup>8, 9, 10, 11</sup> | 1.2                | —   | 1.38                 |      |
| V <sub>DDA_MISC</sub>                              | TRNG and IRC supply voltage                                                    | —                                        | 3.5                | —   | 5.5                  | V    |
| V <sub>DDEx</sub>                                  | I/O supply voltage (fast I/O pads)                                             | 5 V range                                | 4.5                | —   | 5.5                  | V    |
|                                                    |                                                                                | 3.3 V range                              | 3.0                | —   | 3.6                  |      |
| V <sub>DDEHx</sub> <sup>11</sup>                   | I/O supply voltage (medium I/O pads)                                           | 5 V range                                | 4.5                | —   | 5.5                  | V    |
|                                                    |                                                                                | 3.3 V range                              | 3.0                | —   | 3.6                  |      |
| V <sub>DDEH1</sub>                                 | eTPU_A, eSCI_A, eSCI_B, and configuration I/O supply voltage (medium I/O pads) | 5 V range                                | 4.5                | —   | 5.5                  | V    |
| V <sub>DDPMC</sub> <sup>12</sup>                   | Power Management Controller (PMC) supply voltage                               | Full functionality                       | 3.15               | —   | 5.5                  | V    |
| V <sub>DDPWR</sub>                                 | SMPS driver supply voltage                                                     | Reference to V <sub>SSPWR</sub>          | 3.0                | —   | 5.5                  | V    |
| V <sub>DDFLA</sub>                                 | Flash core voltage                                                             | —                                        | 3.15               | —   | 3.6                  | V    |
| V <sub>STBY</sub>                                  | RAM standby supply voltage                                                     | —                                        | 0.95 <sup>13</sup> | —   | 5.5                  | V    |

Table continues on the next page...

**Table 3. Device operating conditions (continued)**

| Symbol                        | Parameter                                            | Conditions                   | Value         |               |                   | Unit |
|-------------------------------|------------------------------------------------------|------------------------------|---------------|---------------|-------------------|------|
|                               |                                                      |                              | Min           | Typ           | Max               |      |
| $V_{STBY\_BO}$                | Standby RAM brownout flag trip point voltage         | —                            | —             | —             | 0.9 <sup>14</sup> | V    |
| $V_{RL\_SD}$                  | SDADC ground reference voltage                       | —                            | $V_{SSA\_SD}$ |               |                   | V    |
| $V_{DDA\_SD}$                 | SDADC supply voltage <sup>15</sup>                   | —                            | 4.5           | —             | 5.5               | V    |
| $V_{DDA\_EQA/B}$              | eQADC supply voltage                                 | —                            | 4.75          | —             | 5.25              | V    |
| $V_{RH\_SD}$                  | SDADC reference                                      | —                            | 4.5           | $V_{DDA\_SD}$ | 5.5               | V    |
| $V_{DDA\_SD} - V_{RH\_SD}$    | SDADC reference differential voltage                 | —                            | —             | —             | 25                | mV   |
| $V_{SSA\_SD} - V_{RL\_SD}$    | $V_{RL\_SD}$ differential voltage                    | —                            | –25           | —             | 25                | mV   |
| $V_{RH\_EQ}$                  | eQADC reference                                      | —                            | 4.75          | —             | 5.25              | V    |
| $V_{DDA\_EQA/B} - V_{RH\_EQ}$ | eQADC reference differential voltage                 | —                            | —             | —             | 25                | mV   |
| $V_{SSA\_EQ} - V_{RL\_EQ}$    | $V_{RL\_EQ}$ differential voltage                    | —                            | –25           | —             | 25                | mV   |
| $V_{SSA\_EQ} - V_{SS}$        | $V_{SSA\_EQ}$ differential voltage                   | —                            | –25           | —             | 25                | mV   |
| $V_{SSA\_SD} - V_{SS}$        | $V_{SSA\_SD}$ differential voltage                   | —                            | –25           | —             | 25                | mV   |
| $V_{RAMP}$                    | Slew rate on power supply pins                       | —                            | —             | —             | 100               | V/ms |
| <b>Current</b>                |                                                      |                              |               |               |                   |      |
| $I_{IC}$                      | DC injection current (per pin) <sup>16, 17, 18</sup> | Digital pins and analog pins | –3.0          | —             | 3.0               | mA   |
| $I_{MAXSEG}$                  | Maximum current per power segment <sup>19, 20</sup>  | —                            | –80           | —             | 80                | mA   |

- Maximum operating frequency is applicable to the computational cores and platform for the device. See the Clocking chapter in the MPC5777C Microcontroller Reference Manual for more information on the clock limitations for the various IP blocks on the device.
- If frequency modulation (FM) is enabled for the operating frequency of 264MHz, the maximum frequency still cannot exceed this value (frequency modulation must spread below nominal frequency). If frequency modulation is enabled for the operating frequency of 300MHz, this maximum frequency can be exceeded (frequency modulation can be center spread from 300MHz).
- 132 MHz applies to the MPC5777C part number with 264 MHz operating frequency. 150 MHz applies to the version with 300 MHz operating frequency.
- 200 MHz applies to the MPC5777C part number with 264 MHz max operating frequency. 240 MHz applies to the version with 300 MHz operating frequency.
- The maximum specification for operating junction temperature  $T_J$  must be respected. [Thermal characteristics](#) provides details.
- Core voltage as measured on device pin to guarantee published silicon performance
- During power ramp, voltage measured on silicon might be lower. Maximum performance is not guaranteed, but correct silicon operation is guaranteed. See power management and reset management for description.
- Maximum core voltage is not permitted for entire product life. See absolute maximum rating.
- When internal LVD/HVDs are disabled, external monitoring is required to guarantee device operation. Failure to monitor externally supply voltage may result in erroneous operation of the device.
- This LVD/HVD disabled supply voltage condition only applies after LVD/HVD are disabled by the application during the reset sequence, and the LVD/HVD are active until that point.
- This spec does not apply to  $V_{DDEH1}$ .
- When internal flash memory regulator is used:
  - Flash memory read operation is supported for a minimum  $V_{DDPMC}$  value of 3.15 V.
  - Flash memory read, program, and erase operations are supported for a minimum  $V_{DDPMC}$  value of 3.5 V.

## Electrical characteristics

When flash memory power is supplied externally ( $V_{DDPMC}$  shorted to  $V_{DDFLA}$ ): The  $V_{DDPMC}$  range must be within the limits specified for LVD\_FLASH and HVD\_FLASH monitoring. Table 29 provides the monitored LVD\_FLASH and HVD\_FLASH limits.

13. If the standby RAM regulator is not used, the  $V_{STBY}$  supply input pin must be tied to ground.
14.  $V_{STBY\_BO}$  is the maximum voltage that sets the standby RAM brownout flag in the device logic. The minimum voltage for RAM data retention is guaranteed always to be less than the  $V_{STBY\_BO}$  maximum value.
15. For supply voltages between 3.0 V and 4.0 V there will be no guaranteed precision of ADC (accuracy/linearity). ADC will recover to a fully functional state when the voltage rises above 4.0 V.
16. Full device lifetime without performance degradation
17. I/O and analog input specifications are only valid if the injection current on adjacent pins is within these limits. See the absolute maximum ratings table for maximum input current for reliability requirements.
18. The I/O pins on the device are clamped to the I/O supply rails for ESD protection. When the voltage of the input pin is above the supply rail, current will be injected through the clamp diode to the supply rail. For external RC network calculation, assume a typical 0.3 V drop across the active diode. The diode voltage drop varies with temperature.
19. The sum of all controller pins (including both digital and analog) must not exceed 200 mA. A  $V_{DDEX}/V_{DDEHx}$  power segment is defined as one or more GPIO pins located between two  $V_{DDEX}/V_{DDEHx}$  supply pins.
20. The average current values given in [I/O pad current specifications](#) should be used to calculate total I/O segment current.

## 3.5 DC electrical specifications

### NOTE

$I_{DDA\_MISC}$  is the sum of current consumption of IRC,  $I_{TRNG}$ , and  $I_{STBY}$  in the 5 V domain. IRC current is provided in the IRC specifications.

### NOTE

I/O, XOSC, EQADC, SDADC, and Temperature Sensor current specifications are in those components' dedicated sections.

**Table 4. DC electrical specifications**

| Symbol       | Parameter                                                                      | Conditions                                   | Value |      |      | Unit |
|--------------|--------------------------------------------------------------------------------|----------------------------------------------|-------|------|------|------|
|              |                                                                                |                                              | Min   | Typ  | Max  |      |
| $I_{DD}$     | Operating current on the $V_{DD}$ core logic supply <sup>1</sup>               | LVD/HVD enabled, $V_{DD} = 1.2$ V to 1.32 V  | —     | 0.65 | 1.35 | A    |
|              |                                                                                | LVD/HVD disabled, $V_{DD} = 1.2$ V to 1.38 V | —     | 0.65 | 1.4  |      |
| $I_{DD\_PE}$ | Operating current on the $V_{DD}$ supply for flash memory program/erase        | —                                            | —     | —    | 85   | mA   |
| $I_{DDPMC}$  | Operating current on the $V_{DDPMC}$ supply <sup>2</sup>                       | Flash memory read                            | —     | —    | 40   | mA   |
|              |                                                                                | Flash memory program/erase                   | —     | —    | 70   |      |
|              |                                                                                | PMC only                                     | —     | —    | 35   |      |
|              | Operating current on the $V_{DDPMC}$ supply (internal core regulator bypassed) | Flash memory read                            | —     | —    | 10   | mA   |
|              |                                                                                | Flash memory program/erase                   | —     | —    | 40   |      |
|              |                                                                                | PMC only                                     | —     | —    | 5    |      |
| $I_{REGCTL}$ | Core regulator DC current output on $V_{REGCTL}$ pin                           | —                                            | —     | —    | 25   | mA   |

Table continues on the next page...

**Table 4. DC electrical specifications (continued)**

| Symbol              | Parameter                                          | Conditions                              | Value |     |      | Unit |
|---------------------|----------------------------------------------------|-----------------------------------------|-------|-----|------|------|
|                     |                                                    |                                         | Min   | Typ | Max  |      |
| I <sub>STBY</sub>   | Standby RAM supply current                         | 1.08 V, T <sub>J</sub> = 150°C          | —     | —   | 1140 | μA   |
|                     |                                                    | 1.25 V to 5.5 V, T <sub>J</sub> = 150°C |       |     | 1170 |      |
|                     |                                                    | 1.25 V to 5.5 V, T <sub>J</sub> = 85°C  |       |     | 360  |      |
|                     |                                                    | 1.25 V to 5.5 V, T <sub>J</sub> = 40°C  | —     | —   | 120  |      |
| I <sub>DD_PWR</sub> | Operating current on the V <sub>DDPWR</sub> supply | —                                       | —     | —   | 50   | mA   |
| I <sub>BG_REF</sub> | Bandgap reference current consumption <sup>3</sup> | —                                       | —     | —   | 600  | μA   |
| I <sub>TRNG</sub>   | True Random Number Generator current               | —                                       | —     | —   | 2.1  | mA   |

1. I<sub>DD</sub> measured on an application-specific pattern with all cores enabled at full frequency, T<sub>J</sub> = 40°C to 150°C. Flash memory program/erase current on the V<sub>DD</sub> supply not included.
2. This value is considering the use of the internal core regulator with the simulation of an external transistor with the minimum value of h<sub>FE</sub> of 60.
3. This bandgap reference is for EQADC calibration and Temperature Sensors.

## 3.6 I/O pad specifications

The following table describes the different pad types on the chip.

**Table 5. I/O pad specification descriptions**

| Pad type                 | Description                                                                                                                      |
|--------------------------|----------------------------------------------------------------------------------------------------------------------------------|
| General-purpose I/O pads | General-purpose I/O and EBI data bus pads with four selectable output slew rate settings; also called SR pads                    |
| EBI pads                 | Provide necessary speed for fast external memory interfaces on the EBI CLKOUT, address, and control signals; also called FC pads |
| LVDS pads                | Low Voltage Differential Signal interface pads                                                                                   |
| Input-only pads          | Low-input-leakage pads that are associated with the ADC channels                                                                 |

### NOTE

Each I/O pin on the device supports specific drive configurations. See the signal description table in the device reference manual for the available drive configurations for each I/O pin.

### NOTE

Throughout the I/O pad specifications, the symbol V<sub>DDEX</sub> represents all V<sub>DDEX</sub> and V<sub>DDEHx</sub> segments.

### 3.6.1 Input pad specifications

Table 6 provides input DC electrical characteristics as described in Figure 4.

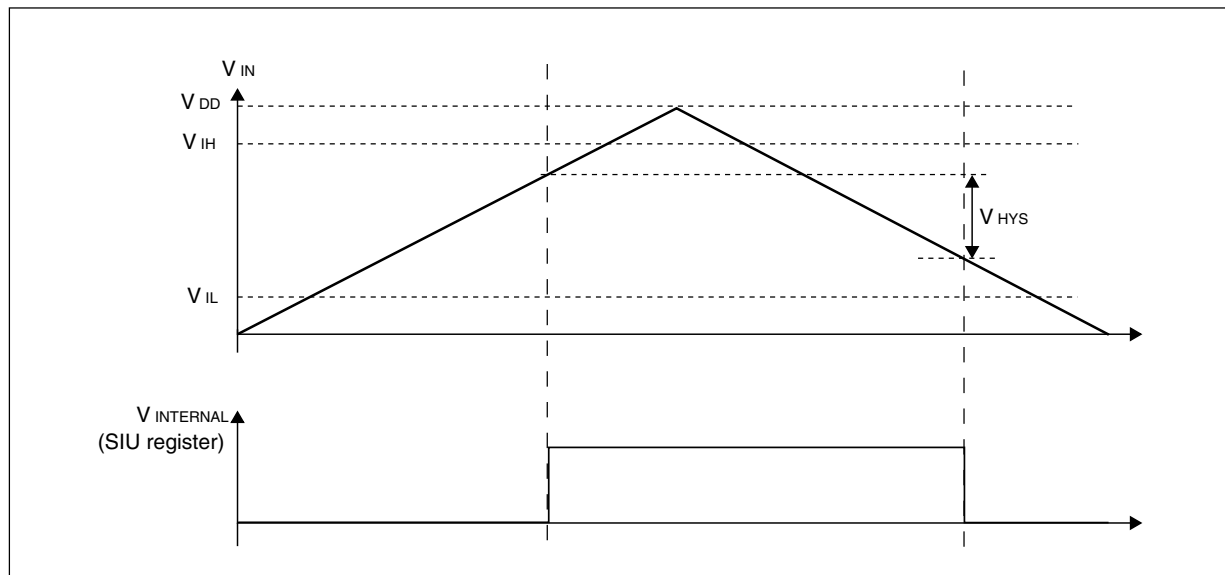


Figure 4. I/O input DC electrical characteristics definition

Table 6. I/O input DC electrical characteristics

| Symbol                                   | Parameter                                                 | Conditions                                                                               | Value             |     |                   | Unit          |
|------------------------------------------|-----------------------------------------------------------|------------------------------------------------------------------------------------------|-------------------|-----|-------------------|---------------|
|                                          |                                                           |                                                                                          | Min               | Typ | Max               |               |
| $V_{IHCMS\_H}$                           | Input high level CMOS (with hysteresis)                   | $3.0\text{ V} < V_{DDEx} < 3.6\text{ V}$ and<br>$4.5\text{ V} < V_{DDEx} < 5.5\text{ V}$ | $0.65 * V_{DDEx}$ | —   | $V_{DDEx} + 0.3$  | V             |
| $V_{IHCMS}$                              | Input high level CMOS (without hysteresis)                | $3.0\text{ V} < V_{DDEx} < 3.6\text{ V}$ and<br>$4.5\text{ V} < V_{DDEx} < 5.5\text{ V}$ | $0.55 * V_{DDEx}$ | —   | $V_{DDEx} + 0.3$  | V             |
| $V_{ILCMS\_H}$                           | Input low level CMOS (with hysteresis)                    | $3.0\text{ V} < V_{DDEx} < 3.6\text{ V}$ and<br>$4.5\text{ V} < V_{DDEx} < 5.5\text{ V}$ | -0.3              | —   | $0.35 * V_{DDEx}$ | V             |
| $V_{ILCMS}$                              | Input low level CMOS (without hysteresis)                 | $3.0\text{ V} < V_{DDEx} < 3.6\text{ V}$ and<br>$4.5\text{ V} < V_{DDEx} < 5.5\text{ V}$ | -0.3              | —   | $0.4 * V_{DDEx}$  | V             |
| $V_{HYSCMS}$                             | Input hysteresis CMOS                                     | $3.0\text{ V} < V_{DDEx} < 3.6\text{ V}$ and<br>$4.5\text{ V} < V_{DDEx} < 5.5\text{ V}$ | $0.1 * V_{DDEx}$  | —   | —                 | V             |
| <b>Input Characteristics<sup>1</sup></b> |                                                           |                                                                                          |                   |     |                   |               |
| $I_{LKG}$                                | Digital input leakage                                     | $V_{SS} < V_{IN} < V_{DDEx}/V_{DDEHx}$                                                   | —                 | —   | 2.5               | $\mu\text{A}$ |
| $I_{LKG\_FAST}$                          | Digital input leakage for EBI address/control signal pads | $V_{SS} < V_{IN} < V_{DDEx}/V_{DDEHx}$                                                   | —                 | —   | 2.5               | $\mu\text{A}$ |
| $I_{LKGA}$                               | Analog pin input leakage (5 V range)                      | $V_{SSA\_SD} < V_{IN} < V_{DDA\_SD}$ ,<br>$V_{SSA\_EQ} < V_{IN} < V_{DDA\_EQA/B}$        | —                 | —   | 220               | nA            |
| $C_{IN}$                                 | Digital input capacitance                                 | GPIO and EBI input pins                                                                  | —                 | —   | 7                 | pF            |

1. For LFAST, microsecond bus, and LVDS input characteristics, see dedicated communication module sections.

Table 7 provides current specifications for weak pullup and pulldown.

**Table 7. I/O pullup/pulldown DC electrical characteristics**

| Symbol           | Parameter             | Conditions                                                                      | Value |     |     | Unit |
|------------------|-----------------------|---------------------------------------------------------------------------------|-------|-----|-----|------|
|                  |                       |                                                                                 | Min   | Typ | Max |      |
| I <sub>WPU</sub> | Weak pullup current   | V <sub>IN</sub> = 0.35 * V <sub>DDEx</sub><br>4.5 V < V <sub>DDEx</sub> < 5.5 V | 40    | —   | 120 | μA   |
|                  |                       | V <sub>IN</sub> = 0.35 * V <sub>DDEx</sub><br>3.0 V < V <sub>DDEx</sub> < 3.6 V | 25    | —   | 80  |      |
| I <sub>WPD</sub> | Weak pulldown current | V <sub>IN</sub> = 0.65 * V <sub>DDEx</sub><br>4.5 V < V <sub>DDEx</sub> < 5.5 V | 40    | —   | 120 | μA   |
|                  |                       | V <sub>IN</sub> = 0.65 * V <sub>DDEx</sub><br>3.0 V < V <sub>DDEx</sub> < 3.6 V | 25    | —   | 80  |      |

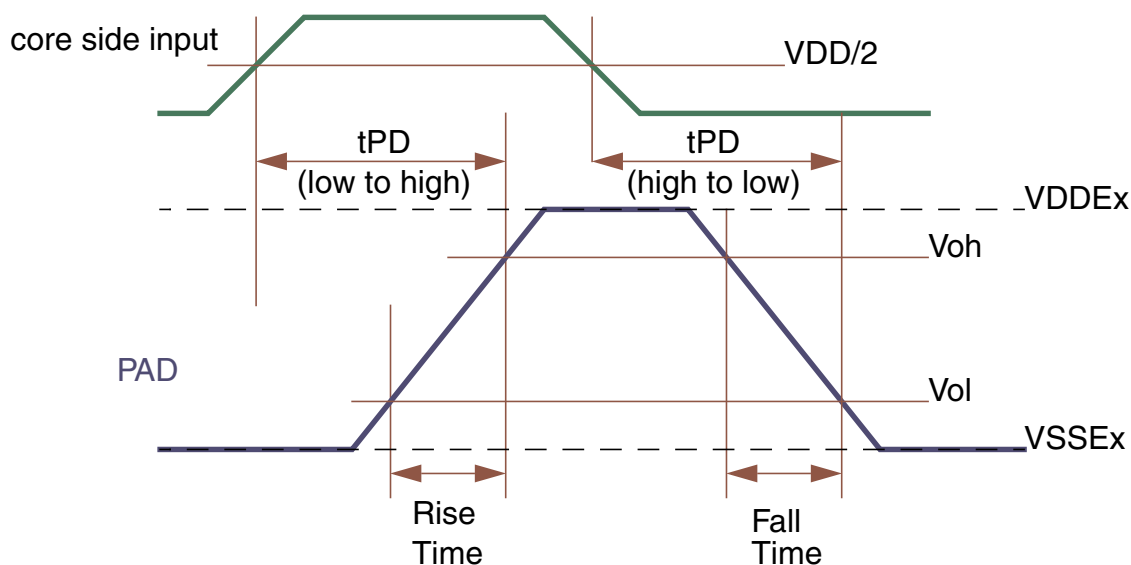
The specifications in [Table 8](#) apply to the pins ANA0\_SDA0 to ANA7, ANA16\_SDB0 to ANA23\_SDC3, and ANB0\_SDD0 to ANB7\_SDD7.

**Table 8. I/O pullup/pulldown resistance electrical characteristics**

| Symbol            | Parameter                                                 | Conditions | Value |     |     | Unit |
|-------------------|-----------------------------------------------------------|------------|-------|-----|-----|------|
|                   |                                                           |            | Min   | Typ | Max |      |
| R <sub>PUPD</sub> | Analog input bias / diagnostic pullup/pulldown resistance | 200 kΩ     | 130   | 200 | 280 | kΩ   |
|                   |                                                           | 100 kΩ     | 65    | 100 | 140 |      |
|                   |                                                           | 5 kΩ       | 1.4   | 5   | 7.5 |      |
| Δ <sub>PUPD</sub> | R <sub>PUPD</sub> pullup/pulldown resistance mismatch     | —          | —     | —   | 5   | %    |

### 3.6.2 Output pad specifications

[Figure 5](#) shows output DC electrical characteristics.



**Figure 5. I/O output DC electrical characteristics definition**

The following tables specify output DC electrical characteristics.

**Table 9. GPIO and EBI data pad output buffer electrical characteristics (SR pads)<sup>1</sup>**

| Symbol   | Parameter                    | Conditions <sup>2</sup>                    |                       | Value <sup>3</sup> |     |     | Unit |
|----------|------------------------------|--------------------------------------------|-----------------------|--------------------|-----|-----|------|
|          |                              |                                            |                       | Min                | Typ | Max |      |
| $I_{OH}$ | GPIO pad output high current | $V_{OH} = 0.8 \cdot V_{DDEx}$              | PCR[SRC] = 11b or 01b | 25                 | —   | —   | mA   |
|          |                              | $4.5 \text{ V} < V_{DDEx} < 5.5 \text{ V}$ | PCR[SRC] = 10b or 00b | 15                 | —   | —   |      |
|          |                              | $V_{OH} = 0.8 \cdot V_{DDEx}$              | PCR[SRC] = 11b or 01b | 13                 | —   | —   |      |
|          |                              | $3.0 \text{ V} < V_{DDEx} < 3.6 \text{ V}$ | PCR[SRC] = 10b or 00b | 8                  | —   | —   |      |
| $I_{OL}$ | GPIO pad output low current  | $V_{OL} = 0.2 \cdot V_{DDEx}$              | PCR[SRC] = 11b or 01b | 48                 | —   | —   | mA   |
|          |                              | $4.5 \text{ V} < V_{DDEx} < 5.5 \text{ V}$ | PCR[SRC] = 10b or 00b | 22                 | —   | —   |      |
|          |                              | $V_{OL} = 0.2 \cdot V_{DDEx}$              | PCR[SRC] = 11b or 01b | 17                 | —   | —   |      |
|          |                              | $3.0 \text{ V} < V_{DDEx} < 3.6 \text{ V}$ | PCR[SRC] = 10b or 00b | 10.5               | —   | —   |      |

Table continues on the next page...

**Table 9. GPIO and EBI data pad output buffer electrical characteristics (SR pads)<sup>1</sup>**  
(continued)

| Symbol          | Parameter                                   | Conditions <sup>2</sup>                      |                | Value <sup>3</sup> |     |      | Unit |
|-----------------|---------------------------------------------|----------------------------------------------|----------------|--------------------|-----|------|------|
|                 |                                             |                                              |                | Min                | Typ | Max  |      |
| $t_{R\_F}$      | GPIO pad output transition time (rise/fall) | PCR[SRC] = 11b<br>4.5 V < $V_{DDEX}$ < 5.5 V | $C_L$ = 25 pF  | —                  | —   | 1.2  | ns   |
|                 |                                             |                                              | $C_L$ = 50 pF  | —                  | —   | 2.5  |      |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 8    |      |
|                 |                                             | PCR[SRC] = 11b<br>3.0 V < $V_{DDEX}$ < 3.6 V | $C_L$ = 25 pF  | —                  | —   | 1.7  |      |
|                 |                                             |                                              | $C_L$ = 50 pF  | —                  | —   | 3.25 |      |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 12   |      |
|                 |                                             | PCR[SRC] = 10b<br>4.5 V < $V_{DDEX}$ < 5.5 V | $C_L$ = 50 pF  | —                  | —   | 5    |      |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 18   |      |
|                 |                                             | PCR[SRC] = 10b<br>3.0 V < $V_{DDEX}$ < 3.6 V | $C_L$ = 50 pF  | —                  | —   | 7    |      |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 25   |      |
|                 |                                             | PCR[SRC] = 01b<br>4.5 V < $V_{DDEX}$ < 5.5 V | $C_L$ = 50 pF  | —                  | —   | 13   |      |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 24   |      |
|                 |                                             | PCR[SRC] = 01b<br>3.0 V < $V_{DDEX}$ < 3.6 V | $C_L$ = 50 pF  | —                  | —   | 25   |      |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 30   |      |
|                 |                                             | PCR[SRC] = 00b<br>4.5 V < $V_{DDEX}$ < 5.5 V | $C_L$ = 50 pF  | —                  | —   | 24   |      |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 50   |      |
|                 |                                             | PCR[SRC] = 00b<br>3.0 V < $V_{DDEX}$ < 3.6 V | $C_L$ = 50 pF  | —                  | —   | 40   |      |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 51   |      |
| $t_{PD}$        | GPIO pad output propagation delay time      | PCR[SRC] = 11b<br>4.5 V < $V_{DDEX}$ < 5.5 V | $C_L$ = 50 pF  | —                  | —   | 6    | ns   |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 13   |      |
|                 |                                             | PCR[SRC] = 11b<br>3.0 V < $V_{DDEX}$ < 3.6 V | $C_L$ = 50 pF  | —                  | —   | 8.25 |      |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 19.5 |      |
|                 |                                             | PCR[SRC] = 10b<br>4.5 V < $V_{DDEX}$ < 5.5 V | $C_L$ = 50 pF  | —                  | —   | 9    |      |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 22   |      |
|                 |                                             | PCR[SRC] = 10b<br>3.0 V < $V_{DDEX}$ < 3.6 V | $C_L$ = 50 pF  | —                  | —   | 12.5 |      |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 35   |      |
|                 |                                             | PCR[SRC] = 01b<br>4.5 V < $V_{DDEX}$ < 5.5 V | $C_L$ = 50 pF  | —                  | —   | 27   |      |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 40   |      |
|                 |                                             | PCR[SRC] = 01b<br>3.0 V < $V_{DDEX}$ < 3.6 V | $C_L$ = 50 pF  | —                  | —   | 45   |      |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 65   |      |
|                 |                                             | PCR[SRC] = 00b<br>4.5 V < $V_{DDEX}$ < 5.5 V | $C_L$ = 50 pF  | —                  | —   | 40   |      |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 65   |      |
|                 |                                             | PCR[SRC] = 00b<br>3.0 V < $V_{DDEX}$ < 3.6 V | $C_L$ = 50 pF  | —                  | —   | 75   |      |
|                 |                                             |                                              | $C_L$ = 200 pF | —                  | —   | 100  |      |
| $ t_{SKEW\_W} $ | Difference between rise and fall time       | —                                            |                | —                  | —   | 25   | %    |

1. All GPIO pad output specifications are valid for 3.0 V <  $V_{DDEX}$  < 5.5 V, except where explicitly stated.

## Electrical characteristics

2. PCR[Src] values refer to the setting of that register field in the SIU.
3. All values to be confirmed during device validation.

The following table shows the EBI CLKOUT, address, and control signal pad electrical characteristics. These pads can also be used for GPIO.

**Table 10. GPIO and EBI CLKOUT, address, and control signal pad output buffer electrical characteristics (FC pads)**

| Symbol                                                                      | Parameter                                                    | Conditions <sup>1</sup>                                                        | Value                  |     |     | Unit |    |
|-----------------------------------------------------------------------------|--------------------------------------------------------------|--------------------------------------------------------------------------------|------------------------|-----|-----|------|----|
|                                                                             |                                                              |                                                                                | Min                    | Typ | Max |      |    |
| EBI Mode Output Specifications: valid for 3.0 V < V <sub>DDEx</sub> < 3.6 V |                                                              |                                                                                |                        |     |     |      |    |
| C <sub>DRV</sub>                                                            | External bus load capacitance                                | PCR[DSC] = 01b                                                                 | —                      | —   | 10  | pF   |    |
|                                                                             |                                                              | PCR[DSC] = 10b                                                                 | —                      | —   | 20  |      |    |
|                                                                             |                                                              | PCR[DSC] = 11b                                                                 | —                      | —   | 30  |      |    |
| f <sub>MAX_EBI</sub>                                                        | External bus maximum operating frequency                     | C <sub>DRV</sub> = 10/20/30 pF                                                 | —                      | —   | 66  | MHz  |    |
| GPIO and EBI Mode Output Specifications                                     |                                                              |                                                                                |                        |     |     |      |    |
| I <sub>OH_EBI</sub>                                                         | GPIO and external bus pad output high current                | V <sub>OH</sub> = 0.8 * V <sub>DDEx</sub><br>4.5 V < V <sub>DDEx</sub> < 5.5 V | PCR[DSC] = 11b         | 30  | —   | —    | mA |
|                                                                             |                                                              |                                                                                | PCR[DSC] = 10b         | 22  | —   | —    |    |
|                                                                             |                                                              |                                                                                | PCR[DSC] = 01b         | 13  | —   | —    |    |
|                                                                             |                                                              |                                                                                | PCR[DSC] = 00b         | 2   | —   | —    |    |
|                                                                             |                                                              | V <sub>OH</sub> = 0.8 * V <sub>DDEx</sub><br>3.0 V < V <sub>DDEx</sub> < 3.6 V | PCR[DSC] = 11b         | 16  | —   | —    |    |
|                                                                             |                                                              |                                                                                | PCR[DSC] = 10b         | 12  | —   | —    |    |
|                                                                             |                                                              |                                                                                | PCR[DSC] = 01b         | 7   | —   | —    |    |
|                                                                             |                                                              |                                                                                | PCR[DSC] = 00b         | 1   | —   | —    |    |
| I <sub>OL_EBI</sub>                                                         | GPIO and external bus pad output low current                 | V <sub>OL</sub> = 0.2 * V <sub>DDEx</sub><br>4.5 V < V <sub>DDEx</sub> < 5.5 V | PCR[DSC] = 11b         | 54  | —   | —    | mA |
|                                                                             |                                                              |                                                                                | PCR[DSC] = 10b         | 25  | —   | —    |    |
|                                                                             |                                                              |                                                                                | PCR[DSC] = 01b         | 16  | —   | —    |    |
|                                                                             |                                                              |                                                                                | PCR[DSC] = 00b         | 2   | —   | —    |    |
|                                                                             |                                                              | V <sub>OL</sub> = 0.2 * V <sub>DDEx</sub><br>3.0 V < V <sub>DDEx</sub> < 3.6 V | PCR[DSC] = 11b         | 17  | —   | —    |    |
|                                                                             |                                                              |                                                                                | PCR[DSC] = 10b         | 14  | —   | —    |    |
|                                                                             |                                                              |                                                                                | PCR[DSC] = 01b         | 8   | —   | —    |    |
|                                                                             |                                                              |                                                                                | PCR[DSC] = 00b         | 1   | —   | —    |    |
| t <sub>R_F_EBI</sub>                                                        | GPIO and external bus pad output transition time (rise/fall) | PCR[DSC] = 11b                                                                 | C <sub>L</sub> = 30 pF | —   | —   | 1.5  | ns |
|                                                                             |                                                              |                                                                                | C <sub>L</sub> = 50 pF | —   | —   | 2.4  |    |
|                                                                             |                                                              | PCR[DSC] = 10b                                                                 | C <sub>L</sub> = 20 pF | —   | —   | 1.5  |    |
|                                                                             |                                                              | PCR[DSC] = 01b                                                                 | C <sub>L</sub> = 10 pF | —   | —   | 1.85 |    |
|                                                                             |                                                              | PCR[DSC] = 00b                                                                 | C <sub>L</sub> = 50 pF | —   | —   | 45   |    |
| t <sub>PD_EBI</sub>                                                         | GPIO and external bus pad output propagation delay time      | PCR[DSC] = 11b                                                                 | C <sub>L</sub> = 30 pF | —   | —   | 4.2  | ns |
|                                                                             |                                                              |                                                                                | C <sub>L</sub> = 50 pF | —   | —   | 5.5  |    |
|                                                                             |                                                              | PCR[DSC] = 10b                                                                 | C <sub>L</sub> = 20 pF | —   | —   | 4.2  |    |
|                                                                             |                                                              | PCR[DSC] = 01b                                                                 | C <sub>L</sub> = 10 pF | —   | —   | 4.4  |    |
|                                                                             |                                                              | PCR[DSC] = 00b                                                                 | C <sub>L</sub> = 50 pF | —   | —   | 59   |    |

1. PCR[DSC] values refer to the setting of that register field in the SIU.

### 3.6.3 I/O pad current specifications

The I/O pads are distributed across the I/O supply segments. Each I/O supply segment is associated with a  $V_{DDEX}$  supply segment.

Table 11 provides I/O consumption figures.

To ensure device reliability, the average current of the I/O on a single segment should remain below the  $I_{MAXSEG}$  value given in Table 1.

To ensure device functionality, the average current of the I/O on a single segment should remain below the  $I_{MAXSEG}$  value given in Table 3.

#### NOTE

The MPC5777C I/O Signal Description and Input Multiplexing Tables are contained in a Microsoft Excel® file attached to the Reference Manual. In the spreadsheet, select the I/O Signal Table tab.

The EBI power segments have been designed to operate within the maximum per-segment current specification when the pins on the segment are used for EBI function. If the pins are used instead for GPIO function, the user must ensure the sum of the current used on each pin in the segment does not exceed the spec.

**Table 11. I/O consumption**

| Symbol          | Parameter                                                  | Conditions                                                                                    | Value |     |      | Unit |
|-----------------|------------------------------------------------------------|-----------------------------------------------------------------------------------------------|-------|-----|------|------|
|                 |                                                            |                                                                                               | Min   | Typ | Max  |      |
| $I_{AVG\_GPIO}$ | Average I/O current for GPIO pads (per pad)                | $C_L = 25 \text{ pF}$ , 2 MHz<br>$V_{DDEX} = 5.0 \text{ V} \pm 10\%$                          | —     | —   | 0.42 | mA   |
|                 |                                                            | $C_L = 50 \text{ pF}$ , 1 MHz<br>$V_{DDEX} = 5.0 \text{ V} \pm 10\%$                          | —     | —   | 0.35 |      |
| $I_{AVG\_EBI}$  | Average I/O current for external bus output pins (per pad) | $C_{DRV} = 10 \text{ pF}$ , $f_{EBI} = 66 \text{ MHz}$<br>$V_{DDEX} = 3.3 \text{ V} \pm 10\%$ | —     | —   | 9    | mA   |
|                 |                                                            | $C_{DRV} = 20 \text{ pF}$ , $f_{EBI} = 66 \text{ MHz}$<br>$V_{DDEX} = 3.3 \text{ V} \pm 10\%$ | —     | —   | 18   |      |
|                 |                                                            | $C_{DRV} = 30 \text{ pF}$ , $f_{EBI} = 66 \text{ MHz}$<br>$V_{DDEX} = 3.3 \text{ V} \pm 10\%$ | —     | —   | 30   |      |

## 3.7 Oscillator and PLL electrical specifications

The on-chip dual PLL—consisting of the peripheral clock and reference PLL (PLL0) and the frequency-modulated system PLL (PLL1)—generates the system and auxiliary clocks from the main oscillator driver.

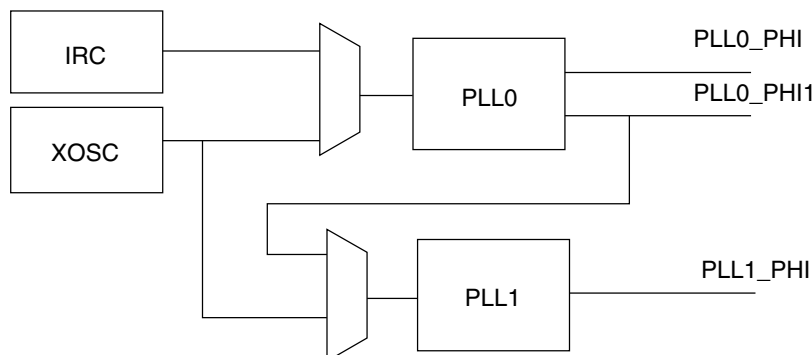


Figure 6. PLL integration

### 3.7.1 PLL electrical specifications

Table 12. PLL0 electrical characteristics

| Symbol                          | Parameter                                                                                                                  | Conditions                                                                 | Value |     |                      | Unit |
|---------------------------------|----------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------|-------|-----|----------------------|------|
|                                 |                                                                                                                            |                                                                            | Min   | Typ | Max                  |      |
| $f_{\text{PLL0IN}}$             | PLL0 input clock <sup>1, 2</sup>                                                                                           | —                                                                          | 8     | —   | 44                   | MHz  |
| $\Delta_{\text{PLL0IN}}$        | PLL0 input clock duty cycle <sup>2</sup>                                                                                   | —                                                                          | 40    | —   | 60                   | %    |
| $f_{\text{PLL0VCO}}$            | PLL0 VCO frequency                                                                                                         | —                                                                          | 600   | —   | 1250                 | MHz  |
| $f_{\text{PLL0PHI}}$            | PLL0 output frequency                                                                                                      | —                                                                          | 4.762 | —   | 200/240 <sup>3</sup> | MHz  |
| $t_{\text{PLL0LOCK}}$           | PLL0 lock time                                                                                                             | —                                                                          | —     | —   | 110                  | μs   |
| $ \Delta_{\text{PLL0PHISPJ}} $  | PLL0_PHI single period jitter<br>$f_{\text{PLL0IN}} = 20 \text{ MHz (resonator)}$                                          | $f_{\text{PLL0PHI}} = 200 \text{ MHz, 6-sigma}$                            | —     | —   | 200                  | ps   |
| $ \Delta_{\text{PLL0PHI1SPJ}} $ | PLL0_PHI1 single period jitter<br>$f_{\text{PLL0IN}} = 20 \text{ MHz (resonator)}$                                         | $f_{\text{PLL0PHI1}} = 40 \text{ MHz, 6-sigma}$                            | —     | —   | 300 <sup>4</sup>     | ps   |
| $\Delta_{\text{PLL0LTJ}}$       | PLL0 output long term jitter <sup>4</sup><br>$f_{\text{PLL0IN}} = 20 \text{ MHz (resonator)}$ ,<br>VCO frequency = 800 MHz | 10 periods accumulated jitter (80 MHz equivalent frequency), 6-sigma pk-pk | —     | —   | ±250                 | ps   |
|                                 |                                                                                                                            | 16 periods accumulated jitter (50 MHz equivalent frequency), 6-sigma pk-pk | —     | —   | ±300                 | ps   |
|                                 |                                                                                                                            | long term jitter (< 1 MHz equivalent frequency), 6-sigma pk-pk             | —     | —   | ±500                 | ps   |
| $I_{\text{PLL0}}$               | PLL0 consumption                                                                                                           | FINE LOCK state                                                            | —     | —   | 7.5                  | mA   |

1. Ensure that the  $f_{\text{PLL0IN}}$  frequency divided by PLLDIG\_PLL0DV[PREDIV] is in the range 8 MHz to 20 MHz.
2. PLL0IN clock retrieved directly from either internal IRC or external XOSC clock. Input characteristics are granted when using internal IRC or external oscillator is used in functional mode.
3. 200 MHz applies to the MPC5777C part number with 264 MHz operating frequency. 240 MHz applies to the version with 300 MHz operating frequency

4. Noise on the  $V_{DD}$  supply with frequency content below 40 kHz and above 50 MHz is filtered by the PLL. Noise on the  $V_{DD}$  supply with frequency content in the range of 40 kHz – 50 MHz must be filtered externally to the device.

**Table 13. PLL1 electrical characteristics**

| Symbol                  | Parameter                                  | Conditions                       | Value |     |                      | Unit    |
|-------------------------|--------------------------------------------|----------------------------------|-------|-----|----------------------|---------|
|                         |                                            |                                  | Min   | Typ | Max                  |         |
| $f_{PLL1IN}$            | PLL1 input clock <sup>1</sup>              | —                                | 38    | —   | 78                   | MHz     |
| $\Delta_{PLL1IN}$       | PLL1 input clock duty cycle <sup>1</sup>   | —                                | 35    | —   | 65                   | %       |
| $f_{PLL1VCO}$           | PLL1 VCO frequency                         | —                                | 600   | —   | 1250                 | MHz     |
| $f_{PLL1PHI}$           | PLL1 output clock PHI                      | —                                | 4.762 | —   | 264/300 <sup>2</sup> | MHz     |
| $t_{PLL1LOCK}$          | PLL1 lock time                             | —                                | —     | —   | 100                  | $\mu$ s |
| $ \Delta_{PLL1PHISPJ} $ | PLL1_PHI single period peak-to-peak jitter | $f_{PLL1PHI} = 200$ MHz, 6-sigma | —     | —   | 500 <sup>3</sup>     | ps      |
| $f_{PLL1MOD}$           | PLL1 modulation frequency                  | —                                | —     | —   | 250                  | kHz     |
| $ \delta_{PLL1MOD} $    | PLL1 modulation depth (when enabled)       | Center spread                    | 0.25  | —   | 2                    | %       |
|                         |                                            | Down spread                      | 0.5   | —   | 4                    | %       |
| $I_{PLL1}$              | PLL1 consumption                           | FINE LOCK state                  | —     | —   | 6                    | mA      |

1. PLL1IN clock retrieved directly from either internal PLL0 or external XOSC clock. Input characteristics are granted when using internal PLL0 or external oscillator in functional mode.
2. 264 MHz applies to the MPC5777C part number with 264 MHz max operating frequency. 300 MHz applies to the version with 300 MHz operating frequency
3. Noise on the  $V_{DD}$  supply with frequency content below 40 kHz and above 50 MHz is filtered by the PLL. Noise on the  $V_{DD}$  supply with frequency content in the range of 40 kHz – 50 MHz must be filtered externally to the device.

### 3.7.2 Oscillator electrical specifications

#### NOTE

All oscillator specifications in [Table 14](#) are valid for  $V_{DDEH6} = 3.0$  V to 5.5 V.

**Table 14. External oscillator (XOSC) electrical specifications**

| Symbol         | Parameter                                                 | Conditions                   | Value           |                 | Unit |
|----------------|-----------------------------------------------------------|------------------------------|-----------------|-----------------|------|
|                |                                                           |                              | Min             | Max             |      |
| $f_{XTAL}$     | Crystal frequency range                                   | —                            | 8               | 40              | MHz  |
| $t_{cst}$      | Crystal start-up time <sup>1, 2</sup>                     | $T_J = 150$ °C               | —               | 5               | ms   |
| $t_{rec}$      | Crystal recovery time <sup>3</sup>                        | —                            | —               | 0.5             | ms   |
| $V_{IHEXT}$    | EXTAL input high voltage (external reference)             | $V_{REF} = 0.28 * V_{DDEH6}$ | $V_{REF} + 0.6$ | —               | V    |
| $V_{ILEXT}$    | EXTAL input low voltage (external reference)              | $V_{REF} = 0.28 * V_{DDEH6}$ | —               | $V_{REF} - 0.6$ | V    |
| $C_{S\_EXTAL}$ | Total on-chip stray capacitance on EXTAL pin <sup>4</sup> | 416-ball MAPBGA              | 2.3             | 3.0             | pF   |
|                |                                                           | 516-ball MAPBGA              | 2.1             | 2.8             |      |
| $C_{S\_XTAL}$  | Total on-chip stray capacitance on XTAL pin <sup>4</sup>  | 416-ball MAPBGA              | 2.3             | 3.0             | pF   |
|                |                                                           | 516-ball MAPBGA              | 2.2             | 2.9             |      |

Table continues on the next page...

**Table 14. External oscillator (XOSC) electrical specifications (continued)**

| Symbol      | Parameter                                                         | Conditions | Value |     | Unit |
|-------------|-------------------------------------------------------------------|------------|-------|-----|------|
|             |                                                                   |            | Min   | Max |      |
| $g_m$       | Oscillator transconductance <sup>5</sup>                          | Low        | 3     | 10  | mA/V |
|             |                                                                   | Medium     | 10    | 27  |      |
|             |                                                                   | High       | 12    | 35  |      |
| $V_{EXTAL}$ | Oscillation amplitude on the EXTAL pin after startup <sup>6</sup> | —          | 0.5   | 1.6 | V    |
| $V_{HYS}$   | Comparator hysteresis                                             | —          | 0.1   | 1.0 | V    |
| $I_{XTAL}$  | XTAL current <sup>6, 7</sup>                                      | —          | —     | 14  | mA   |

1. This value is determined by the crystal manufacturer and board design.
2. Proper PC board layout procedures must be followed to achieve specifications.
3. Crystal recovery time is the time for the oscillator to settle to the correct frequency after adjustment of the integrated load capacitor value.
4. See crystal manufacturer's specification for recommended load capacitor ( $C_L$ ) values. The external oscillator requires external load capacitors when operating in a "low" transconductance range. Account for on-chip stray capacitance ( $C_{S\_EXTAL}/C_{S\_XTAL}$ ) and PCB capacitance when selecting a load capacitor value. When operating in a "medium" or "high" transconductance range, the integrated load capacitor value is selected via software to match the crystal manufacturer's specification, while accounting for on-chip and PCB capacitance.
5. Select a "low," "medium," or "high" setting using the UTEST Miscellaneous DCF client's XOSC\_LF\_EN and XOSC\_EN\_HIGH fields. "Low" is the setting commonly used for crystals at 8 MHz, "medium" is commonly used for crystals greater than 8 MHz to 20 MHz, and "high" is commonly used for crystals greater than 20 MHz to 40 MHz. However, the user must characterize carefully to determine the best  $g_m$  setting for the intended application because crystal load capacitance, board layout, and other factors affect the  $g_m$  value that is needed. The user may need an additional Rshunt to optimize  $g_m$  depending on the system environment. Use of overtone crystals is not recommended.
6. Amplitude on the EXTAL pin after startup is determined by the ALC block (that is, the Automatic Level Control Circuit). The function of the ALC is to provide high drive current during oscillator startup, while reducing current after oscillation to reduce power, distortion, and RFI, and to avoid over-driving the crystal. The operating point of the ALC is dependent on the crystal value and loading conditions.
7.  $I_{XTAL}$  is the oscillator bias current out of the XTAL pin with both EXTAL and XTAL pins grounded. This is the maximum current during startup of the oscillator. The current after oscillation is typically in the 2–3 mA range and is dependent on the load and series resistance of the crystal. Test circuit is shown in [Figure 7](#).

**Table 15. Selectable load capacitance**

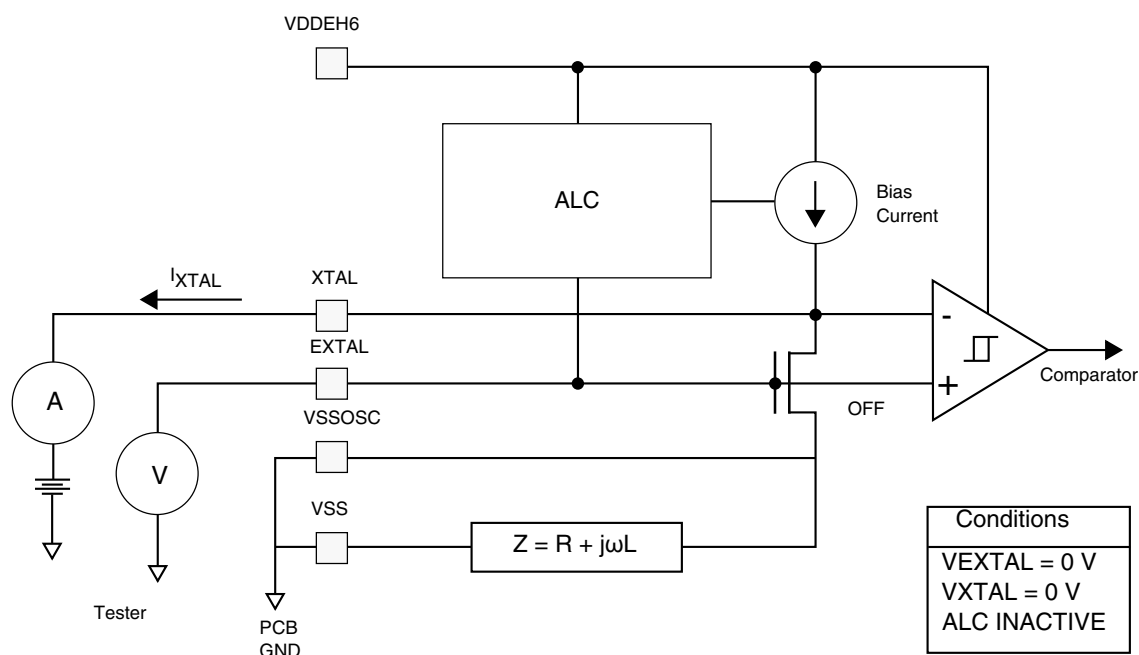
| load_cap_sel[4:0] from DCF record | Load capacitance <sup>1, 2</sup> (pF) |
|-----------------------------------|---------------------------------------|
| 00000                             | 1.8                                   |
| 00001                             | 2.8                                   |
| 00010                             | 3.7                                   |
| 00011                             | 4.6                                   |
| 00100                             | 5.6                                   |
| 00101                             | 6.5                                   |
| 00110                             | 7.4                                   |
| 00111                             | 8.4                                   |
| 01000                             | 9.3                                   |
| 01001                             | 10.2                                  |
| 01010                             | 11.2                                  |

Table continues on the next page...

**Table 15. Selectable load capacitance (continued)**

| load_cap_sel[4:0] from DCF record | Load capacitance <sup>1, 2</sup> (pF) |
|-----------------------------------|---------------------------------------|
| 01011                             | 12.1                                  |
| 01100                             | 13.0                                  |
| 01101                             | 13.9                                  |
| 01110                             | 14.9                                  |
| 01111                             | 15.8                                  |

1. Values are determined from simulation across process corners and voltage and temperature variation. Capacitance values vary  $\pm 12\%$  across process,  $0.25\%$  across voltage, and no variation across temperature.
2. Values in this table do not include the die and package capacitances given by  $C_{S\_XTAI}/C_{S\_EXTAI}$  in Table 14.



### Figure 7. Test circuit

### Table 16. Internal RC (IRC) oscillator electrical specifications

| Symbol                     | Parameter               | Conditions | Value |     |     | Unit |
|----------------------------|-------------------------|------------|-------|-----|-----|------|
|                            |                         |            | Min   | Typ | Max |      |
| $f_{\text{Target}}$        | IRC target frequency    | —          | —     | 16  | —   | MHz  |
| $\delta f_{\text{var\_T}}$ | IRC frequency variation | T < 150 °C | −8    | —   | 8   | %    |

### 3.8 Analog-to-Digital Converter (ADC) electrical specifications

### 3.8.1 Enhanced Queued Analog-to-Digital Converter (eQADC)

**Table 17. eQADC conversion specifications (operating)**

| Symbol      | Parameter                                                    | Value            |                       | Unit                 |
|-------------|--------------------------------------------------------------|------------------|-----------------------|----------------------|
|             |                                                              | Min              | Max                   |                      |
| $f_{ADCLK}$ | ADC Clock (ADCLK) Frequency                                  | 2                | 33                    | MHz                  |
| CC          | Conversion Cycles                                            | 2 + 13           | 128 + 15 <sup>1</sup> | ADCLK cycles         |
| $T_{SR}$    | Stop Mode Recovery Time <sup>2</sup>                         | 10               | —                     | μs                   |
| —           | Resolution <sup>3</sup>                                      | 1.25             | —                     | mV                   |
| INL         | INL: 16.5 MHz eQADC clock <sup>4</sup>                       | −4               | 4                     | LSB <sup>5</sup>     |
|             | INL: 33 MHz eQADC clock <sup>4</sup>                         | −6               | 6                     | LSB                  |
| DNL         | DNL: 16.5 MHz eQADC clock <sup>4</sup>                       | −3               | 3                     | LSB                  |
|             | DNL: 33 MHz eQADC clock <sup>4</sup>                         | −3               | 3                     | LSB                  |
| OFFNC       | Offset Error without Calibration                             | 0                | 140                   | LSB                  |
| OFFWC       | Offset Error with Calibration                                | −8               | 8                     | LSB                  |
| GAINNC      | Full Scale Gain Error without Calibration                    | −150             | 0                     | LSB                  |
| GAINWC      | Full Scale Gain Error with Calibration                       | −8               | 8                     | LSB                  |
| $I_{INJ}$   | Disruptive Input Injection Current <sup>6, 7, 8, 9</sup>     | −3               | 3                     | mA                   |
| $E_{INJ}$   | Incremental Error due to injection current <sup>10, 11</sup> | —                | +4                    | Counts               |
| TUE         | TUE value <sup>12, 13</sup> (with calibration)               | —                | ±8                    | Counts               |
| GAINVGA1    | Variable gain amplifier accuracy (gain = 1) <sup>14</sup>    | -                | -                     | Counts <sup>16</sup> |
|             | INL, 16.5 MHz ADC                                            | −4               | 4                     |                      |
|             | INL, 33 MHz ADC                                              | −8               | 8                     |                      |
|             | DNL, 16.5 MHz ADC                                            | −3 <sup>15</sup> | 3 <sup>15</sup>       |                      |
|             | DNL, 33 MHz ADC                                              | −3 <sup>15</sup> | 3 <sup>15</sup>       |                      |
| GAINVGA2    | Variable gain amplifier accuracy (gain = 2) <sup>14</sup>    | -                | -                     | Counts               |
|             | INL, 16.5 MHz ADC                                            | −5               | 5                     |                      |
|             | INL, 33 MHz ADC                                              | −8               | 8                     |                      |
|             | DNL, 16.5 MHz ADC                                            | −3               | 3                     |                      |
|             | DNL, 33 MHz ADC                                              | −3               | 3                     |                      |
| GAINVGA4    | Variable gain amplifier accuracy (gain = 4) <sup>14</sup>    | -                | -                     | Counts               |
|             | INL, 16.5 MHz ADC                                            | −7               | 7                     |                      |
|             | INL, 33 MHz ADC                                              | −8               | 8                     |                      |
|             | DNL, 16.5 MHz ADC                                            | −4               | 4                     |                      |
|             | DNL, 33 MHz ADC                                              | −4               | 4                     |                      |
| $I_{ADC}$   | Current consumption per ADC (two ADCs per EQADC)             | —                | 10                    | mA                   |
| $I_{ADR}$   | Reference voltage current consumption per EQADC              | —                | 200                   | μA                   |

- 128 sampling cycles (LST=128), differential conversion, pregain of x4
- Stop mode recovery time is the time from the setting of either of the enable bits in the ADC Control Register to the time that the ADC is ready to perform conversions. Delay from power up to full accuracy = 8 ms.
- At  $V_{RH\_EQ} - V_{RL\_EQ} = 5.12$  V, one count = 1.25 mV without using pregain. Based on 12-bit conversion result; does not account for AC and DC errors
- INL and DNL are tested from  $V_{RL} + 50$  LSB to  $V_{RH} - 50$  LSB.

5. At  $V_{RH\_EQ} - V_{RL\_EQ} = 5.12\text{ V}$ , one LSB = 1.25 mV.
6. Below disruptive current conditions, the channel being stressed has conversion values of \$3FF for analog inputs greater than  $V_{RH}$  and \$000 for values less than  $V_{RL}$ . Other channels are not affected by non-disruptive conditions.
7. Exceeding limit may cause conversion error on stressed channels and on unstressed channels. Transitions within the limit do not affect device reliability or cause permanent damage.
8. Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values using  $V_{POSCLAMP} = V_{DDA} + 0.5\text{ V}$  and  $V_{NEGCLAMP} = -0.3\text{ V}$ , then use the larger of the calculated values.
9. Condition applies to two adjacent pins at injection limits.
10. Performance expected with production silicon.
11. All channels have same  $10\text{ k}\Omega < R_s < 100\text{ k}\Omega$ . Channel under test has  $R_s = 10\text{ k}\Omega$ ,  $I_{INJ} = I_{INJMAX}, I_{INJMIN}$ .
12. The TUE specification is always less than the sum of the INL, DNL, offset, and gain errors due to cancelling errors.
13. TUE, Gain, and Offset specifications do not apply to differential conversions.
14. Variable gain is controlled by setting the PRE\_GAIN bits in the ADC\_ACR1-8 registers to select a gain factor of  $\times 1$ ,  $\times 2$ , or  $\times 4$ . Settings are for differential input only. Tested at  $\times 1$  gain. Values for other settings are guaranteed as indicated.
15. Guaranteed 10-bit monotonicity.
16. At  $V_{RH\_EQ} - V_{RL\_EQ} = 5.12\text{ V}$ , one LSB = 1.25 mV.

### 3.8.2 Sigma-Delta ADC (SDADC)

The SDADC is a 16-bit Sigma-Delta analog-to-digital converter with a 333 Ksps maximum output conversion rate.

#### NOTE

The voltage range is 4.5 V to 5.5 V for SDADC specifications, except where noted otherwise.

**Table 18. SDADC electrical specifications**

| Symbol                             | Parameter                                                                                                             | Conditions                                                                   | Value                     |      |                     | Unit |
|------------------------------------|-----------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------|---------------------------|------|---------------------|------|
|                                    |                                                                                                                       |                                                                              | Min                       | Typ  | Max                 |      |
| V <sub>IN</sub>                    | ADC input signal                                                                                                      | —                                                                            | 0                         | —    | V <sub>DDA_SD</sub> | V    |
| V <sub>IN_PK2PK</sub> <sup>1</sup> | Input range peak to peak<br><br>V <sub>IN_PK2PK</sub> = V <sub>INP</sub> <sup>2</sup> – V <sub>INM</sub> <sup>3</sup> | Single ended<br>V <sub>INM</sub> = V <sub>RL_SD</sub>                        | V <sub>RH_SD</sub> /GAIN  |      |                     | V    |
|                                    |                                                                                                                       | Single ended<br>V <sub>INM</sub> = 0.5*V <sub>RH_SD</sub><br>GAIN = 1        | ±0.5*V <sub>RH_SD</sub>   |      |                     |      |
|                                    |                                                                                                                       | Single ended<br>V <sub>INM</sub> = 0.5*V <sub>RH_SD</sub><br>GAIN = 2,4,8,16 | ±V <sub>RH_SD</sub> /GAIN |      |                     |      |
|                                    |                                                                                                                       | Differential<br>0 < V <sub>IN</sub> < V <sub>DDEx</sub>                      | ±V <sub>RH_SD</sub> /GAIN |      |                     |      |
| f <sub>ADCD_M</sub>                | SD clock frequency <sup>4</sup>                                                                                       | —                                                                            | 4                         | 14.4 | 16                  | MHz  |
| f <sub>ADCD_S</sub>                | Conversion rate                                                                                                       | —                                                                            | —                         | —    | 333                 | Ksps |
| —                                  | Oversampling ratio                                                                                                    | Internal modulator                                                           | 24                        | —    | 256                 | —    |
| RESOLUTION                         | SD register resolution <sup>5</sup>                                                                                   | 2's complement notation                                                      | 16                        |      |                     | bit  |

Table continues on the next page...

Table 18. SDADC electrical specifications (continued)

| Symbol                 | Parameter                                            | Conditions                                                                                                                                        | Value |                                |     | Unit |
|------------------------|------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------|-------|--------------------------------|-----|------|
|                        |                                                      |                                                                                                                                                   | Min   | Typ                            | Max |      |
| GAIN                   | ADC gain                                             | Defined through SDADC_MCR[PGAN]. Only integer powers of 2 are valid gain values.                                                                  | 1     | —                              | 16  | —    |
| $\delta_{\text{GAIN}}$ | Absolute value of the ADC gain error <sup>6, 7</sup> | Before calibration (applies to gain setting = 1)                                                                                                  | —     | —                              | 1.5 | %    |
|                        |                                                      | After calibration<br>$\Delta V_{\text{RH\_SD}} < 5\%$ , $\Delta V_{\text{DDA\_SD}} < 10\%$<br>$\Delta T_{\text{J}} < 50\text{ }^{\circ}\text{C}$  | —     | —                              | 5   | mV   |
|                        |                                                      | After calibration<br>$\Delta V_{\text{RH\_SD}} < 5\%$ , $\Delta V_{\text{DDA\_SD}} < 10\%$<br>$\Delta T_{\text{J}} < 100\text{ }^{\circ}\text{C}$ | —     | —                              | 7.5 |      |
|                        |                                                      | After calibration<br>$\Delta V_{\text{RH\_SD}} < 5\%$ , $\Delta V_{\text{DDA\_SD}} < 10\%$<br>$\Delta T_{\text{J}} < 150\text{ }^{\circ}\text{C}$ | —     | —                              | 10  |      |
| $V_{\text{OFFSET}}$    | Conversion offset <sup>6, 7</sup>                    | Before calibration (applies to all gain settings: 1, 2, 4, 8, 16)                                                                                 | —     | $10 \cdot (1 + 1/\text{gain})$ | 20  | mV   |
|                        |                                                      | After calibration<br>$\Delta V_{\text{DDA\_SD}} < 10\%$<br>$\Delta T_{\text{J}} < 50\text{ }^{\circ}\text{C}$                                     | —     | —                              | 5   |      |
|                        |                                                      | After calibration<br>$\Delta V_{\text{DDA\_SD}} < 10\%$<br>$\Delta T_{\text{J}} < 100\text{ }^{\circ}\text{C}$                                    | —     | —                              | 7.5 |      |
|                        |                                                      | After calibration<br>$\Delta V_{\text{DDA\_SD}} < 10\%$<br>$\Delta T_{\text{J}} < 150\text{ }^{\circ}\text{C}$                                    | —     | —                              | 10  |      |

Table continues on the next page...

**Table 18. SDADC electrical specifications (continued)**

| Symbol                 | Parameter                                                        | Conditions                                                                                                  | Value |     |     | Unit |
|------------------------|------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------|-------|-----|-----|------|
|                        |                                                                  |                                                                                                             | Min   | Typ | Max |      |
| SNR <sub>DIFF150</sub> | Signal to noise ratio in differential mode, 150 Ksps output rate | 4.5 V < V <sub>DDA_SD</sub> < 5.5 V <sup>8,9</sup><br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub><br>GAIN = 1  | 80    | —   | —   | dB   |
|                        |                                                                  | 4.5 V < V <sub>DDA_SD</sub> < 5.5 V <sup>8,9</sup><br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub><br>GAIN = 2  | 77    | —   | —   |      |
|                        |                                                                  | 4.5 V < V <sub>DDA_SD</sub> < 5.5 V <sup>8,9</sup><br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub><br>GAIN = 4  | 74    | —   | —   |      |
|                        |                                                                  | 4.5 V < V <sub>DDA_SD</sub> < 5.5 V <sup>8,9</sup><br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub><br>GAIN = 8  | 71    | —   | —   |      |
|                        |                                                                  | 4.5 V < V <sub>DDA_SD</sub> < 5.5 V <sup>8,9</sup><br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub><br>GAIN = 16 | 68    | —   | —   |      |
|                        |                                                                  |                                                                                                             |       |     |     |      |
| SNR <sub>DIFF333</sub> | Signal to noise ratio in differential mode, 333 Ksps output rate | 4.5 V < V <sub>DDA_SD</sub> < 5.5 V <sup>8,9</sup><br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub><br>GAIN = 1  | 71    | —   | —   | dB   |
|                        |                                                                  | 4.5 V < V <sub>DDA_SD</sub> < 5.5 V <sup>8,9</sup><br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub><br>GAIN = 2  | 70    | —   | —   |      |
|                        |                                                                  | 4.5 V < V <sub>DDA_SD</sub> < 5.5 V <sup>8,9</sup><br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub><br>GAIN = 4  | 68    | —   | —   |      |
|                        |                                                                  | 4.5 V < V <sub>DDA_SD</sub> < 5.5 V <sup>8,9</sup><br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub><br>GAIN = 8  | 65    | —   | —   |      |
|                        |                                                                  | 4.5 V < V <sub>DDA_SD</sub> < 5.5 V <sup>8,9</sup><br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub><br>GAIN = 16 | 62    | —   | —   |      |
|                        |                                                                  |                                                                                                             |       |     |     |      |

Table continues on the next page...

**Table 18. SDADC electrical specifications (continued)**

| Symbol                   | Parameter                                                                       | Conditions                                                                                                  | Value |     |     | Unit |
|--------------------------|---------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------|-------|-----|-----|------|
|                          |                                                                                 |                                                                                                             | Min   | Typ | Max |      |
| SNR <sub>SE150</sub>     | Signal to noise ratio in single ended mode, 150 Ksps output rate                | 4.5 V < V <sub>DDA_SD</sub> < 5.5 V <sup>8,9</sup><br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub><br>GAIN = 1  | 72    | —   | —   | dB   |
|                          |                                                                                 | 4.5 V < V <sub>DDA_SD</sub> < 5.5 V <sup>8,9</sup><br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub><br>GAIN = 2  | 69    | —   | —   |      |
|                          |                                                                                 | 4.5 V < V <sub>DDA_SD</sub> < 5.5 V <sup>8,9</sup><br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub><br>GAIN = 4  | 66    | —   | —   |      |
|                          |                                                                                 | 4.5 V < V <sub>DDA_SD</sub> < 5.5 V <sup>8,9</sup><br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub><br>GAIN = 8  | 62    | —   | —   |      |
|                          |                                                                                 | 4.5 V < V <sub>DDA_SD</sub> < 5.5 V <sup>8,9</sup><br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub><br>GAIN = 16 | 54    | —   | —   |      |
|                          |                                                                                 |                                                                                                             |       |     |     |      |
| SINAD <sub>DIFF150</sub> | Signal to noise and distortion ratio in differential mode, 150 Ksps output rate | Gain = 1<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>                 | 72    | —   | —   | dBFS |
|                          |                                                                                 | Gain = 2<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>                 | 72    | —   | —   |      |
|                          |                                                                                 | Gain = 4<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>                 | 69    | —   | —   |      |
|                          |                                                                                 | Gain = 8<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>                 | 68.8  | —   | —   |      |
|                          |                                                                                 | Gain = 16<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>                | 64.8  | —   | —   |      |
|                          |                                                                                 |                                                                                                             |       |     |     |      |

Table continues on the next page...

**Table 18. SDADC electrical specifications (continued)**

| Symbol                   | Parameter                                                                       | Conditions                                                                                   | Value |     |     | Unit |
|--------------------------|---------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------|-------|-----|-----|------|
|                          |                                                                                 |                                                                                              | Min   | Typ | Max |      |
| SINAD <sub>DIFF333</sub> | Signal to noise and distortion ratio in differential mode, 333 Ksps output rate | Gain = 1<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 66    | —   | —   | dBFS |
|                          |                                                                                 | Gain = 2<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 66    | —   | —   |      |
|                          |                                                                                 | Gain = 4<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 63    | —   | —   |      |
|                          |                                                                                 | Gain = 8<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 62    | —   | —   |      |
|                          |                                                                                 | Gain = 16<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub> | 59    | —   | —   |      |
|                          |                                                                                 |                                                                                              |       |     |     |      |
|                          |                                                                                 |                                                                                              |       |     |     |      |
| SINAD <sub>SE150</sub>   | Signal to noise and distortion ratio in single-ended mode, 150 Ksps output rate | Gain = 1<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 66    | —   | —   | dBFS |
|                          |                                                                                 | Gain = 2<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 66    | —   | —   |      |
|                          |                                                                                 | Gain = 4<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 63    | —   | —   |      |
|                          |                                                                                 | Gain = 8<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 62    | —   | —   |      |
|                          |                                                                                 | Gain = 16<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub> | 54    | —   | —   |      |
|                          |                                                                                 |                                                                                              |       |     |     |      |
|                          |                                                                                 |                                                                                              |       |     |     |      |

Table continues on the next page...

**Table 18. SDADC electrical specifications (continued)**

| Symbol                 | Parameter                                                            | Conditions                                                                                   | Value |     |     | Unit |
|------------------------|----------------------------------------------------------------------|----------------------------------------------------------------------------------------------|-------|-----|-----|------|
|                        |                                                                      |                                                                                              | Min   | Typ | Max |      |
| THD <sub>DIFF150</sub> | Total harmonic distortion in differential mode, 150 Ksps output rate | Gain = 1<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 65    | —   | —   | dBFS |
|                        |                                                                      | Gain = 2<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 68    | —   | —   |      |
|                        |                                                                      | Gain = 4<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 74    | —   | —   |      |
|                        |                                                                      | Gain = 8<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 80    | —   | —   |      |
|                        |                                                                      | Gain = 16<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub> | 80    | —   | —   |      |
|                        |                                                                      |                                                                                              |       |     |     |      |
|                        |                                                                      |                                                                                              |       |     |     |      |
|                        |                                                                      |                                                                                              |       |     |     |      |
| THD <sub>DIFF333</sub> | Total harmonic distortion in differential mode, 333 Ksps output rate | Gain = 1<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 65    | —   | —   | dBFS |
|                        |                                                                      | Gain = 2<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 68    | —   | —   |      |
|                        |                                                                      | Gain = 4<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 74    | —   | —   |      |
|                        |                                                                      | Gain = 8<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 80    | —   | —   |      |
|                        |                                                                      | Gain = 16<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub> | 80    | —   | —   |      |
|                        |                                                                      |                                                                                              |       |     |     |      |
|                        |                                                                      |                                                                                              |       |     |     |      |
|                        |                                                                      |                                                                                              |       |     |     |      |

Table continues on the next page...

Table 18. SDADC electrical specifications (continued)

| Symbol                | Parameter                                                            | Conditions                                                                                   | Value |                       |                             | Unit |
|-----------------------|----------------------------------------------------------------------|----------------------------------------------------------------------------------------------|-------|-----------------------|-----------------------------|------|
|                       |                                                                      |                                                                                              | Min   | Typ                   | Max                         |      |
| THD <sub>SE150</sub>  | Total harmonic distortion in single-ended mode, 150 Ksps output rate | Gain = 1<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 68    | —                     | —                           | dBFS |
|                       |                                                                      | Gain = 2<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 68    | —                     | —                           |      |
|                       |                                                                      | Gain = 4<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 66    | —                     | —                           |      |
|                       |                                                                      | Gain = 8<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub>  | 68    | —                     | —                           |      |
|                       |                                                                      | Gain = 16<br>4.5 V < V <sub>DDA_SD</sub> < 5.5 V<br>V <sub>RH_SD</sub> = V <sub>DDA_SD</sub> | 68    | —                     | —                           |      |
|                       |                                                                      |                                                                                              |       |                       |                             |      |
| SFDR                  | Spurious free dynamic range                                          | Any GAIN                                                                                     | 60    | —                     | —                           | dB   |
| Z <sub>DIFF</sub>     | Differential input impedance <sup>10, 11</sup>                       | GAIN = 1                                                                                     | 1000  | 1250                  | 1500                        | kΩ   |
|                       |                                                                      | GAIN = 2                                                                                     | 600   | 800                   | 1000                        |      |
|                       |                                                                      | GAIN = 4                                                                                     | 300   | 400                   | 500                         |      |
|                       |                                                                      | GAIN = 8                                                                                     | 200   | 250                   | 300                         |      |
|                       |                                                                      | GAIN = 16                                                                                    | 200   | 250                   | 300                         |      |
| Z <sub>CM</sub>       | Common Mode input impedance <sup>11, 12</sup>                        | GAIN = 1                                                                                     | 1400  | 1800                  | 2200                        | kΩ   |
|                       |                                                                      | GAIN = 2                                                                                     | 1000  | 1300                  | 1600                        |      |
|                       |                                                                      | GAIN = 4                                                                                     | 700   | 950                   | 1150                        |      |
|                       |                                                                      | GAIN = 8                                                                                     | 500   | 650                   | 800                         |      |
|                       |                                                                      | GAIN = 16                                                                                    | 500   | 650                   | 800                         |      |
| R <sub>BIAS</sub>     | Bare bias resistance                                                 | —                                                                                            | 110   | 144                   | 180                         | kΩ   |
| ΔV <sub>INTCM</sub>   | Common Mode input reference voltage <sup>13</sup>                    | —                                                                                            | −12   | —                     | +12                         | %    |
| V <sub>BIAS</sub>     | Bias voltage                                                         | —                                                                                            | —     | V <sub>RH_SD</sub> /2 | —                           | V    |
| δV <sub>BIAS</sub>    | Bias voltage accuracy                                                | —                                                                                            | −2.5  | —                     | +2.5                        | %    |
| CMRR                  | Common mode rejection ratio                                          | —                                                                                            | 20    | —                     | —                           | dB   |
| R <sub>Caaf</sub>     | Anti-aliasing filter                                                 | External series resistance                                                                   | —     | —                     | 20                          | kΩ   |
|                       |                                                                      | Filter capacitances                                                                          | 220   | —                     | —                           | pF   |
| f <sub>PASSBAND</sub> | Pass band <sup>9</sup>                                               | —                                                                                            | 0.01  | —                     | 0.333 * f <sub>ADCD_S</sub> | kHz  |
| δ <sub>RIPPLE</sub>   | Pass band ripple <sup>14</sup>                                       | 0.333 * f <sub>ADCD_S</sub>                                                                  | −1    | —                     | 1                           | %    |

Table continues on the next page...

Table 18. SDADC electrical specifications (continued)

| Symbol                  | Parameter                                                                                  | Conditions                                             | Value                     |                              |                                              | Unit          |
|-------------------------|--------------------------------------------------------------------------------------------|--------------------------------------------------------|---------------------------|------------------------------|----------------------------------------------|---------------|
|                         |                                                                                            |                                                        | Min                       | Typ                          | Max                                          |               |
| $F_{\text{rolloff}}$    | Stop band attenuation                                                                      | $[0.5 * f_{\text{ADCD\_S}}, 1.0 * f_{\text{ADCD\_S}}]$ | 40                        | —                            | —                                            | dB            |
|                         |                                                                                            | $[1.0 * f_{\text{ADCD\_S}}, 1.5 * f_{\text{ADCD\_S}}]$ | 45                        | —                            | —                                            |               |
|                         |                                                                                            | $[1.5 * f_{\text{ADCD\_S}}, 2.0 * f_{\text{ADCD\_S}}]$ | 50                        | —                            | —                                            |               |
|                         |                                                                                            | $[2.0 * f_{\text{ADCD\_S}}, 2.5 * f_{\text{ADCD\_S}}]$ | 55                        | —                            | —                                            |               |
|                         |                                                                                            | $[2.5 * f_{\text{ADCD\_S}}, f_{\text{ADCD\_M}}/2]$     | 60                        | —                            | —                                            |               |
| $\delta_{\text{GROUP}}$ | Group delay                                                                                | Within pass band: Tclk is $f_{\text{ADCD\_M}} / 2$     | —                         | —                            | —                                            | —             |
|                         |                                                                                            | OSR = 24                                               | —                         | —                            | 235.5                                        | Tclk          |
|                         |                                                                                            | OSR = 28                                               | —                         | —                            | 275                                          |               |
|                         |                                                                                            | OSR = 32                                               | —                         | —                            | 314.5                                        |               |
|                         |                                                                                            | OSR = 36                                               | —                         | —                            | 354                                          |               |
|                         |                                                                                            | OSR = 40                                               | —                         | —                            | 393.5                                        |               |
|                         |                                                                                            | OSR = 44                                               | —                         | —                            | 433                                          |               |
|                         |                                                                                            | OSR = 48                                               | —                         | —                            | 472.5                                        |               |
|                         |                                                                                            | OSR = 56                                               | —                         | —                            | 551.5                                        |               |
|                         |                                                                                            | OSR = 64                                               | —                         | —                            | 630.5                                        |               |
|                         |                                                                                            | OSR = 72                                               | —                         | —                            | 709.5                                        |               |
|                         |                                                                                            | OSR = 75                                               | —                         | —                            | 696                                          |               |
|                         |                                                                                            | OSR = 80                                               | —                         | —                            | 788.5                                        |               |
|                         |                                                                                            | OSR = 88                                               | —                         | —                            | 867.5                                        |               |
|                         |                                                                                            | OSR = 96                                               | —                         | —                            | 946.5                                        |               |
|                         |                                                                                            | OSR = 112                                              | —                         | —                            | 1104.5                                       |               |
|                         |                                                                                            | OSR = 128                                              | —                         | —                            | 1262.5                                       |               |
|                         |                                                                                            | OSR = 144                                              | —                         | —                            | 1420.5                                       |               |
|                         |                                                                                            | OSR = 160                                              | —                         | —                            | 1578.5                                       |               |
|                         |                                                                                            | OSR = 176                                              | —                         | —                            | 1736.5                                       |               |
|                         |                                                                                            | OSR = 192                                              | —                         | —                            | 1894.5                                       |               |
|                         |                                                                                            | OSR = 224                                              | —                         | —                            | 2210.5                                       |               |
|                         |                                                                                            | OSR = 256                                              | —                         | —                            | 2526.5                                       |               |
|                         |                                                                                            | Distortion within pass band                            | $-0.5/f_{\text{ADCD\_S}}$ | —                            | $+0.5/f_{\text{ADCD\_S}}$                    | —             |
| $f_{\text{HIGH}}$       | High pass filter 3 dB frequency                                                            | Enabled                                                | —                         | $10e-5 * f_{\text{ADCD\_S}}$ | —                                            | —             |
| $t_{\text{STARTUP}}$    | Startup time from power down state                                                         | —                                                      | —                         | —                            | 100                                          | $\mu\text{s}$ |
| $t_{\text{LATENCY}}$    | Latency between input data and converted data when input mux does not change <sup>15</sup> | HPF = ON                                               | —                         | —                            | $\delta_{\text{GROUP}} + f_{\text{ADCD\_S}}$ | —             |
|                         |                                                                                            | HPF = OFF                                              | —                         | —                            | $\delta_{\text{GROUP}}$                      |               |

Table continues on the next page...

Table 18. SDADC electrical specifications (continued)

| Symbol                  | Parameter                                                      | Conditions                                                 | Value |     |                                                              | Unit |
|-------------------------|----------------------------------------------------------------|------------------------------------------------------------|-------|-----|--------------------------------------------------------------|------|
|                         |                                                                |                                                            | Min   | Typ | Max                                                          |      |
| $t_{\text{SETTLING}}$   | Settling time after mux change                                 | Analog inputs are muxed<br>HPF = ON                        | —     | —   | $2 \cdot \delta_{\text{GROUP}} + 3 \cdot f_{\text{ADCD\_S}}$ | —    |
|                         |                                                                | HPF = OFF                                                  | —     | —   | $2 \cdot \delta_{\text{GROUP}} + 2 \cdot f_{\text{ADCD\_S}}$ |      |
| $t_{\text{ODRECOVERY}}$ | Overdrive recovery time                                        | After input comes within range from saturation<br>HPF = ON | —     | —   | $2 \cdot \delta_{\text{GROUP}} + f_{\text{ADCD\_S}}$         | —    |
|                         |                                                                | HPF = OFF                                                  | —     | —   | $2 \cdot \delta_{\text{GROUP}}$                              |      |
| $C_{\text{S\_D}}$       | SDADC sampling capacitance after sampling switch <sup>16</sup> | GAIN = 1, 2, 4, 8                                          | —     | —   | $75 \cdot \text{GAIN}$                                       | fF   |
|                         |                                                                | GAIN = 16                                                  | —     | —   | 600                                                          | fF   |
| $I_{\text{BIAS}}$       | Bias consumption                                               | At least one SDADC enabled                                 | —     | —   | 3.5                                                          | mA   |
| $I_{\text{ADV\_D}}$     | SDADC supply consumption                                       | Per SDADC enabled                                          | —     | —   | 4.325                                                        | mA   |
| $I_{\text{ADR\_D}}$     | SDADC reference current consumption                            | Per SDADC enabled                                          | —     | —   | 20                                                           | μA   |

- For input voltage above the maximum and below the clamp voltage of the input pad, there is no latch-up concern, and the signal will only be “clipped.”
- VINP is the input voltage applied to the positive terminal of the SDADC
- VINM is the input voltage applied to the negative terminal of the SDADC
- Sampling is generated internally  $f_{\text{SAMPLING}} = f_{\text{ADCD\_M}}/2$
- For Gain = 16, SDADC resolution is 15 bit.
- Calibration of gain is possible when gain = 1. Offset Calibration should be done with respect to  $0.5 \cdot V_{\text{RH\_SD}}$  for differential mode and single ended mode with negative input =  $0.5 \cdot V_{\text{RH\_SD}}$ . Offset Calibration should be done with respect to 0 for single ended mode with negative input = 0. Both Offset and Gain Calibration is guaranteed for +/-5% variation of  $V_{\text{RH\_SD}}$ , +/-10% variation of  $V_{\text{DDA\_SD}}$ , +/-50 C temperature variation.
- Offset and gain error due to temperature drift can occur in either direction (+/-) for each of the SDADCs on the device.
- SDADC is functional in the range  $3.6 \text{ V} < V_{\text{DDA\_SD}} < 4.0 \text{ V}$ : SNR parameter degrades by 3 dB. SDADC is functional in the range  $3.0 \text{ V} < V_{\text{RH\_SD}} < 4.0 \text{ V}$ : SNR parameter degrades by 9 dB.
- SNR values guaranteed only if external noise on the ADC input pin is attenuated by the required SNR value in the frequency range of  $f_{\text{ADCD\_M}} - f_{\text{ADCD\_S}}$  to  $f_{\text{ADCD\_M}} + f_{\text{ADCD\_S}}$ , where  $f_{\text{ADCD\_M}}$  is the input sampling frequency and  $f_{\text{ADCD\_S}}$  is the output sample frequency. A proper external input filter should be used to remove any interfering signals in this frequency range.
- Input impedance in differential mode  $Z_{\text{IN}} = Z_{\text{DIFF}}$
- Input impedance given at  $f_{\text{ADCD\_M}} = 16 \text{ MHz}$ . Impedance is inversely proportional to SDADC clock frequency.  $Z_{\text{DIFF}} (f_{\text{ADCD\_M}}) = (16 \text{ MHz} / f_{\text{ADCD\_M}}) \cdot Z_{\text{DIFF}}$ ,  $Z_{\text{CM}} (f_{\text{ADCD\_M}}) = (16 \text{ MHz} / f_{\text{ADCD\_M}}) \cdot Z_{\text{CM}}$ .
- Input impedance in single-ended mode  $Z_{\text{IN}} = (2 \cdot Z_{\text{DIFF}} \cdot Z_{\text{CM}}) / (Z_{\text{DIFF}} + Z_{\text{CM}})$
- $V_{\text{INTCM}}$  is the Common Mode input reference voltage for the SDADC. It has a nominal value of  $(V_{\text{RH\_SD}} - V_{\text{RL\_SD}}) / 2$ .
- The ±1% passband ripple specification is equivalent to  $20 \cdot \log_{10} (0.99) = 0.087 \text{ dB}$ .
- Propagation of the information from the pin to the register CDR[CDATA] and the flags SFR[DFF] and SFR[DFFF] is given by the different modules that must be crossed: delta/sigma filters, high pass filter, FIFO module, and clock domain synchronizers. The time elapsed between data availability at the pin and internal SDADC module registers is given by the following formula, where  $f_{\text{ADCD\_S}}$  is the frequency of the sampling clock,  $f_{\text{ADCD\_M}}$  is the frequency of the modulator, and  $f_{\text{FM\_PER\_CLK}}$  is the frequency of the peripheral bridge clock feeds to the SDADC module:

$$\text{REGISTER LATENCY} = t_{\text{LATENCY}} + 0.5/f_{\text{ADCD\_S}} + 2 (\sim+1)/f_{\text{ADCD\_M}} + 2 (\sim+1)f_{\text{FM\_PER\_CLK}}$$

The (~+1) symbol refers to the number of clock cycles uncertainty (from 0 to 1 clock cycle) to be added due to resynchronization of the signal during clock domain crossing.

## Electrical characteristics

Some further latency may be added by the target module (core, DMA, interrupt) controller to process the data received from the SDADC module.

16. This capacitance does not include pin capacitance, that can be considered together with external capacitance, before sampling switch.

## 3.9 Temperature Sensor

The following table describes the Temperature Sensor electrical characteristics.

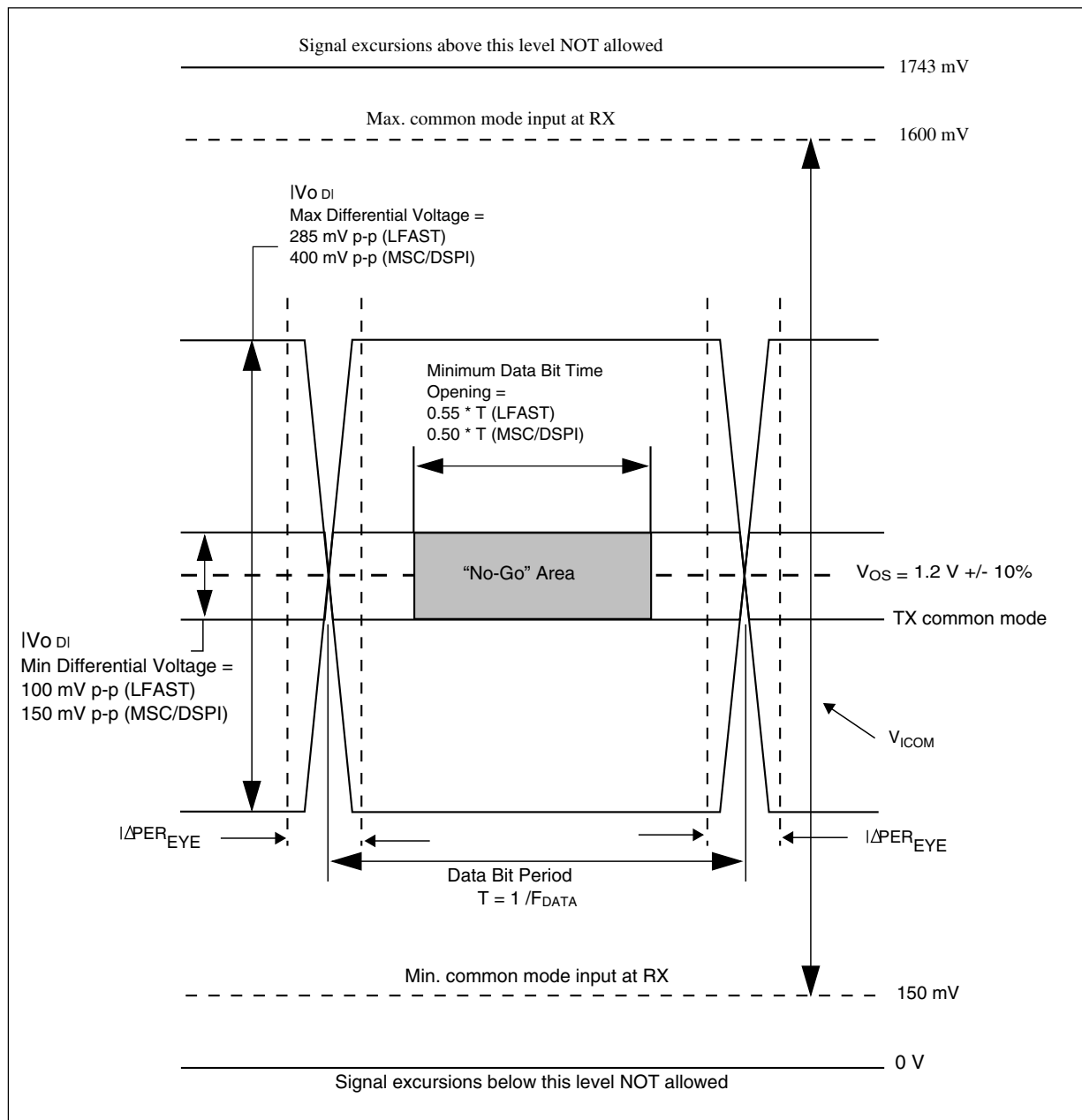
**Table 19. Temperature Sensor electrical characteristics**

| Symbol                 | Parameter                                                  | Conditions                     | Value |      |     | Unit  |
|------------------------|------------------------------------------------------------|--------------------------------|-------|------|-----|-------|
|                        |                                                            |                                | Min   | Typ  | Max |       |
| —                      | Temperature monitoring range                               | —                              | −40   | —    | 150 | °C    |
| T <sub>SENS</sub>      | Sensitivity                                                | —                              | —     | 5.18 | —   | mV/°C |
| T <sub>ACC</sub>       | Accuracy                                                   | −40°C < T <sub>J</sub> < 150°C | −5    | —    | 5   | °C    |
| I <sub>TEMP_SENS</sub> | V <sub>DDA_EQA</sub> power supply current, per Temp Sensor | —                              | —     | —    | 700 | μA    |

## 3.10 LVDS Fast Asynchronous Serial Transmission (LFAST) pad electrical characteristics

The LFAST pad electrical characteristics apply to the SIPI interface on the chip. The same LVDS pad is used for the Microsecond Channel (MSC) and DSPI LVDS interfaces, with different characteristics given in the following tables.

### 3.10.1 LFAST interface timing diagrams



**Figure 8. LFAST and MSC/DSPI LVDS timing definition**

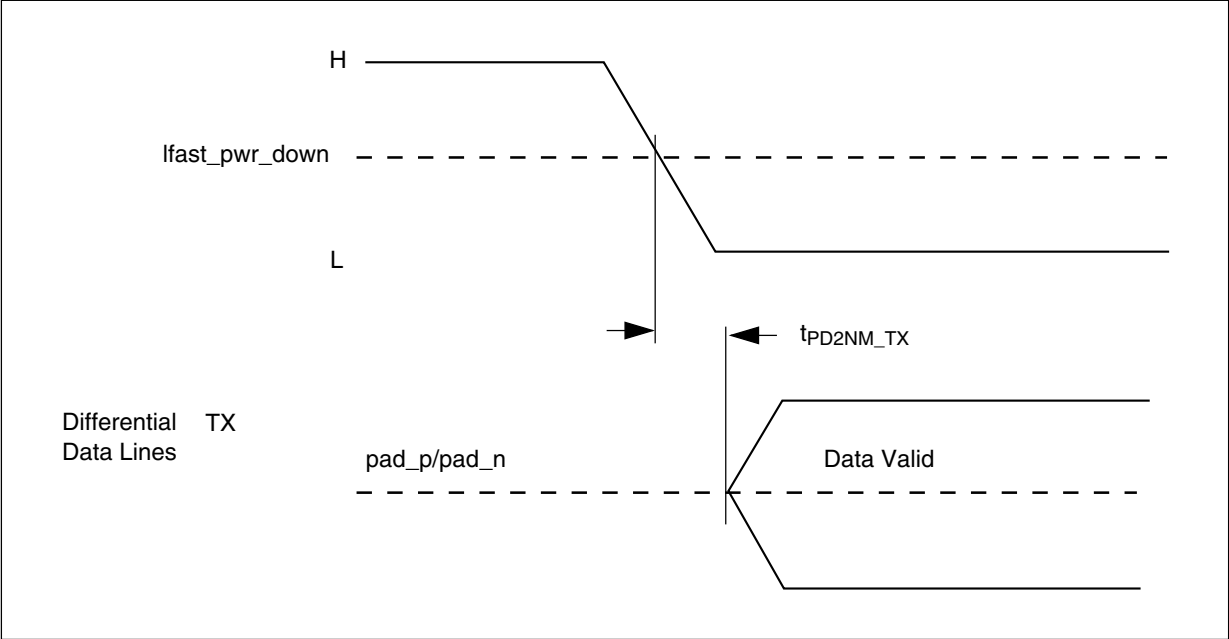


Figure 9. Power-down exit time

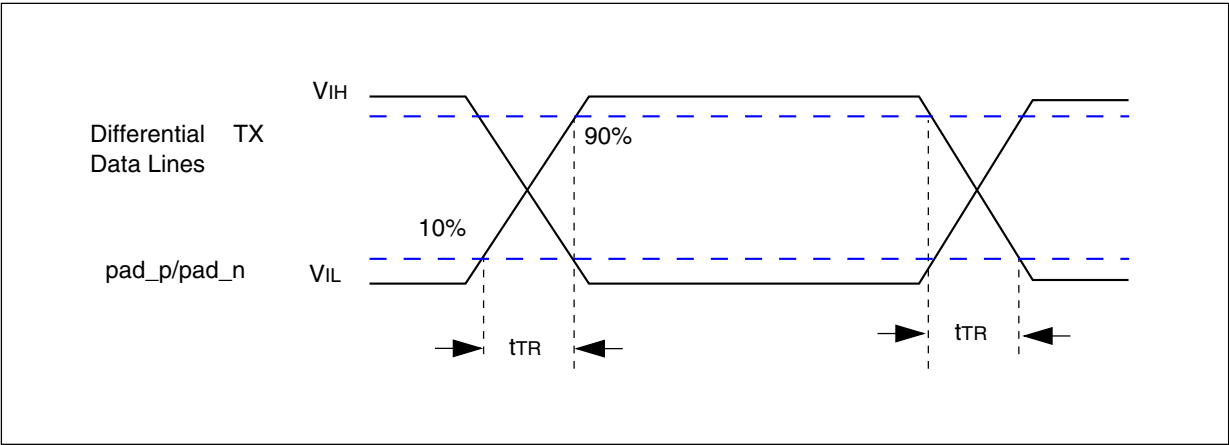


Figure 10. Rise/fall time

3.10.2 LFAST and MSC/DSPI LVDS interface electrical characteristics

The following table contains the electrical characteristics for the LFAST interface.

Table 20. LVDS pad startup and receiver electrical characteristics<sup>1</sup>

| Symbol                 | Parameter                                        | Conditions | Value |     |     | Unit |
|------------------------|--------------------------------------------------|------------|-------|-----|-----|------|
|                        |                                                  |            | Min   | Typ | Max |      |
| STARTUP <sup>2,3</sup> |                                                  |            |       |     |     |      |
| t <sub>STRT_BIAS</sub> | Bias current reference startup time <sup>4</sup> | —          | —     | 0.5 | 4   | μs   |

Table continues on the next page...

**Table 20. LVDS pad startup and receiver electrical characteristics<sup>1</sup> (continued)**

| Symbol                                               | Parameter                                                         | Conditions                                | Value             |     |                   | Unit     |
|------------------------------------------------------|-------------------------------------------------------------------|-------------------------------------------|-------------------|-----|-------------------|----------|
|                                                      |                                                                   |                                           | Min               | Typ | Max               |          |
| $t_{PD2NM\_TX}$                                      | Transmitter startup time (power down to Normal mode) <sup>5</sup> | —                                         | —                 | 0.4 | 2.75              | $\mu s$  |
| $t_{SM2NM\_TX}$                                      | Transmitter startup time (Sleep mode to Normal mode) <sup>6</sup> | Not applicable to the MSC/DSPI LVDS pad   | —                 | 0.2 | 0.5               | $\mu s$  |
| $t_{PD2NM\_RX}$                                      | Receiver startup time (power down to Normal mode) <sup>7</sup>    | —                                         | —                 | 20  | 40                | ns       |
| $t_{PD2SM\_RX}$                                      | Receiver startup time (power down to Sleep mode) <sup>8</sup>     | Not applicable to the MSC/DSPI LVDS pad   | —                 | 20  | 50                | ns       |
| $I_{LVDS\_BIAS}$                                     | LVDS bias current consumption                                     | Tx or Rx enabled                          | —                 | —   | 0.95              | mA       |
| <b>TRANSMISSION LINE CHARACTERISTICS (PCB Track)</b> |                                                                   |                                           |                   |     |                   |          |
| $Z_0$                                                | Transmission line characteristic impedance                        | —                                         | 47.5              | 50  | 52.5              | $\Omega$ |
| $Z_{DIFF}$                                           | Transmission line differential impedance                          | —                                         | 95                | 100 | 105               | $\Omega$ |
| <b>RECEIVER</b>                                      |                                                                   |                                           |                   |     |                   |          |
| $V_{ICOM}$                                           | Common mode voltage                                               | —                                         | 0.15 <sup>9</sup> | —   | 1.6 <sup>10</sup> | V        |
| $ \Delta V_{II} $                                    | Differential input voltage                                        | —                                         | 100               | —   | —                 | mV       |
| $V_{HYS}$                                            | Input hysteresis                                                  | —                                         | 25                | —   | —                 | mV       |
| $R_{IN}$                                             | Terminating resistance                                            | $V_{DDEH} = 3.0\text{ V to }5.5\text{ V}$ | 80                | 125 | 150               | $\Omega$ |
| $C_{IN}$                                             | Differential input capacitance <sup>11</sup>                      | —                                         | —                 | 3.5 | 6.0               | pF       |
| $I_{LVDS\_RX}$                                       | Receiver DC current consumption                                   | Enabled                                   | —                 | —   | 0.5               | mA       |

1. The LVDS pad startup and receiver electrical characteristics in this table apply to both the LFAST and the MSC/DSPI LVDS pad except where noted in the conditions.
2. All startup times are defined after a 2 peripheral bridge clock delay from writing to the corresponding enable bit in the LVDS control registers (LCR) of the LFAST and High-Speed Debug modules.
3. Startup times are valid for the maximum external loads CL defined in both the LFAST/HSD and MSC/DSPI transmitter electrical characteristic tables.
4. Bias startup time is defined as the time taken by the current reference block to reach the settling bias current after being enabled.
5. Total transmitter startup time from power down to normal mode is  $t_{STRT\_BIAS} + t_{PD2NM\_TX} + 2$  peripheral bridge clock periods.
6. Total transmitter startup time from sleep mode to normal mode is  $t_{SM2NM\_TX} + 2$  peripheral bridge clock periods. Bias block remains enabled in sleep mode.
7. Total receiver startup time from power down to normal mode is  $t_{STRT\_BIAS} + t_{PD2NM\_RX} + 2$  peripheral bridge clock periods.
8. Total receiver startup time from power down to sleep mode is  $t_{PD2SM\_RX} + 2$  peripheral bridge clock periods. Bias block remains enabled in sleep mode.
9. Absolute min =  $0.15\text{ V} - (285\text{ mV}/2) = 0\text{ V}$
10. Absolute max =  $1.6\text{ V} + (285\text{ mV}/2) = 1.743\text{ V}$
11. Total internal capacitance including receiver and termination, co-bonded GPIO pads, and package contributions. For bare die devices, subtract the package value given in [Figure 11](#).

**Table 21. LFAST transmitter electrical characteristics<sup>1</sup>**

| Symbol     | Parameter | Conditions | Value |     |     | Unit |
|------------|-----------|------------|-------|-----|-----|------|
|            |           |            | Min   | Typ | Max |      |
| $f_{DATA}$ | Data rate | —          | —     | —   | 240 | Mbps |

Table continues on the next page...

**Table 21. LFAST transmitter electrical characteristics<sup>1</sup> (continued)**

| Symbol               | Parameter                                                     | Conditions               | Value |     |      | Unit |
|----------------------|---------------------------------------------------------------|--------------------------|-------|-----|------|------|
|                      |                                                               |                          | Min   | Typ | Max  |      |
| V <sub>OS</sub>      | Common mode voltage                                           | —                        | 1.08  | —   | 1.32 | V    |
| V <sub>OD</sub>      | Differential output voltage swing (terminated) <sup>2,3</sup> | —                        | 110   | 200 | 285  | mV   |
| t <sub>TR</sub>      | Rise/fall time (10% – 90% of swing) <sup>2,3</sup>            | —                        | 0.26  | —   | 1.5  | ns   |
| C <sub>L</sub>       | External lumped differential load capacitance <sup>2</sup>    | V <sub>DDE</sub> = 4.5 V | —     | —   | 12.0 | pF   |
|                      |                                                               | V <sub>DDE</sub> = 3.0 V | —     | —   | 8.5  |      |
| I <sub>LVDS_TX</sub> | Transmitter DC current consumption                            | Enabled                  | —     | —   | 3.2  | mA   |

1. The LFAST pad electrical characteristics are based on worst-case internal capacitance values shown in [Figure 11](#).
2. Valid for maximum data rate f<sub>DATA</sub>. Value given is the capacitance on each terminal of the differential pair, as shown in [Figure 11](#).
3. Valid for maximum external load C<sub>L</sub>.

**Table 22. MSC/DSPI LVDS transmitter electrical characteristics<sup>1</sup>**

| Symbol               | Parameter                                                     | Conditions               | Value |     |      | Unit |
|----------------------|---------------------------------------------------------------|--------------------------|-------|-----|------|------|
|                      |                                                               |                          | Min   | Typ | Max  |      |
| f <sub>DATA</sub>    | Data rate                                                     | —                        | —     | —   | 80   | Mbps |
| V <sub>OS</sub>      | Common mode voltage                                           | —                        | 1.08  | —   | 1.32 | V    |
| V <sub>OD</sub>      | Differential output voltage swing (terminated) <sup>2,3</sup> | —                        | 150   | 200 | 400  | mV   |
| t <sub>TR</sub>      | Rise/Fall time (10%–90% of swing) <sup>2,3</sup>              | —                        | 0.8   | —   | 4.0  | ns   |
| C <sub>L</sub>       | External lumped differential load capacitance <sup>2</sup>    | V <sub>DDE</sub> = 4.5 V | —     | —   | 50   | pF   |
|                      |                                                               | V <sub>DDE</sub> = 3.0 V | —     | —   | 39   |      |
| I <sub>LVDS_TX</sub> | Transmitter DC current consumption                            | Enabled                  | —     | —   | 4.0  | mA   |

1. The MSC and DSPI LVDS pad electrical characteristics are based on the application circuit and typical worst-case internal capacitance values given in [Figure 11](#).
2. Valid for maximum data rate f<sub>DATA</sub>. Value given is the capacitance on each terminal of the differential pair, as shown in [Figure 11](#).
3. Valid for maximum external load C<sub>L</sub>.

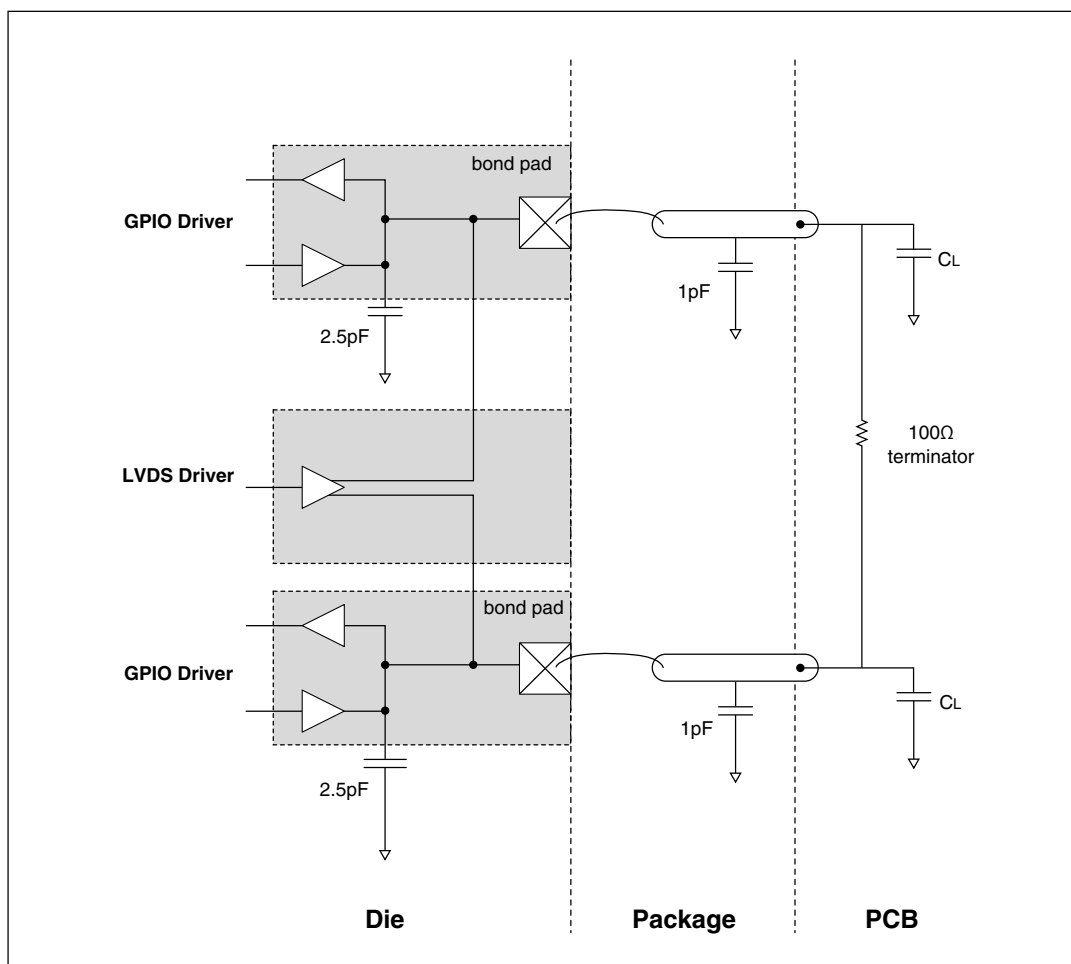


Figure 11. LVDS pad external load diagram

### 3.10.3 LFAST PLL electrical characteristics

The following table contains the electrical characteristics for the LFAST PLL.

Table 23. LFAST PLL electrical characteristics<sup>1</sup>

| Symbol        | Parameter                                 | Conditions                     | Value |                  |     | Unit |
|---------------|-------------------------------------------|--------------------------------|-------|------------------|-----|------|
|               |                                           |                                | Min   | Nominal          | Max |      |
| $f_{RF\_REF}$ | PLL reference clock frequency             | —                              | 10    | —                | 26  | MHz  |
| $ERR_{REF}$   | PLL reference clock frequency error       | —                              | -1    | —                | 1   | %    |
| $DC_{REF}$    | PLL reference clock duty cycle            | —                              | 45    | —                | 55  | %    |
| PN            | Integrated phase noise (single side band) | $f_{RF\_REF} = 20 \text{ MHz}$ | —     | —                | -58 | dBc  |
|               |                                           | $f_{RF\_REF} = 10 \text{ MHz}$ | —     | —                | -64 |      |
| $f_{VCO}$     | PLL VCO frequency                         | —                              | —     | 480 <sup>2</sup> | —   | MHz  |
| $t_{LOCK}$    | PLL phase lock <sup>3</sup>               | —                              | —     | —                | 40  | μs   |

Table continues on the next page...

**Table 23. LFAST PLL electrical characteristics<sup>1</sup> (continued)**

| Symbol                          | Parameter                                     | Conditions                                           | Value |         |     | Unit |
|---------------------------------|-----------------------------------------------|------------------------------------------------------|-------|---------|-----|------|
|                                 |                                               |                                                      | Min   | Nominal | Max |      |
| $\Delta\text{PER}_{\text{REF}}$ | Input reference clock jitter (peak to peak)   | Single period, $f_{\text{RF\_REF}} = 10 \text{ MHz}$ | —     | —       | 300 | ps   |
|                                 |                                               | Long term, $f_{\text{RF\_REF}} = 10 \text{ MHz}$     | –500  | —       | 500 |      |
| $\Delta\text{PER}_{\text{EYE}}$ | Output Eye Jitter (peak to peak) <sup>4</sup> | —                                                    | —     | —       | 400 | ps   |

1. The specifications in this table apply to both the interprocessor bus and debug LFAST interfaces.
2. The 480 MHz frequency is achieved with a 10 MHz or 20 MHz reference clock. With a 13 MHz or 26 MHz reference, the VCO frequency is 468 MHz.
3. The time from the PLL enable bit register write to the start of phase locks is maximum 2 clock cycles of the peripheral bridge clock that is connected to the PLL on the device.
4. Measured at the transmitter output across a 100 Ohm termination resistor on a device evaluation board. See [Figure 11](#).

## 3.11 Power management: PMC, POR/LVD, power sequencing

### 3.11.1 Power management electrical characteristics

The power management module monitors the different power supplies. It also generates the internal supplies that are required for correct device functionality. The power management is supplied by the  $V_{\text{DDPMC}}$  supply.

#### 3.11.1.1 LDO mode recommended power transistors

Only specific orderable part numbers of MPC5777C support LDO regulation mode. See [Ordering information](#) for MPC5777C parts that support this regulation mode.

The following NPN transistors are recommended for use with the on-chip LDO voltage regulator controller: ON Semiconductor™ NJD2873. The collector of the external transistor is preferably connected to the same voltage supply source as the output stage of the regulator.

The following table describes the characteristics of the power transistors.

**Table 24. Recommended operating characteristics**

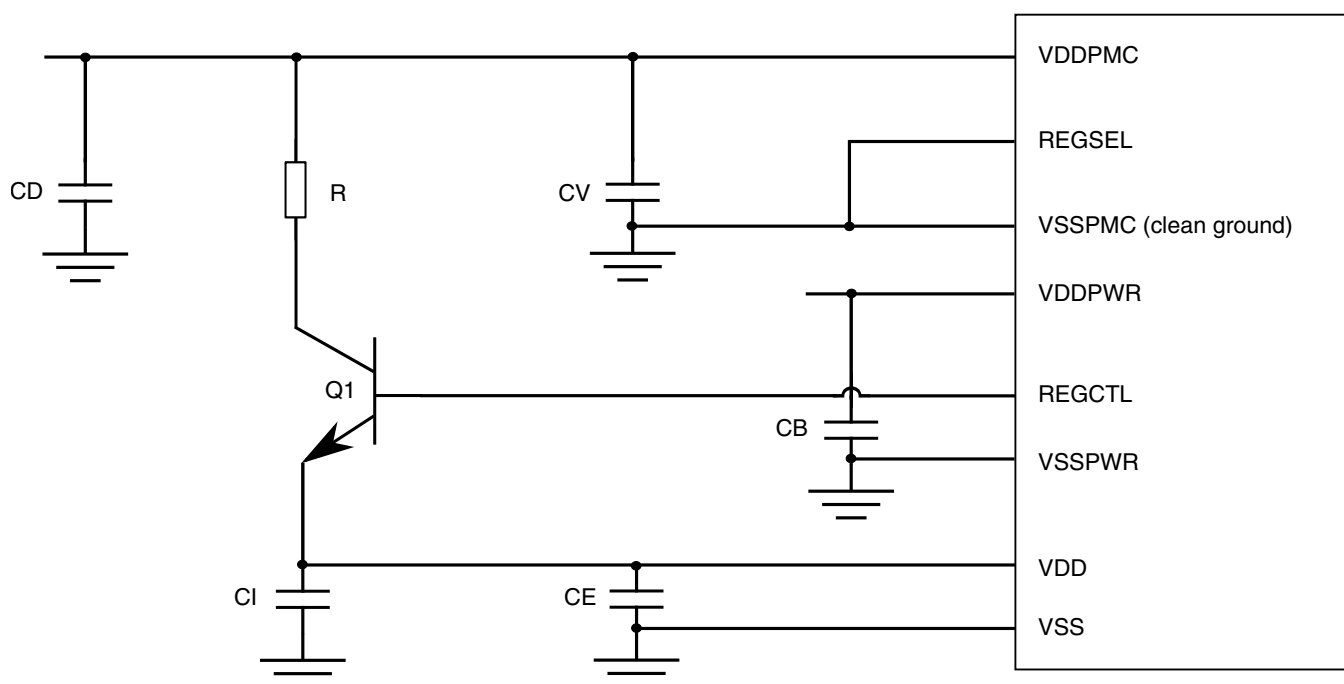
| Symbol              | Parameter                               | Value  | Unit |
|---------------------|-----------------------------------------|--------|------|
| $h_{\text{FE}}$     | DC current gain (Beta)                  | 60-550 | —    |
| $P_{\text{D}}$      | Absolute minimum power dissipation      | 1.60   | W    |
| $I_{\text{CMaxDC}}$ | Maximum DC collector current            | 2.0    | A    |
| $V_{\text{CESAT}}$  | Collector to emitter saturation voltage | 300    | mV   |
| $V_{\text{BE}}$     | Base to emitter voltage                 | 0.95   | V    |
| $V_{\text{C}}$      | Minimum voltage at transistor collector | 2.5    | V    |

The following table shows the recommended components to be used in LDO regulation mode.

**Table 25. Recommended operating characteristics**

| Part name | Part type | Nominal                         | Description                                                                                      |
|-----------|-----------|---------------------------------|--------------------------------------------------------------------------------------------------|
| Q1        | NPN BJT   | $h_{FE} = 400$                  | NJD2873: ON Semiconductor LDO voltage regulator controller (VRC)                                 |
| CI        | Capacitor | 4.7 $\mu\text{F}$ - 20 V        | Ceramic capacitor, total ESR < 70 m $\Omega$                                                     |
| CE        | Capacitor | 0.047–0.049 $\mu\text{F}$ - 7 V | Ceramic—one capacitor for each $V_{DD}$ pin                                                      |
| CV        | Capacitor | 22 $\mu\text{F}$ - 20 V         | Ceramic $V_{DDPMC}$ (optional 0.1 $\mu\text{F}$ )                                                |
| CD        | Capacitor | 22 $\mu\text{F}$ - 20 V         | Ceramic supply decoupling capacitor, ESR < 50 m $\Omega$ (as close as possible to NPN collector) |
| CB        | Capacitor | 0.1 $\mu\text{F}$ - 7 V         | Ceramic $V_{DDPWR}$                                                                              |
| R         | Resistor  | Application specific            | Optional; reduces thermal loading on the NPN with high $V_{DDPMC}$ levels                        |

The following diagram shows the LDO configuration connection.



**Figure 12. VRC 1.2 V LDO configuration**

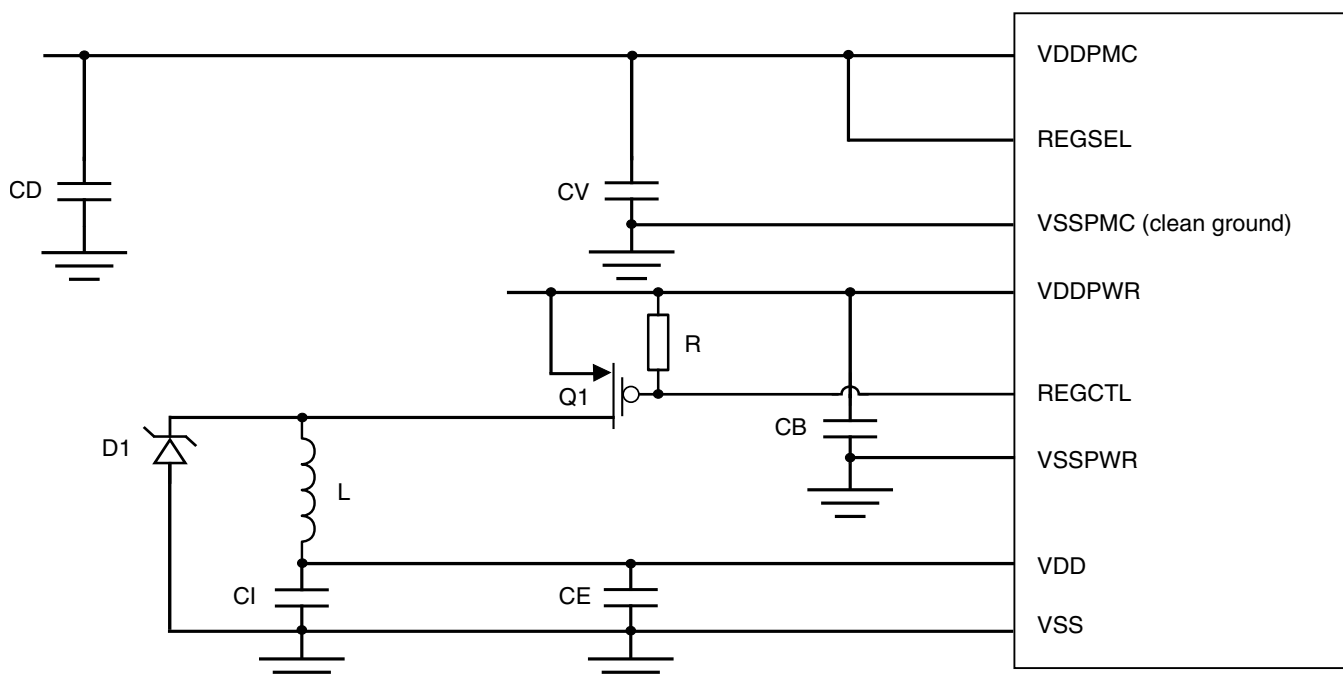
### 3.11.1.2 SMPS mode recommended external components and characteristics

The following table shows the recommended components to be used in SMPS regulation mode.

**Table 26. Recommended operating characteristics**

| Part name | Part type | Nominal             | Description                                                                                                                             |
|-----------|-----------|---------------------|-----------------------------------------------------------------------------------------------------------------------------------------|
| Q1        | p-MOS     | 3 A - 20 V          | SQ2301ES / FDC642P or equivalent: low threshold p-MOS, $V_{th} < 2.0$ V, $R_{dson}$ @ 4.5 V < 100 m $\Omega$ , $C_g < 5$ nF             |
| D1        | Schottky  | 2 A - 20 V          | SS8P3L or equivalent: Vishay™ low $V_f$ Schottky diode                                                                                  |
| L         | Inductor  | 3–4 $\mu$ H - 1.5 A | Buck shielded coil low ESR                                                                                                              |
| CI        | Capacitor | 22 $\mu$ F - 20 V   | Ceramic capacitor, total ESR < 70 m $\Omega$                                                                                            |
| CE        | Capacitor | 0.1 $\mu$ F - 7 V   | Ceramic—one capacitor for each $V_{DD}$ pin                                                                                             |
| CV        | Capacitor | 22 $\mu$ F - 20 V   | Ceramic $V_{DDPMC}$ (optional 0.1 $\mu$ F capacitor in parallel)                                                                        |
| CD        | Capacitor | 22 $\mu$ F - 20 V   | Ceramic supply decoupling capacitor, ESR < 50 m $\Omega$ (as close as possible to the p-MOS source)                                     |
| R         | Resistor  | 2.0-4.7 k $\Omega$  | Pullup for power p-MOS gate                                                                                                             |
| CB        | Capacitor | 22 $\mu$ F - 20 V   | Ceramic, connect 100 nF capacitor in parallel (as close as possible to package to reduce current loop from $V_{DDPWR}$ to $V_{SSPWR}$ ) |

The following diagram shows the SMPS configuration connection.

**Figure 13. SMPS configuration****NOTE**

The REGSEL pin is tied to  $V_{DDPMC}$  to select SMPS. If REGSEL is 0, the chip boots with the linear regulator.

See [Power sequencing requirements](#) for details about  $V_{DDPMC}$  and  $V_{DDPWR}$ .

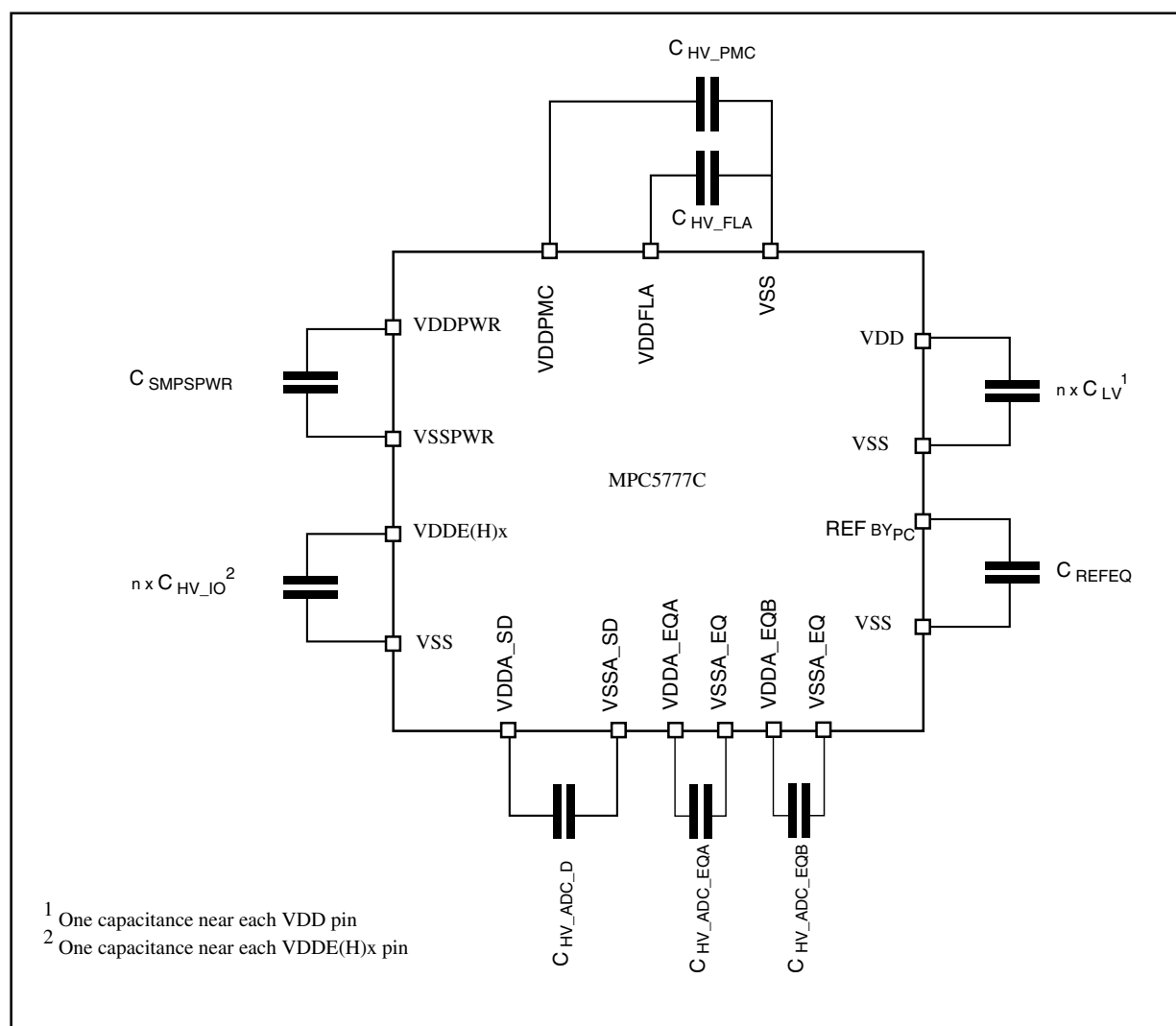
The SMPS regulator characteristics appear in the following table.

**Table 27. SMPS electrical characteristics**

| Symbol                | Parameter                  | Conditions | Value |       |      | Unit |
|-----------------------|----------------------------|------------|-------|-------|------|------|
|                       |                            |            | Min   | Typ   | Max  |      |
| SMPS <sub>CLOCK</sub> | SMPS oscillator frequency  | Trimmed    | 825   | 1000  | 1220 | kHz  |
| SMPS <sub>SLOPE</sub> | SMPS soft-start ramp slope | —          | 0.01  | 0.025 | 0.05 | V/μs |
| SMPS <sub>EFF</sub>   | SMPS typical efficiency    | —          | —     | 70    | —    | %    |

### 3.11.2 Power management integration

To ensure correct functionality of the device, use the following recommended integration scheme for LDO mode.



**Figure 14. Recommended supply pin circuits**

The following table describes the supply stability capacitances required on the device for proper operation.

**Table 28. Device power supply integration**

| Symbol                    | Parameter                                                                       | Conditions | Value <sup>1</sup> |                  |     | Unit |
|---------------------------|---------------------------------------------------------------------------------|------------|--------------------|------------------|-----|------|
|                           |                                                                                 |            | Min                | Typ              | Max |      |
| C <sub>LV</sub>           | Minimum V <sub>DD</sub> external bulk capacitance <sup>2, 3</sup>               | LDO mode   | 4.7                | —                | —   | μF   |
|                           |                                                                                 | SMPS mode  | 22                 | —                | —   | μF   |
| C <sub>SMPS_PWR</sub>     | Minimum SMPS driver supply capacitance                                          | —          | 22                 | —                | —   | μF   |
| C <sub>HV_PMC</sub>       | Minimum V <sub>DDPMC</sub> external bulk capacitance <sup>4, 5</sup>            | LDO mode   | 22                 | —                | —   | μF   |
|                           |                                                                                 | SMPS mode  | 22                 | —                | —   | μF   |
| C <sub>HV_IO</sub>        | Minimum V <sub>DDEX</sub> /V <sub>DDEHx</sub> external capacitance <sup>2</sup> | —          | —                  | 4.7 <sup>6</sup> | —   | μF   |
| C <sub>HV_FLA</sub>       | Minimum V <sub>DD_FLA</sub> external capacitance <sup>7</sup>                   | —          | 1.0                | 2.0              | —   | μF   |
| C <sub>HV_ADC_EQA/B</sub> | Minimum V <sub>DDEQA/B</sub> external capacitance <sup>8</sup>                  | —          | 0.01               | —                | —   | μF   |
| C <sub>REFEQ</sub>        | Minimum REF <sub>BYPQA/B</sub> external capacitance <sup>9</sup>                | —          | 0.01               | —                | —   | μF   |
| C <sub>HV_ADC_SD</sub>    | Minimum V <sub>DDESD</sub> external capacitance <sup>10</sup>                   | —          | 1.0                | 2.2              | —   | μF   |

1. See Figure 14 for capacitor integration.
2. Recommended X7R or X5R ceramic low ESR capacitors, ±15% variation over process, voltage, temperature, and aging.
3. Each V<sub>DD</sub> pin requires both a 47 nF and a 0.01 μF capacitor for high-frequency bypass and EMC requirements.
4. Recommended X7R or X5R ceramic low ESR capacitors, ±15% variation over process, voltage, temperature, and aging.
5. Each V<sub>DDPMC</sub> pin requires both a 47 nF and a 0.01 μF capacitor for high-frequency bypass and EMC requirements.
6. The actual capacitance should be selected based on the I/O usage in order to keep the supply voltage within its operating range.
7. The recommended flash regulator composition capacitor is 2.0 μF typical X7R or X5R, with -50% and +35% as min and max. This puts the min cap at 0.75 μF.
8. For noise filtering it is recommended to add a high frequency bypass capacitance of 0.1 μF between V<sub>DDEQA/B</sub> and V<sub>SSA\_EQ</sub>.
9. For noise filtering it is recommended to add a high frequency bypass capacitance of 0.1 μF between REF<sub>BYPQA/B</sub> and V<sub>SS</sub>.
10. For noise filtering it is recommended to add a high frequency bypass capacitance of 0.1 μF between V<sub>DDESD</sub> and V<sub>SSA\_SD</sub>.

### 3.11.3 Device voltage monitoring

The LVD/HVDs for the device and their levels are given in the following table. Voltage monitoring threshold definition is provided in the following figure.

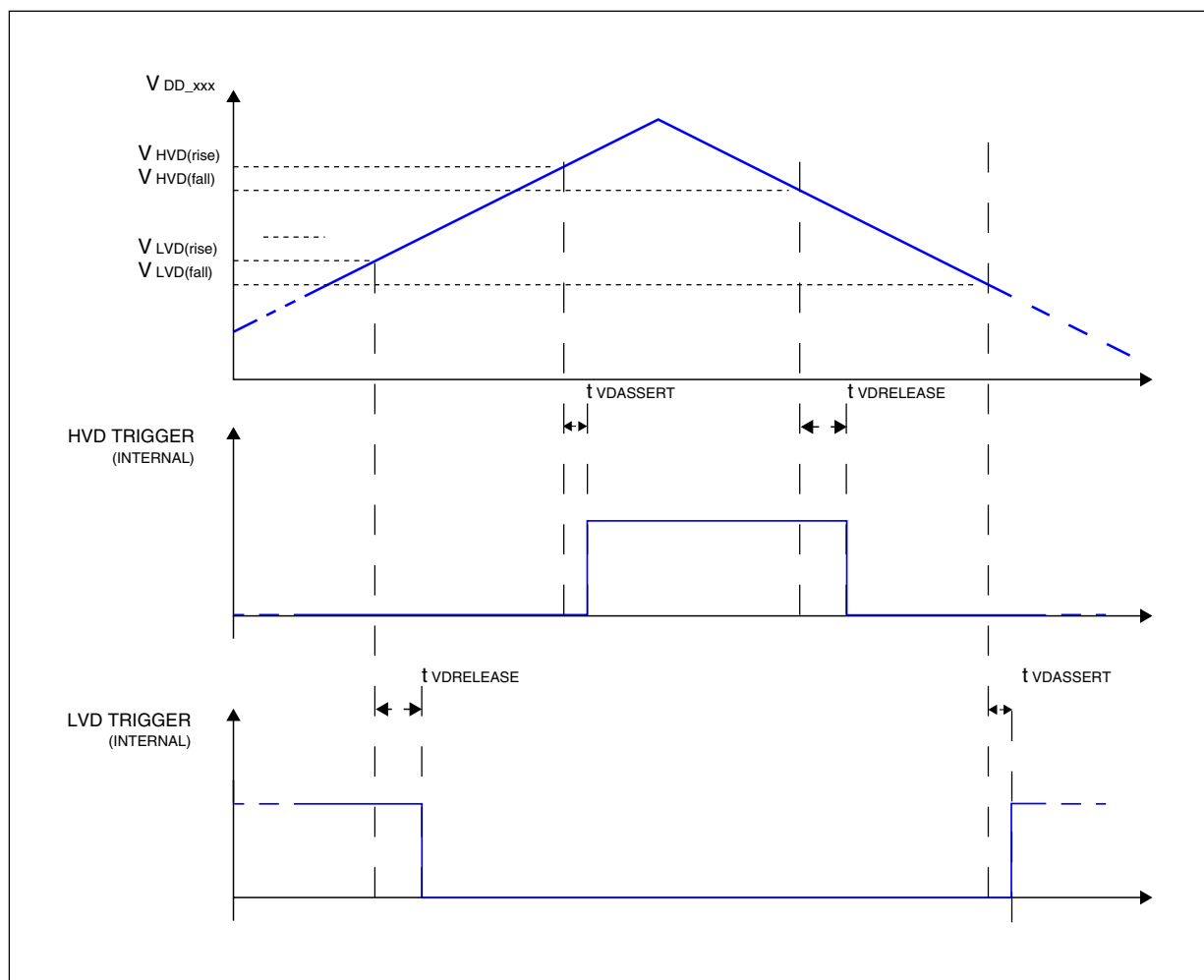


Figure 15. Voltage monitor threshold definition

Table 29. Voltage monitor electrical characteristics<sup>1, 2</sup>

| Symbol                | Parameter                                              | Conditions                   | Configuration |           |         | Value |      |      | Unit |
|-----------------------|--------------------------------------------------------|------------------------------|---------------|-----------|---------|-------|------|------|------|
|                       |                                                        |                              | Trim bits     | Mask Opt. | Pow. Up | Min   | Typ  | Max  |      |
| POR098_c <sup>3</sup> | LV internal supply power on reset                      | Rising voltage (powerup)     | N/A           | No        | Enab.   | 960   | 1010 | 1060 | mV   |
|                       |                                                        | Falling voltage (power down) |               |           |         | 940   | 990  | 1040 |      |
| LVD_core_hot          | LV internal <sup>4</sup> supply low voltage monitoring | Rising voltage (untrimmed)   | 4bit          | No        | Enab.   | 1100  | 1140 | 1183 | mV   |
|                       |                                                        | Falling voltage (untrimmed)  |               |           |         | 1080  | 1120 | 1163 |      |
|                       |                                                        | Rising voltage (trimmed)     |               |           |         | 1142  | 1165 | 1183 |      |
|                       |                                                        | Falling voltage (trimmed)    |               |           |         | 1122  | 1145 | 1163 |      |
| LVD_core_cold         | LV external <sup>5</sup> supply low voltage monitoring | Rising voltage               | 4bit          | Yes       | Disab.  | 1165  | 1180 | 1198 | mV   |
|                       |                                                        | Falling voltage              |               |           |         | 1136  | 1160 | 1178 |      |
| HVD_core              | LV internal cold supply high voltage monitoring        | Rising voltage               | 4bit          | Yes       | Disab.  | 1338  | 1365 | 1385 | mV   |
|                       |                                                        | Falling voltage              |               |           |         | 1318  | 1345 | 1365 |      |

Table continues on the next page...

**Table 29. Voltage monitor electrical characteristics<sup>1, 2</sup> (continued)**

| Symbol          | Parameter                                              | Conditions                   | Configuration |           |         | Value |      |      | Unit    |
|-----------------|--------------------------------------------------------|------------------------------|---------------|-----------|---------|-------|------|------|---------|
|                 |                                                        |                              | Trim bits     | Mask Opt. | Pow. Up | Min   | Typ  | Max  |         |
| POR_HV          | HV $V_{DDPMC}$ supply power on reset threshold         | Rising voltage (powerup)     | N/A           | No        | Enab.   | 2444  | 2600 | 2756 | mV      |
|                 |                                                        | Falling voltage (power down) |               |           |         | 2424  | 2580 | 2736 |         |
| LVD_HV          | HV internal $V_{DDPMC}$ supply low voltage monitoring  | Rising voltage (untrimmed)   | 4bit          | No        | Enab.   | 2935  | 3023 | 3112 | mV      |
|                 |                                                        | Falling voltage (untrimmed)  |               |           |         | 2922  | 3010 | 3099 |         |
|                 |                                                        | Rising voltage (trimmed)     |               |           |         | 2946  | 3010 | 3066 |         |
|                 |                                                        | Falling voltage (trimmed)    |               |           |         | 2934  | 2998 | 3044 |         |
| HVD_HV          | HV internal $V_{DDPMC}$ supply high voltage monitoring | Rising voltage               | 4bit          | Yes       | Disab.  | 5696  | 5860 | 5968 | mV      |
|                 |                                                        | Falling voltage              |               |           |         | 5666  | 5830 | 5938 |         |
| LVD_FLASH       | FLASH supply low voltage monitoring <sup>6</sup>       | Rising voltage (untrimmed)   | 4bit          | No        | Enab.   | 2935  | 3023 | 3112 | mV      |
|                 |                                                        | Falling voltage (untrimmed)  |               |           |         | 2922  | 3010 | 3099 |         |
|                 |                                                        | Rising voltage (trimmed)     |               |           |         | 2956  | 3010 | 3053 |         |
|                 |                                                        | Falling voltage (trimmed)    |               |           |         | 2944  | 2998 | 3041 |         |
| HVD_FLASH       | FLASH supply high voltage monitoring <sup>6</sup>      | Rising voltage               | 4bit          | Yes       | Disab.  | 3456  | 3530 | 3584 | mV      |
|                 |                                                        | Falling voltage              |               |           |         | 3426  | 3500 | 3554 |         |
| LVD_IO          | Main I/O $V_{DDEH1}$ supply low voltage monitoring     | Rising voltage (untrimmed)   | 4bit          | No        | Enab.   | 3250  | 3350 | 3488 | mV      |
|                 |                                                        | Falling voltage (untrimmed)  |               |           |         | 3220  | 3320 | 3458 |         |
|                 |                                                        | Rising voltage (trimmed)     |               |           |         | 3347  | 3420 | 3468 |         |
|                 |                                                        | Falling voltage (trimmed)    |               |           |         | 3317  | 3390 | 3438 |         |
| $t_{VDASSERT}$  | Voltage detector threshold crossing assertion          | —                            | —             | —         | —       | 0.1   | —    | 2.0  | $\mu$ s |
| $t_{VDRELEASE}$ | Voltage detector threshold crossing de-assertion       | —                            | —             | —         | —       | 5     | —    | 20   | $\mu$ s |

1. LVD is released after  $t_{VDRELEASE}$  temporization when upper threshold is crossed; LVD is asserted  $t_{VDASSERT}$  after detection when lower threshold is crossed.
2. HVD is released after  $t_{VDRELEASE}$  temporization when lower threshold is crossed; HVD is asserted  $t_{VDASSERT}$  after detection when upper threshold is crossed.
3. POR098\_c threshold is an untrimmed value, before the completion of the power-up sequence. All other LVD/HVD thresholds are provided after trimming.
4. LV internal supply levels are measured on device internal supply grid after internal voltage drop.
5. LV external supply levels are measured on the die side of the package bond wire after package voltage drop.
6.  $V_{DDFLA}$  range is guaranteed when internal flash memory regulator is used.

### 3.11.4 Power sequencing requirements

Requirements for power sequencing include the following.

**NOTE**

In these descriptions, *star route layout* means a track split as close as possible to the power supply source. Each of the split tracks is routed individually to the intended end connection.

1. For both LDO mode and SMPS mode,  $V_{DDPMC}$  and  $V_{DDPWR}$  must be connected together (shorted) to ensure aligned voltage ramping up/down. In addition:
  - For SMPS mode, a star route layout of the power track is required to minimize mutual noise. If SMPS mode is not used, the star route layout is not required.  $V_{DDPWR}$  is the supply pin for the SMPS circuitry.
  - For 3.3 V operation,  $V_{DDFLA}$  must also be star routed and shorted to  $V_{DDPWR}$  and  $V_{DDPMC}$ . This triple connection is required because 3.3 V does not guarantee correct functionality of the internal  $V_{DDFLA}$  regulator. Consequently,  $V_{DDFLA}$  is supplied externally.
2.  $V_{DDA\_MISC}$ : IRC operation is required to provide the clock for chip startup.
  - The  $V_{DDPMC}$ ,  $V_{DD}$ , and  $V_{DDEH1}$  (reset pin pad segment) supplies are monitored. They hold IRC until all of them reach operational voltage. In other words,  $V_{DDA\_MISC}$  must reach its specified minimum operating voltage before or at the same time that all of these monitored voltages reach their respective specified minimum voltages.
  - An alternative is to connect the same supply voltage to both  $V_{DDEH1}$  and  $V_{DDA\_MISC}$ . This alternative approach requires a star route layout to minimize mutual noise.
3. Multiple  $V_{DDEx}$  supplies can be powered up in any order.
 

During any time when  $V_{DD}$  is powered up but  $V_{DDEx}$  is not yet powered up: pad outputs are unpowered.

During any time when  $V_{DDEx}$  is powered up before all other supplies: all pad output buffers are tristated.
4. Ramp up  $V_{DDA\_EQ}$  before  $V_{DD}$ . Otherwise, a reset might occur.
5. When the device is powering down while using the internal SMPS regulator,  $V_{DDPMC}$  and  $V_{DDPWR}$  supplies must ramp down through the voltage range from 2.5 V to 1.5 V in less than 1 second. Slower ramp-down times might result in reduced lifetime reliability of the device.

## 3.12 Flash memory specifications

### 3.12.1 Flash memory program and erase specifications

#### NOTE

All timing, voltage, and current numbers specified in this section are defined for a single embedded flash memory within an SoC, and represent average currents for given supplies and operations.

Table 30 shows the estimated Program/Erase times.

**Table 30. Flash memory program and erase specifications**

| Symbol               | Characteristic <sup>1</sup>        | Typ <sup>2</sup> | Factory Programming <sup>3, 4</sup> |                              | Field Update                     |                           |                  | Unit |
|----------------------|------------------------------------|------------------|-------------------------------------|------------------------------|----------------------------------|---------------------------|------------------|------|
|                      |                                    |                  | Initial Max                         | Initial Max, Full Temp       | Typical End of Life <sup>5</sup> | Lifetime Max <sup>6</sup> |                  |      |
|                      |                                    |                  | 20°C ≤T <sub>A</sub> ≤30°C          | -40°C ≤T <sub>J</sub> ≤150°C | -40°C ≤T <sub>J</sub> ≤150°C     | ≤ 1,000 cycles            | ≤ 250,000 cycles |      |
| t <sub>dwpgm</sub>   | Doubleword (64 bits) program time  | 43               | 100                                 | 150                          | 55                               | 500                       |                  | μs   |
| t <sub>ppgm</sub>    | Page (256 bits) program time       | 73               | 200                                 | 300                          | 108                              | 500                       |                  | μs   |
| t <sub>qppgm</sub>   | Quad-page (1024 bits) program time | 268              | 800                                 | 1,200                        | 396                              | 2,000                     |                  | μs   |
| t <sub>16kers</sub>  | 16 KB Block erase time             | 168              | 290                                 | 320                          | 250                              | 1,000                     |                  | ms   |
| t <sub>16kpgm</sub>  | 16 KB Block program time           | 34               | 45                                  | 50                           | 40                               | 1,000                     |                  | ms   |
| t <sub>32kers</sub>  | 32 KB Block erase time             | 217              | 360                                 | 390                          | 310                              | 1,200                     |                  | ms   |
| t <sub>32kpgm</sub>  | 32 KB Block program time           | 69               | 100                                 | 110                          | 90                               | 1,200                     |                  | ms   |
| t <sub>64kers</sub>  | 64 KB Block erase time             | 315              | 490                                 | 590                          | 420                              | 1,600                     |                  | ms   |
| t <sub>64kpgm</sub>  | 64 KB Block program time           | 138              | 180                                 | 210                          | 170                              | 1,600                     |                  | ms   |
| t <sub>256kers</sub> | 256 KB Block erase time            | 884              | 1,520                               | 2,030                        | 1,080                            | 4,000                     | —                | ms   |
| t <sub>256kpgm</sub> | 256 KB Block program time          | 552              | 720                                 | 880                          | 650                              | 4,000                     | —                | ms   |

1. Program times are actual hardware programming times and do not include software overhead. Block program times assume quad-page programming.
2. Typical program and erase times represent the median performance and assume nominal supply values and operation at 25 °C. Typical program and erase times may be used for throughput calculations.
3. Conditions: ≤ 150 cycles, nominal voltage.
4. Plant Programming times provide guidance for timeout limits used in the factory.
5. Typical End of Life program and erase times represent the median performance and assume nominal supply values. Typical End of Life program and erase values may be used for throughput calculations.
6. Conditions: -40°C ≤ T<sub>J</sub> ≤ 150°C, full spec voltage.

### 3.12.2 Flash memory Array Integrity and Margin Read specifications

**Table 31. Flash memory Array Integrity and Margin Read specifications**

| Symbol          | Characteristic                                                | Min    | Typical | Max <sup>1</sup>                    | Units <sup>2</sup> |
|-----------------|---------------------------------------------------------------|--------|---------|-------------------------------------|--------------------|
| $t_{ai16kseq}$  | Array Integrity time for sequential sequence on 16 KB block.  | —      | —       | 512 x $T_{period} \times N_{read}$  | —                  |
| $t_{ai32kseq}$  | Array Integrity time for sequential sequence on 32 KB block.  | —      | —       | 1024 x $T_{period} \times N_{read}$ | —                  |
| $t_{ai64kseq}$  | Array Integrity time for sequential sequence on 64 KB block.  | —      | —       | 2048 x $T_{period} \times N_{read}$ | —                  |
| $t_{ai256kseq}$ | Array Integrity time for sequential sequence on 256 KB block. | —      | —       | 8192 x $T_{period} \times N_{read}$ | —                  |
| $t_{mr16kseq}$  | Margin Read time for sequential sequence on 16 KB block.      | 73.81  | —       | 110.7                               | $\mu s$            |
| $t_{mr32kseq}$  | Margin Read time for sequential sequence on 32 KB block.      | 128.43 | —       | 192.6                               | $\mu s$            |
| $t_{mr64kseq}$  | Margin Read time for sequential sequence on 64 KB block.      | 237.65 | —       | 356.5                               | $\mu s$            |
| $t_{mr256kseq}$ | Margin Read time for sequential sequence on 256 KB block.     | 893.01 | —       | 1,339.5                             | $\mu s$            |

1. Array Integrity times need to be calculated and is dependent on system frequency and number of clocks per read. The equation presented require  $T_{period}$  (which is the unit accurate period, thus for 200 MHz,  $T_{period}$  would equal  $5e-9$ ) and  $N_{read}$  (which is the number of clocks required for read, including pipeline contribution. Thus for a read setup that requires 6 clocks to read with no pipeline,  $N_{read}$  would equal 6. For a read setup that requires 6 clocks to read, and has the address pipeline set to 2,  $N_{read}$  would equal 4 (or  $6 - 2$ ).)
2. The units for Array Integrity are determined by the period of the system clock. If unit accurate period is used in the equation, the results of the equation are also unit accurate.

### 3.12.3 Flash memory module life specifications

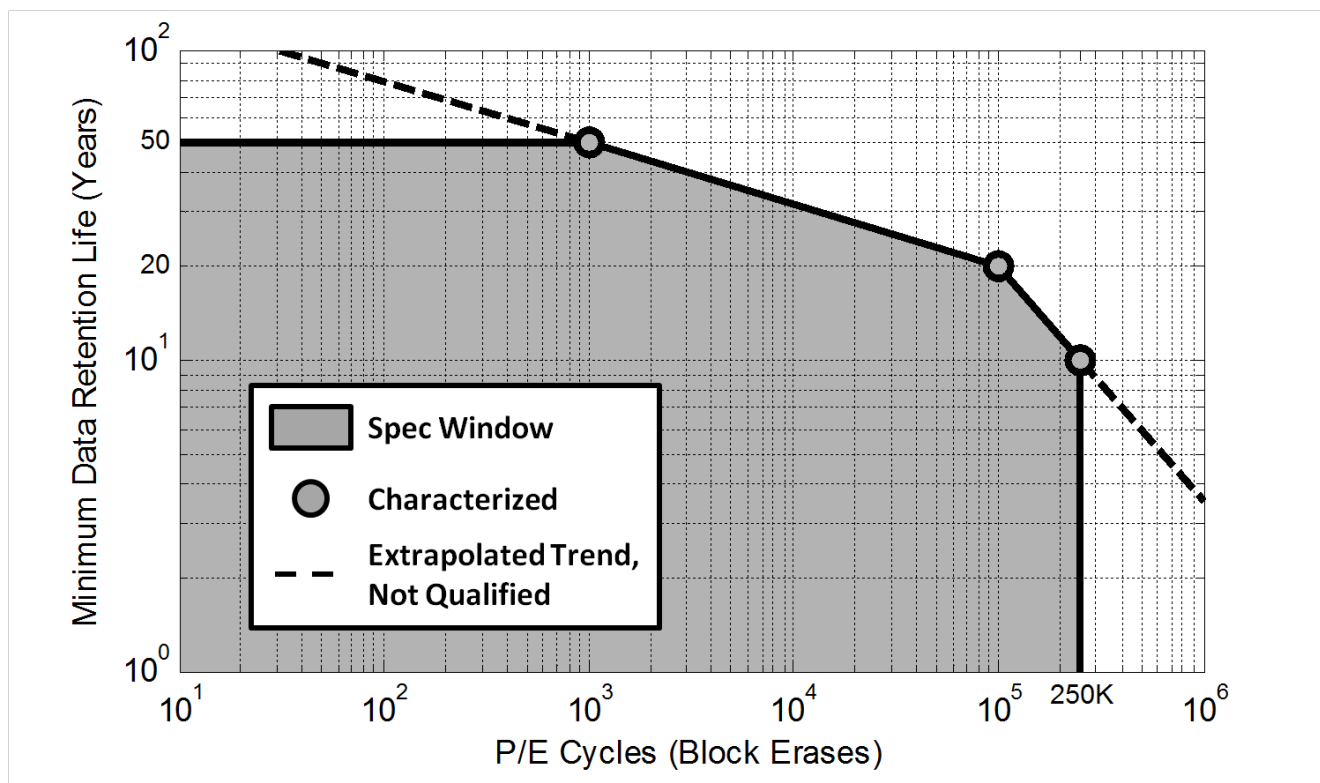
**Table 32. Flash memory module life specifications**

| Symbol           | Characteristic                                                                           | Conditions                        | Min     | Typical | Units      |
|------------------|------------------------------------------------------------------------------------------|-----------------------------------|---------|---------|------------|
| Array P/E cycles | Number of program/erase cycles per block for 16 KB, 32 KB and 64 KB blocks. <sup>1</sup> | —                                 | 250,000 | —       | P/E cycles |
|                  | Number of program/erase cycles per block for 256 KB blocks. <sup>2</sup>                 | —                                 | 1,000   | 250,000 | P/E cycles |
| Data retention   | Minimum data retention.                                                                  | Blocks with 0 - 1,000 P/E cycles. | 50      | —       | Years      |
|                  |                                                                                          | Blocks with 100,000 P/E cycles.   | 20      | —       | Years      |
|                  |                                                                                          | Blocks with 250,000 P/E cycles.   | 10      | —       | Years      |

1. Program and erase supported across standard temperature specs.
2. Program and erase supported across standard temperature specs.

### 3.12.4 Data retention vs program/erase cycles

Graphically, Data Retention versus Program/Erase Cycles can be represented by the following figure. The spec window represents qualified limits. The extrapolated dotted line demonstrates technology capability, however is beyond the qualification limits.



### 3.12.5 Flash memory AC timing specifications

Table 33. Flash memory AC timing specifications

| Symbol     | Characteristic                                                                | Min | Typical                                        | Max                                             | Units   |
|------------|-------------------------------------------------------------------------------|-----|------------------------------------------------|-------------------------------------------------|---------|
| $t_{psus}$ | Time from setting the MCR-PSUS bit until MCR-DONE bit is set to a 1.          | —   | 9.4<br>plus four<br>system<br>clock<br>periods | 11.5<br>plus four<br>system<br>clock<br>periods | $\mu s$ |
| $t_{esus}$ | Time from setting the MCR-ESUS bit until MCR-DONE bit is set to a 1.          | —   | 16<br>plus four<br>system<br>clock<br>periods  | 20.8<br>plus four<br>system<br>clock<br>periods | $\mu s$ |
| $t_{res}$  | Time from clearing the MCR-ESUS or PSUS bit with EHV = 1 until DONE goes low. | —   | —                                              | 100                                             | ns      |

Table continues on the next page...

**Table 33. Flash memory AC timing specifications (continued)**

| Symbol        | Characteristic                                                                                                                                                                                                               | Min                                              | Typical                                       | Max                                              | Units   |
|---------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------|-----------------------------------------------|--------------------------------------------------|---------|
| $t_{done}$    | Time from 0 to 1 transition on the MCR-EHV bit initiating a program/erase until the MCR-DONE bit is cleared.                                                                                                                 | —                                                | —                                             | 5                                                | ns      |
| $t_{dones}$   | Time from 1 to 0 transition on the MCR-EHV bit aborting a program/erase until the MCR-DONE bit is set to a 1.                                                                                                                | —                                                | 16<br>plus four<br>system<br>clock<br>periods | 20.8<br>plus four<br>system<br>clock<br>periods  | $\mu$ s |
| $t_{drcv}$    | Time to recover once exiting low power mode.                                                                                                                                                                                 | 16<br>plus seven<br>system<br>clock<br>periods.  | —                                             | 45<br>plus seven<br>system<br>clock<br>periods   | $\mu$ s |
| $t_{aistart}$ | Time from 0 to 1 transition of UT0-AIE initiating a Margin Read or Array Integrity until the UT0-AID bit is cleared. This time also applies to the resuming from a suspend or breakpoint by clearing AISUS or clearing NAIBP | —                                                | —                                             | 5                                                | ns      |
| $t_{aistop}$  | Time from 1 to 0 transition of UT0-AIE initiating an Array Integrity abort until the UT0-AID bit is set. This time also applies to the UT0-AISUS to UT0-AID setting in the event of a Array Integrity suspend request.       | —                                                | —                                             | 80<br>plus fifteen<br>system<br>clock<br>periods | ns      |
| $t_{mrstop}$  | Time from 1 to 0 transition of UT0-AIE initiating a Margin Read abort until the UT0-AID bit is set. This time also applies to the UT0-AISUS to UT0-AID setting in the event of a Margin Read suspend request.                | 10.36<br>plus four<br>system<br>clock<br>periods | —                                             | 20.42<br>plus four<br>system<br>clock<br>periods | $\mu$ s |

### 3.12.6 Flash memory read wait-state and address-pipeline control settings

The following table describes the recommended settings of the Flash Memory Controller's PFCR1[RWSC] and PFCR1[APC] fields at various flash memory operating frequencies, based on specified intrinsic flash memory access times of the C55FMC array at 150°C.

**Table 34. Flash memory read wait-state and address-pipeline control combinations**

| Flash memory frequency         | RWSC | APC | Flash memory read latency on mini-cache miss (# of $f_{PLATF}$ clock periods) | Flash memory read latency on mini-cache hit (# of $f_{PLATF}$ clock periods) |
|--------------------------------|------|-----|-------------------------------------------------------------------------------|------------------------------------------------------------------------------|
| 0 MHz < $f_{PLATF}$ ≤ 33 MHz   | 0    | 0   | 3                                                                             | 1                                                                            |
| 33 MHz < $f_{PLATF}$ ≤ 100 MHz | 2    | 1   | 5                                                                             | 1                                                                            |

Table continues on the next page...

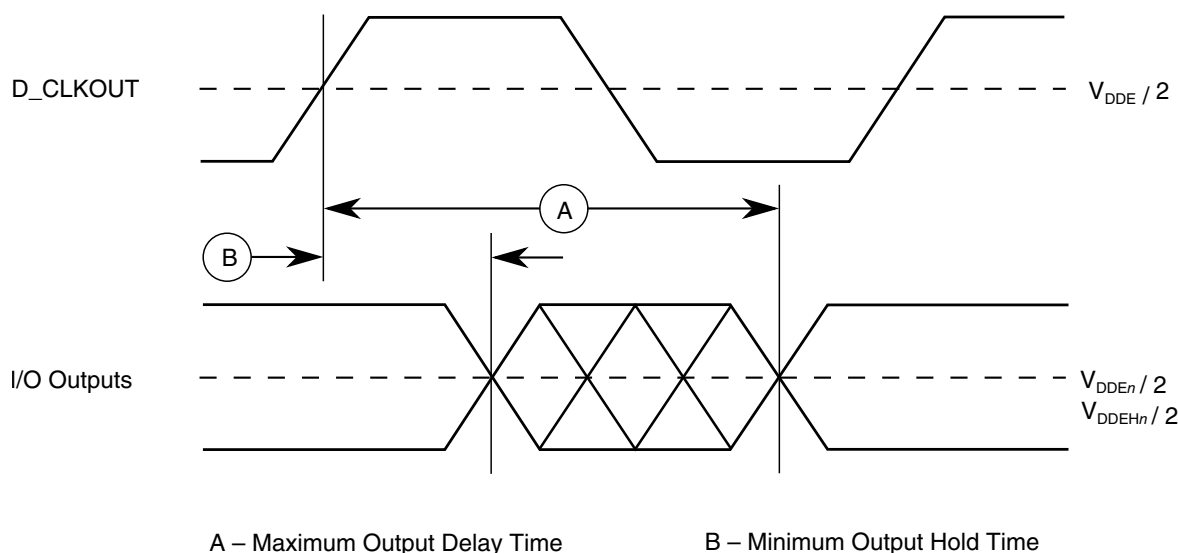
**Table 34. Flash memory read wait-state and address-pipeline control combinations (continued)**

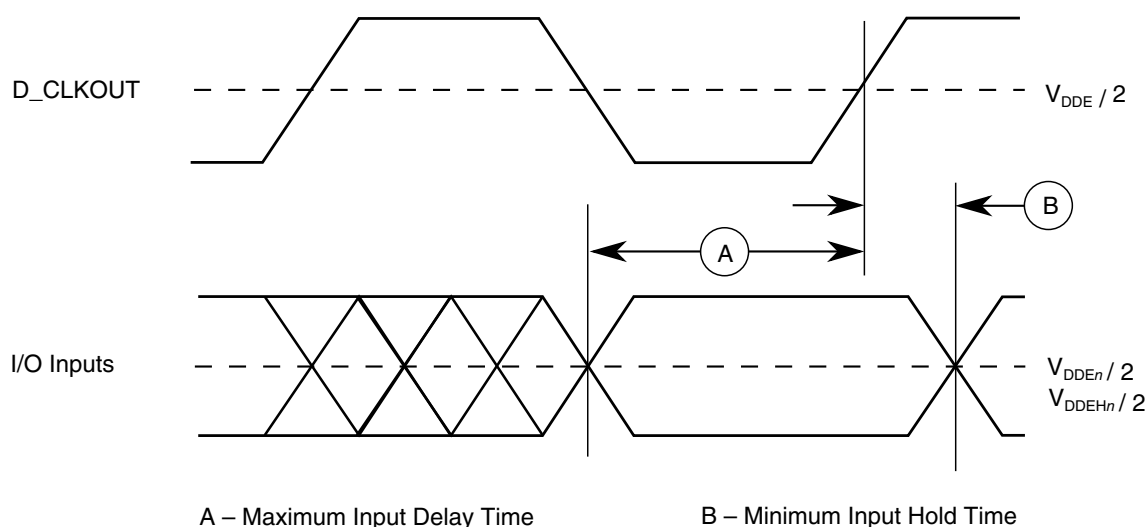
| Flash memory frequency                                    | RWSC | APC | Flash memory read latency on mini-cache miss (# of $f_{\text{PLATF}}$ clock periods) | Flash memory read latency on mini-cache hit (# of $f_{\text{PLATF}}$ clock periods) |
|-----------------------------------------------------------|------|-----|--------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------|
| $100 \text{ MHz} < f_{\text{PLATF}} \leq 150 \text{ MHz}$ | 3    | 1   | 6                                                                                    | 1                                                                                   |

## 3.13 AC timing

### 3.13.1 Generic timing diagrams

The generic timing diagrams in [Figure 16](#) and [Figure 17](#) apply to all I/O pins with pad types SR and FC. See the associated MPC5777C Microsoft Excel® file in the Reference Manual for the pad type for each pin.

**Figure 16. Generic output delay/hold timing**



**Figure 17. Generic input setup/hold timing**

### 3.13.2 Reset and configuration pin timing

**Table 35. Reset and configuration pin timing<sup>1</sup>**

| Spec | Characteristic                                     | Symbol     | Min | Max | Unit                   |
|------|----------------------------------------------------|------------|-----|-----|------------------------|
| 1    | RESET Pulse Width                                  | $t_{RPW}$  | 10  | —   | $t_{cyc}$ <sup>2</sup> |
| 2    | RESET Glitch Detect Pulse Width                    | $t_{GPW}$  | 2   | —   | $t_{cyc}$ <sup>2</sup> |
| 3    | PLLCFG, BOOTCFG, WKPCFG Setup Time to RSTOUT Valid | $t_{RCSU}$ | 10  | —   | $t_{cyc}$ <sup>2</sup> |
| 4    | PLLCFG, BOOTCFG, WKPCFG Hold Time to RSTOUT Valid  | $t_{RCH}$  | 0   | —   | $t_{cyc}$ <sup>2</sup> |

1. Reset timing specified at:  $V_{DDEH} = 3.0\text{ V to }5.25\text{ V}$ ,  $V_{DD} = 1.08\text{ V to }1.32\text{ V}$ ,  $T_A = T_L\text{ to }T_H$ .

2. For further information on  $t_{cyc}$ , see [Table 3](#).

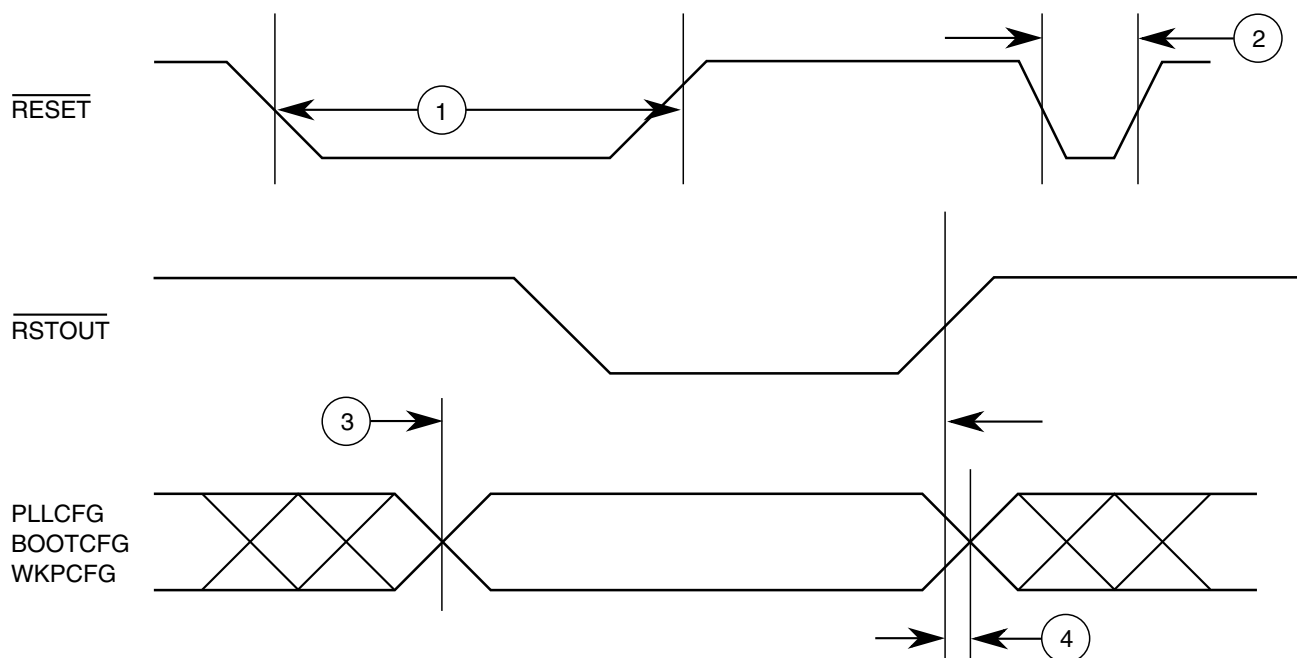


Figure 18. Reset and configuration pin timing

### 3.13.3 IEEE 1149.1 interface timing

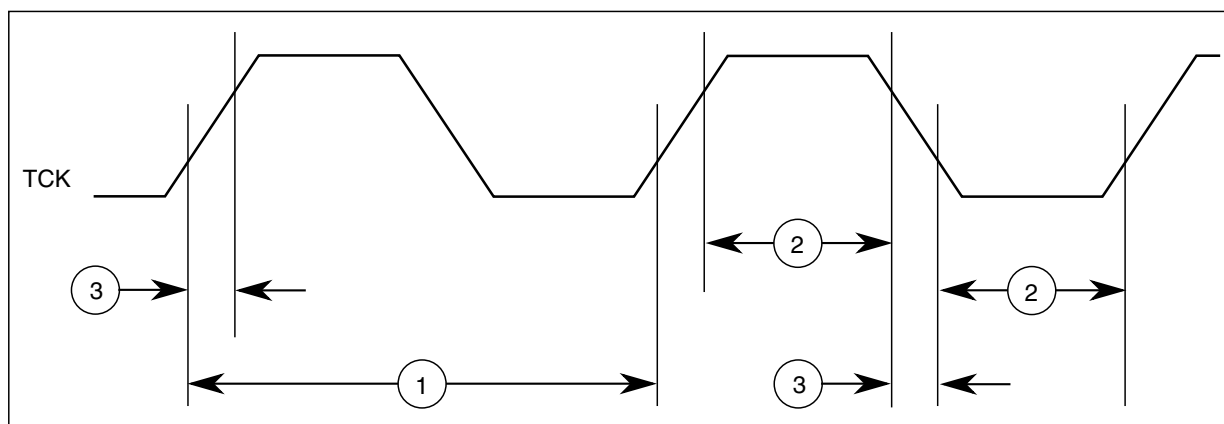
Table 36. JTAG pin AC electrical characteristics<sup>1</sup>

| #  | Symbol               | Characteristic                                         | Value |                  | Unit |
|----|----------------------|--------------------------------------------------------|-------|------------------|------|
|    |                      |                                                        | Min   | Max              |      |
| 1  | $t_{JCYC}$           | TCK cycle time                                         | 100   | —                | ns   |
| 2  | $t_{JDC}$            | TCK clock pulse width                                  | 40    | 60               | %    |
| 3  | $t_{TCKRISE}$        | TCK rise and fall times (40%–70%)                      | —     | 3                | ns   |
| 4  | $t_{TMSS}, t_{TDIS}$ | TMS, TDI data setup time                               | 5     | —                | ns   |
| 5  | $t_{TMSH}, t_{TDIH}$ | TMS, TDI data hold time                                | 5     | —                | ns   |
| 6  | $t_{TDOV}$           | TCK low to TDO data valid                              | —     | 16 <sup>2</sup>  | ns   |
| 7  | $t_{TDOI}$           | TCK low to TDO data invalid                            | 0     | —                | ns   |
| 8  | $t_{TDOHZ}$          | TCK low to TDO high impedance                          | —     | 15               | ns   |
| 9  | $t_{JCMPPW}$         | JCOMP assertion time                                   | 100   | —                | ns   |
| 10 | $t_{JCMPs}$          | JCOMP setup time to TCK low                            | 40    | —                | ns   |
| 11 | $t_{BSDV}$           | TCK falling edge to output valid                       | —     | 600 <sup>3</sup> | ns   |
| 12 | $t_{BSDVZ}$          | TCK falling edge to output valid out of high impedance | —     | 600              | ns   |
| 13 | $t_{BSDHZ}$          | TCK falling edge to output high impedance              | —     | 600              | ns   |
| 14 | $t_{BSDST}$          | Boundary scan input valid to TCK rising edge           | 15    | —                | ns   |
| 15 | $t_{BSDHT}$          | TCK rising edge to boundary scan input invalid         | 15    | —                | ns   |

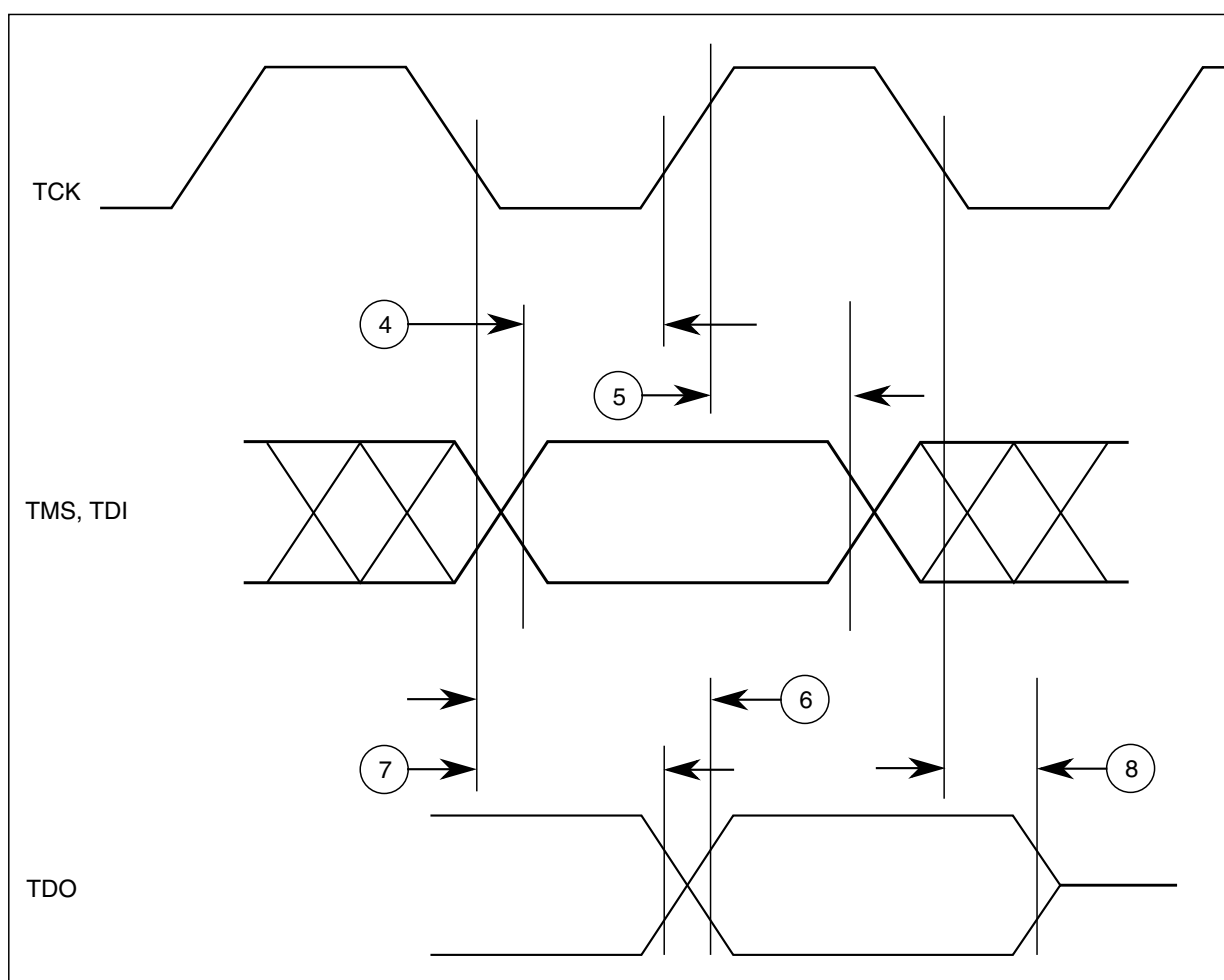
1. These specifications apply to JTAG boundary scan only. See Table 37 for functional specifications.

2. Timing includes TCK pad delay, clock tree delay, logic delay and TDO output pad delay.

3. Applies to all pins, limited by pad slew rate. Refer to I/O delay and transition specification and add 20 ns for JTAG delay.



**Figure 19. JTAG test clock input timing**



**Figure 20. JTAG test access port timing**

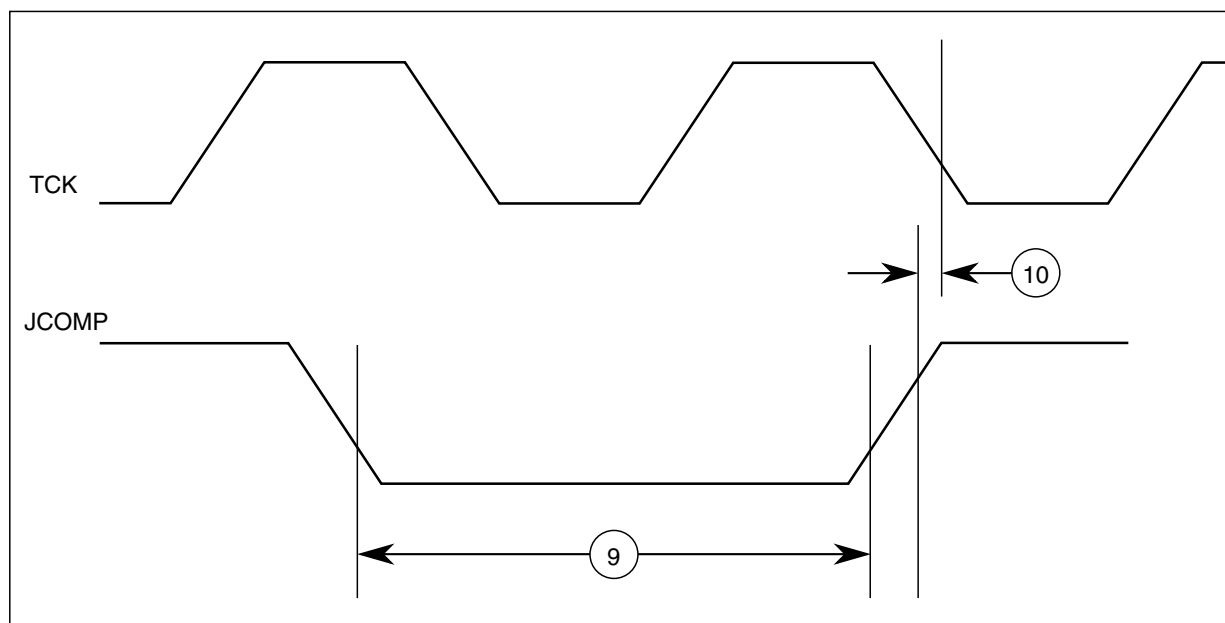


Figure 21. JTAG JCOMP timing

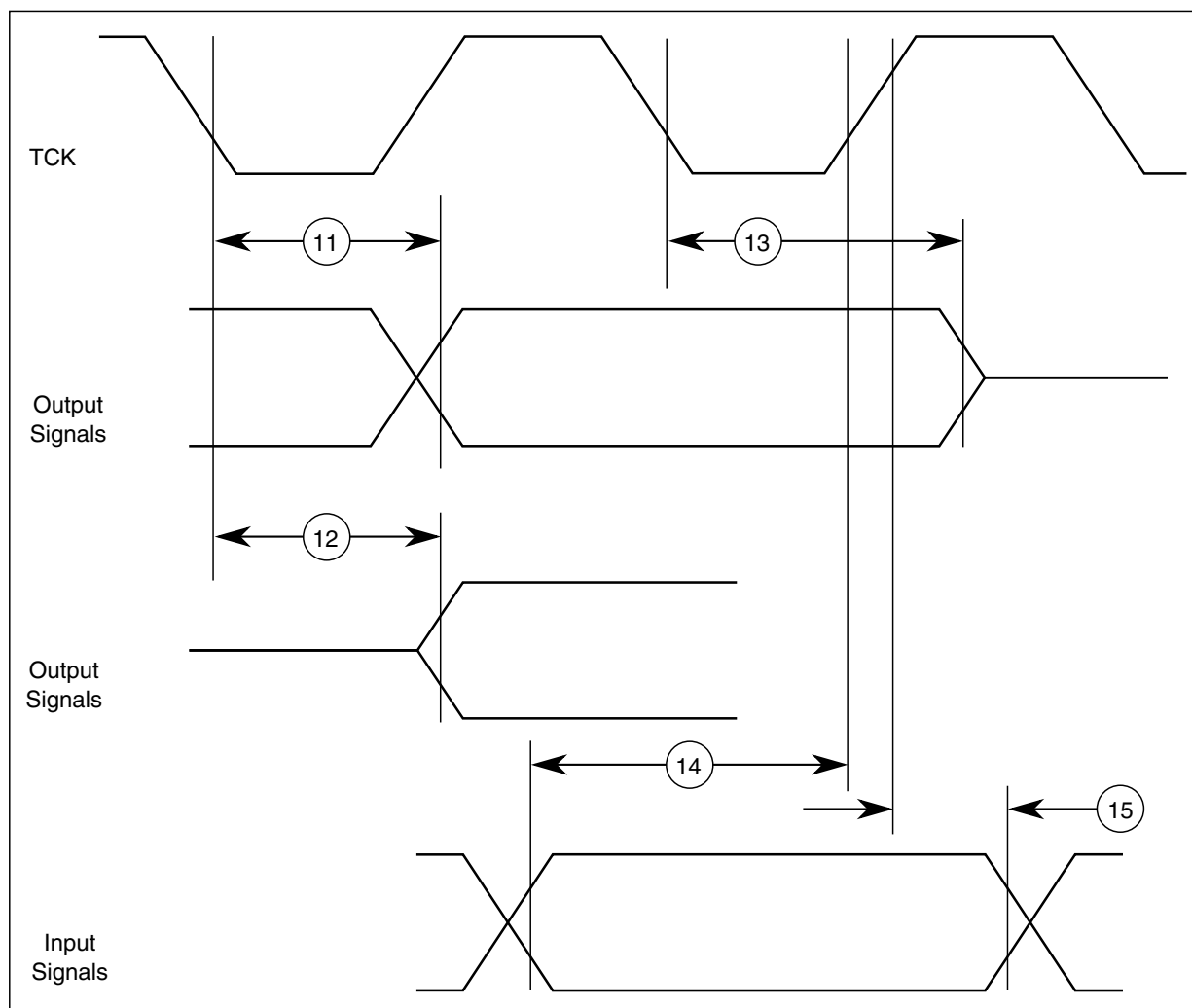


Figure 22. JTAG boundary scan timing

### 3.13.4 Nexus timing

Table 37. Nexus debug port timing<sup>1</sup>

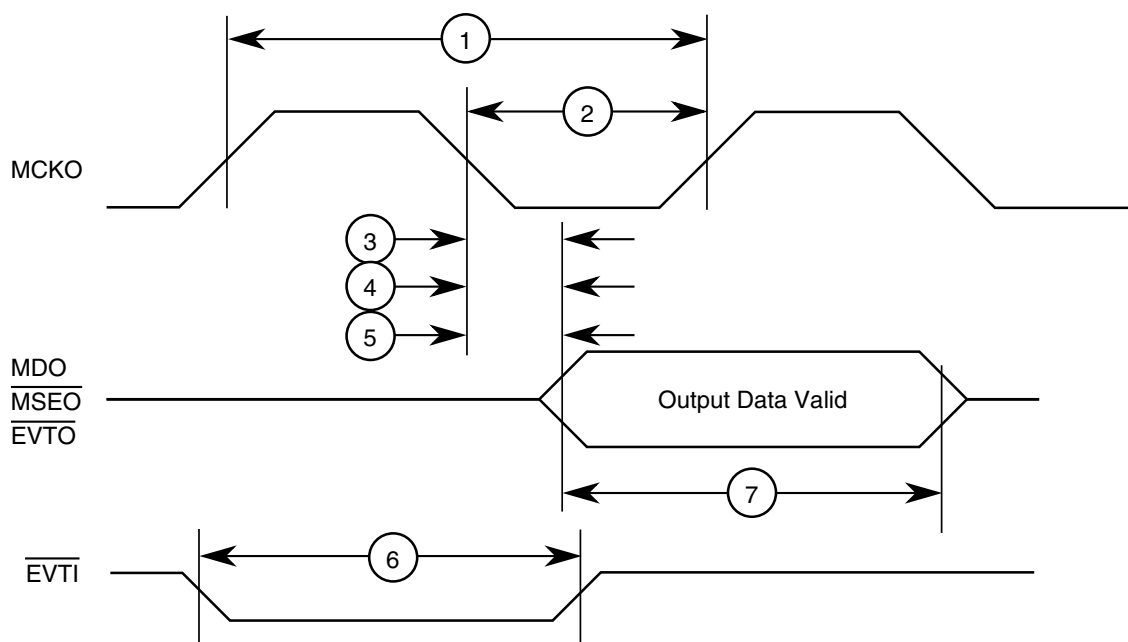
| Spec | Characteristic                                        | Symbol       | Min            | Max | Unit       |
|------|-------------------------------------------------------|--------------|----------------|-----|------------|
| 1    | MCKO Cycle Time                                       | $t_{MCYC}$   | 2              | 8   | $t_{CYC}$  |
| 2    | MCKO Duty Cycle                                       | $t_{MDC}$    | 40             | 60  | %          |
| 3    | MCKO Low to MDO Data Valid <sup>2</sup>               | $t_{MDOV}$   | -0.1           | 0.2 | $t_{MCYC}$ |
| 4    | MCKO Low to $\overline{MSEO}$ Data Valid <sup>2</sup> | $t_{MSEOV}$  | -0.1           | 0.2 | $t_{MCYC}$ |
| 5    | MCKO Low to $\overline{EVT0}$ Data Valid <sup>2</sup> | $t_{EVT0V}$  | -0.1           | 0.2 | $t_{MCYC}$ |
| 6    | $\overline{EVTI}$ Pulse Width                         | $t_{EVTIPW}$ | 4.0            | —   | $t_{TCYC}$ |
| 7    | $\overline{EVT0}$ Pulse Width                         | $t_{EVT0PW}$ | 1              | —   | $t_{MCYC}$ |
| 8    | TCK Cycle Time                                        | $t_{TCYC}$   | 2 <sup>3</sup> | —   | $t_{CYC}$  |

Table continues on the next page...

**Table 37. Nexus debug port timing<sup>1</sup> (continued)**

| Spec | Characteristic                                                               | Symbol                 | Min             | Max | Unit |
|------|------------------------------------------------------------------------------|------------------------|-----------------|-----|------|
| 8    | Absolute minimum TCK cycle time <sup>4</sup> (TDO sampled on posedge of TCK) | $t_{TCYC}$             | 40 <sup>5</sup> | —   | ns   |
|      | Absolute minimum TCK cycle time <sup>4</sup> (TDO sampled on negedge of TCK) |                        | 20 <sup>5</sup> | —   |      |
| 9    | TCK Duty Cycle                                                               | $t_{TDC}$              | 40              | 60  | %    |
| 10   | TDI, TMS Data Setup Time <sup>6</sup>                                        | $t_{NTDIS}, t_{NTMSS}$ | 8               | —   | ns   |
| 11   | TDI, TMS Data Hold Time <sup>6</sup>                                         | $T_{NTDIH}, t_{NTMSH}$ | 5               | —   | ns   |
| 12   | TCK Low to TDO Data Valid <sup>6</sup>                                       | $t_{NTDOV}$            | 0               | 18  | ns   |
| 13   | $\overline{RDY}$ Valid to MCKO <sup>7</sup>                                  | —                      | —               | —   | —    |
| 14   | TDO hold time after TCLK low <sup>6</sup>                                    | $t_{NTDOH}$            | 1               | —   | ns   |

1. All Nexus timing relative to MCKO is measured from 50% of MCKO and 50% of the respective signal. Nexus timing specified at  $V_{DD} = 1.08\text{ V to }1.32\text{ V}$ ,  $V_{DDE} = 3.0\text{ V to }3.6\text{ V}$ ,  $V_{DD33}$  and  $V_{DDSYN} = 3.0\text{ V to }3.6\text{ V}$ ,  $T_A = T_L$  to  $T_H$ , and  $C_L = 30\text{ pF}$  with  $DSC = 0b10$ .
2. MDO, MSEO, and EVTO data is held valid until next MCKO low cycle.
3. This is a functionally allowable feature. However, it may be limited by the maximum frequency specified by the absolute minimum TCK period specification.
4. This value is TDO propagation time plus 2 ns setup time to sampling edge.
5. This may require a maximum clock speed that is less than the maximum functional capability of the design depending on the actual system frequency being used.
6. Applies to TMS pin timing for the bit frame when using the 1149.7 advanced protocol.
7. The  $\overline{RDY}$  pin timing is asynchronous to MCKO. The timing is guaranteed by design to function correctly.

**Figure 23. Nexus timings**

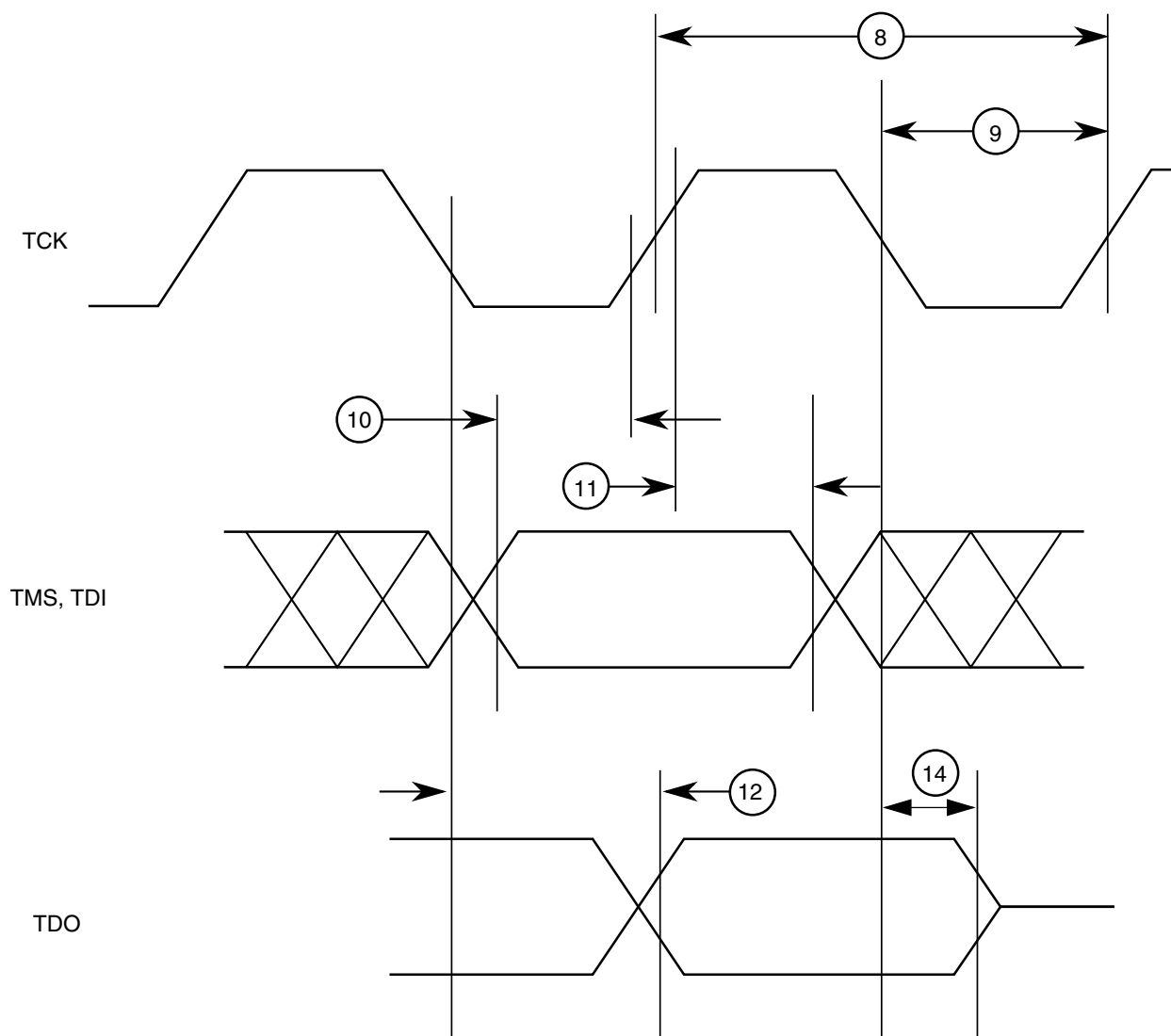


Figure 24. Nexus TCK, TDI, TMS, TDO Timing

### 3.13.5 External Bus Interface (EBI) timing

Table 38. Bus operation timing<sup>1</sup>

| Spec | Characteristic      | Symbol    | 66 MHz (Ext. bus freq.) <sup>2, 3</sup> |                | Unit  | Notes                                   |
|------|---------------------|-----------|-----------------------------------------|----------------|-------|-----------------------------------------|
|      |                     |           | Min                                     | Max            |       |                                         |
| 1    | D_CLKOUT Period     | $t_C$     | 15.2                                    | —              | ns    | Signals are measured at 50% $V_{DDE}$ . |
| 2    | D_CLKOUT Duty Cycle | $t_{CDC}$ | 45%                                     | 55%            | $t_C$ | —                                       |
| 3    | D_CLKOUT Rise Time  | $t_{CRT}$ | —                                       | — <sup>4</sup> | ns    | —                                       |
| 4    | D_CLKOUT Fall Time  | $t_{CFT}$ | —                                       | — <sup>4</sup> | ns    | —                                       |

Table continues on the next page...

**Table 38. Bus operation timing<sup>1</sup> (continued)**

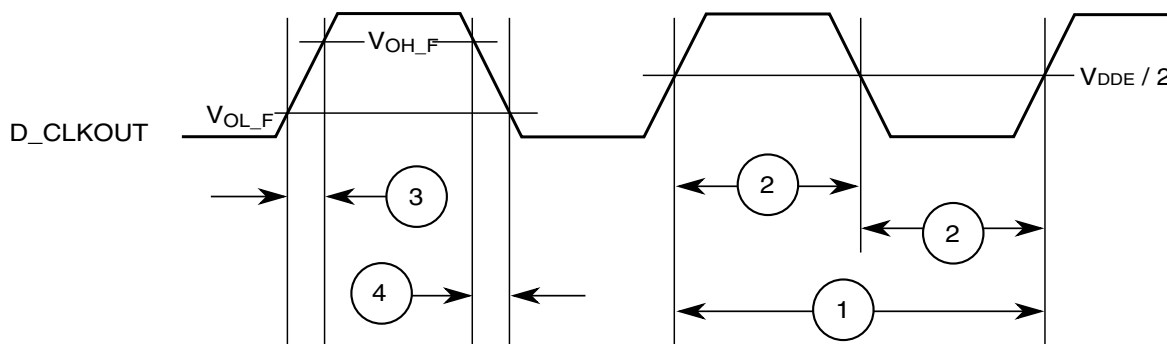
| Spec | Characteristic                                                                                                                                                                 | Symbol           | 66 MHz (Ext. bus freq.) <sup>2, 3</sup> |         | Unit | Notes                                                                                        |
|------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------|-----------------------------------------|---------|------|----------------------------------------------------------------------------------------------|
|      |                                                                                                                                                                                |                  | Min                                     | Max     |      |                                                                                              |
| 5    | D_CLKOUT Posedge to Output Signal Invalid or High Z (Hold Time)<br>D_ADD[9:30]<br>D_BDIP<br>D_CS[0:3]<br>D_DAT[0:15]<br>D_OE<br>D_RD_WR<br>D_TA<br>D_TS<br>D_WE[0:3]/D_BE[0:3] | t <sub>COH</sub> | 1.0/1.5                                 | —       | ns   | Hold time selectable via SIU_ECCR[EBTS] bit:<br>EBTS = 0: 1.0 ns<br>EBTS = 1: 1.5 ns         |
| 6    | D_CLKOUT Posedge to Output Signal Valid (Output Delay)<br>D_ADD[9:30]<br>D_BDIP<br>D_CS[0:3]<br>D_DAT[0:15]<br>D_OE<br>D_RD_WR<br>D_TA<br>D_TS<br>D_WE[0:3]/D_BE[0:3]          | t <sub>COV</sub> | —                                       | 8.5/9.0 | ns   | Output valid time selectable via SIU_ECCR[EBTS] bit:<br>EBTS = 0: 8.5 ns<br>EBTS = 1: 9.0 ns |
|      |                                                                                                                                                                                |                  |                                         | 11.5    |      | —                                                                                            |
|      |                                                                                                                                                                                |                  |                                         | 8.5/9.0 |      | Output valid time selectable via SIU_ECCR[EBTS] bit:<br>EBTS = 0: 8.5 ns<br>EBTS = 1: 9.0 ns |
| 7    | Input Signal Valid to D_CLKOUT Posedge (Setup Time)<br>D_ADD[9:30]<br>D_DAT[0:15]<br>D_RD_WR<br>D_TA<br>D_TS                                                                   | t <sub>CIS</sub> | 7.5                                     | —       | ns   | —                                                                                            |
| 8    | D_CLKOUT Posedge to Input Signal Invalid (Hold Time)<br>D_ADD[9:30]<br>D_DAT[0:15]<br>D_RD_WR<br>D_TA<br>D_TS                                                                  | t <sub>CIH</sub> | 1.0                                     | —       | ns   | —                                                                                            |
| 9    | D_ALE Pulse Width                                                                                                                                                              | t <sub>APW</sub> | 6.5                                     | —       | ns   | The timing is for Asynchronous external memory system.                                       |

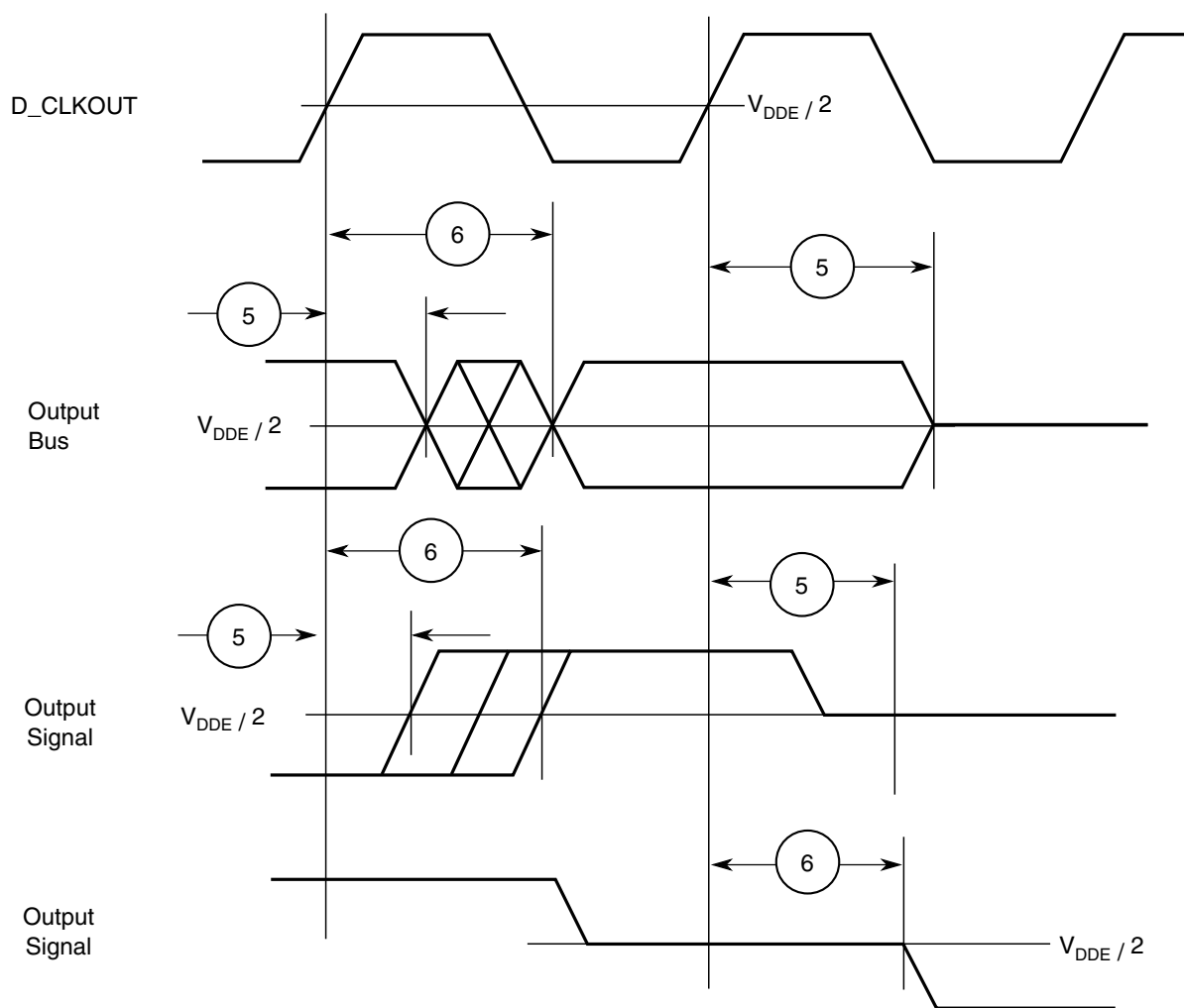
Table continues on the next page...

**Table 38. Bus operation timing<sup>1</sup> (continued)**

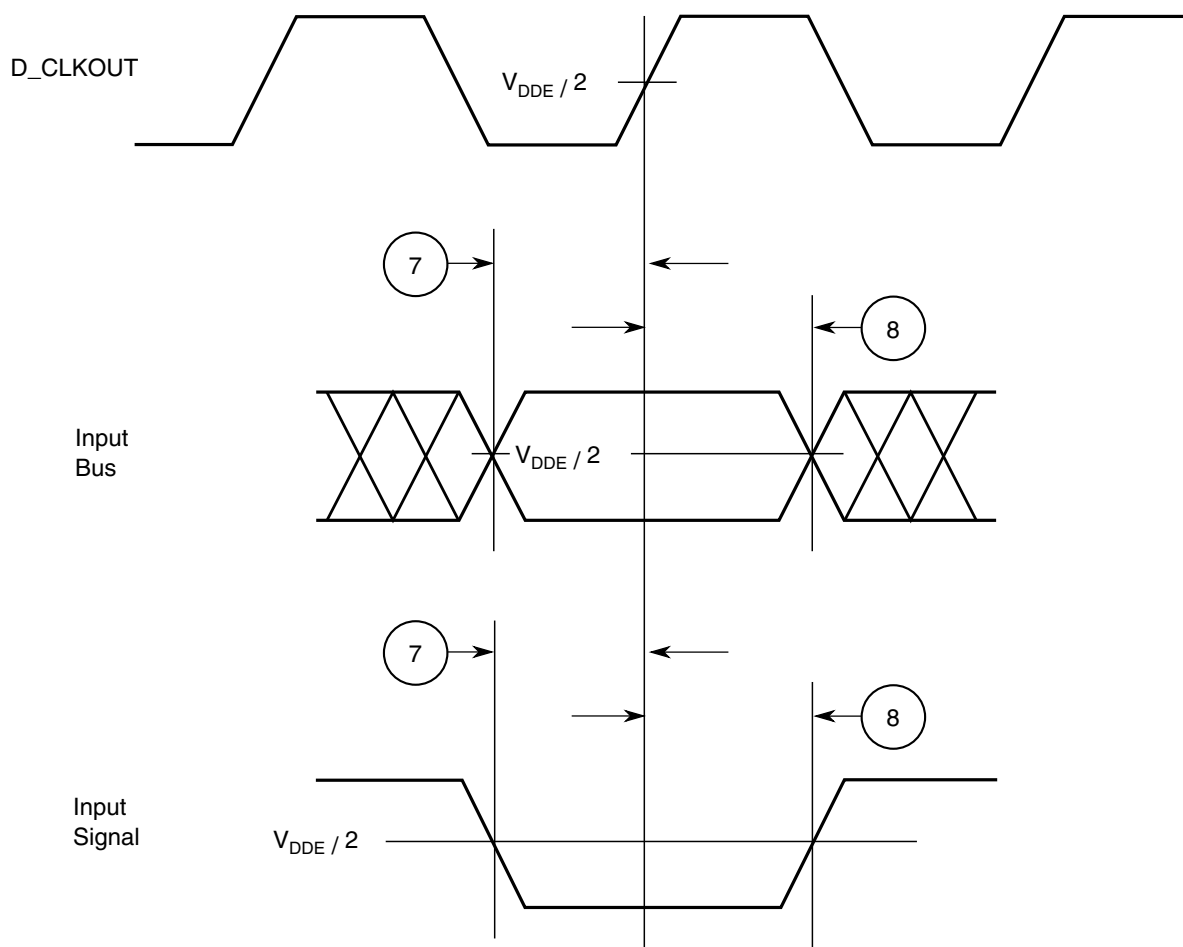
| Spec | Characteristic                   | Symbol    | 66 MHz (Ext. bus freq.) <sup>2, 3</sup> |     | Unit | Notes                                                                                     |
|------|----------------------------------|-----------|-----------------------------------------|-----|------|-------------------------------------------------------------------------------------------|
|      |                                  |           | Min                                     | Max |      |                                                                                           |
| 10   | D_ALE Negated to Address Invalid | $t_{AAI}$ | 2.0/1.0 <sup>5</sup>                    | —   | ns   | The timing is for Asynchronous external memory system.<br>ALE is measured at 50% of VDDE. |

- EBI timing specified at  $V_{DD} = 1.08\text{ V}$  to  $1.32\text{ V}$ ,  $V_{DDE} = 3.0\text{ V}$  to  $3.6\text{ V}$ ,  $T_A = T_L$  to  $T_H$ , and  $C_L = 30\text{ pF}$  with  $SIU\_PCR[DSC] = 11b$  for ADDR/CTRL and  $SIU\_PCR[SRC] = 11b$  for DATA/ALE.
- Speed is the nominal maximum frequency. Max speed is the maximum speed allowed including frequency modulation (FM).
- Depending on the internal bus speed, set the  $SIU\_ECCR[EBDF]$  bits correctly not to exceed maximum external bus frequency. The maximum external bus frequency is 66 MHz.
- Refer to D\_CLKOUT pad timing in [Table 10](#).
- ALE hold time spec is temperature dependant. 1.0 ns spec applies for temperature range  $-40$  to  $0^\circ\text{C}$ . 2.0ns spec applies to temperatures  $> 0^\circ\text{C}$ . This spec has no dependency on the  $SIU\_ECCR[EBTS]$  bit.

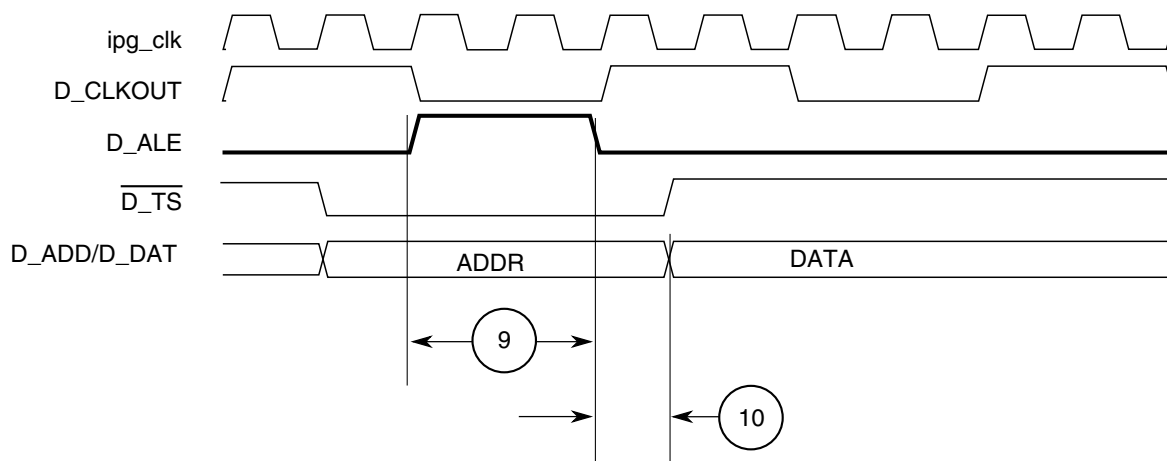
**Figure 25. D\_CLKOUT timing**



**Figure 26. Synchronous output timing**



**Figure 27. Synchronous input timing**



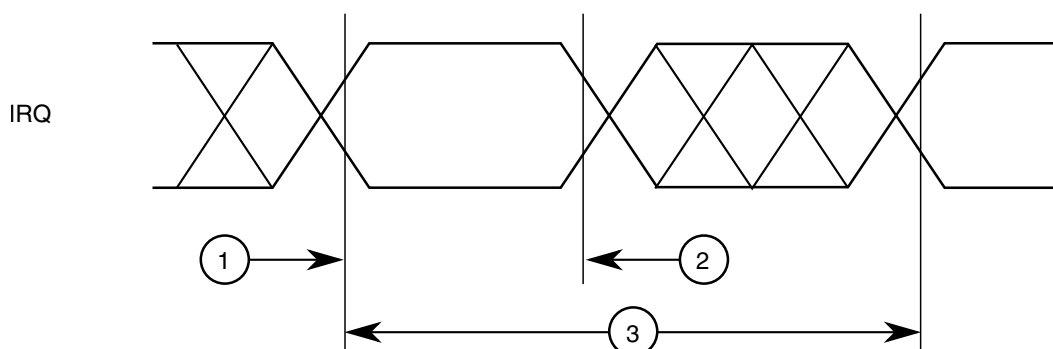
**Figure 28. ALE signal timing**

### 3.13.6 External interrupt timing (IRQ/NMI pin)

**Table 39. External Interrupt timing<sup>1</sup>**

| Spec | Characteristic                         | Symbol     | Min | Max | Unit                   |
|------|----------------------------------------|------------|-----|-----|------------------------|
| 1    | IRQ/NMI Pulse Width Low                | $t_{IPWL}$ | 3   | —   | $t_{cyc}$ <sup>2</sup> |
| 2    | IRQ/NMI Pulse Width High               | $t_{IPWH}$ | 3   | —   | $t_{cyc}$ <sup>2</sup> |
| 3    | IRQ/NMI Edge to Edge Time <sup>3</sup> | $t_{ICYC}$ | 6   | —   | $t_{cyc}$ <sup>2</sup> |

1. IRQ/NMI timing specified at  $V_{DD} = 1.08\text{ V}$  to  $1.32\text{ V}$ ,  $V_{DDEH} = 3.0\text{ V}$  to  $5.5\text{ V}$ ,  $T_A = T_L$  to  $T_H$ .
2. For further information on  $t_{cyc}$ , see [Table 3](#).
3. Applies when IRQ/NMI pins are configured for rising edge or falling edge events, but not both.



**Figure 29. External interrupt timing**

### 3.13.7 eTPU timing

**Table 40. eTPU timing<sup>1</sup>**

| Spec | Characteristic                  | Symbol     | Min            | Max | Unit                         |
|------|---------------------------------|------------|----------------|-----|------------------------------|
| 1    | eTPU Input Channel Pulse Width  | $t_{ICPW}$ | 4              | —   | $t_{CYC\_ETPU}$ <sup>2</sup> |
| 2    | eTPU Output Channel Pulse Width | $t_{OCPW}$ | 1 <sup>3</sup> | —   | $t_{CYC\_ETPU}$ <sup>2</sup> |

1. eTPU timing specified at  $V_{DD} = 1.08\text{ V}$  to  $1.32\text{ V}$ ,  $V_{DDEH} = 3.0\text{ V}$  to  $5.5\text{ V}$ ,  $T_A = T_L$  to  $T_H$ , and  $C_L = 200\text{ pF}$  with  $SRC = 0b00$ .
2. For further information on  $t_{CYC\_ETPU}$ , see [Table 3](#).
3. This specification does not include the rise and fall times. When calculating the minimum eTPU pulse width, include the rise and fall times defined in the slew rate control fields (SRC) of the pad configuration registers (PCR).

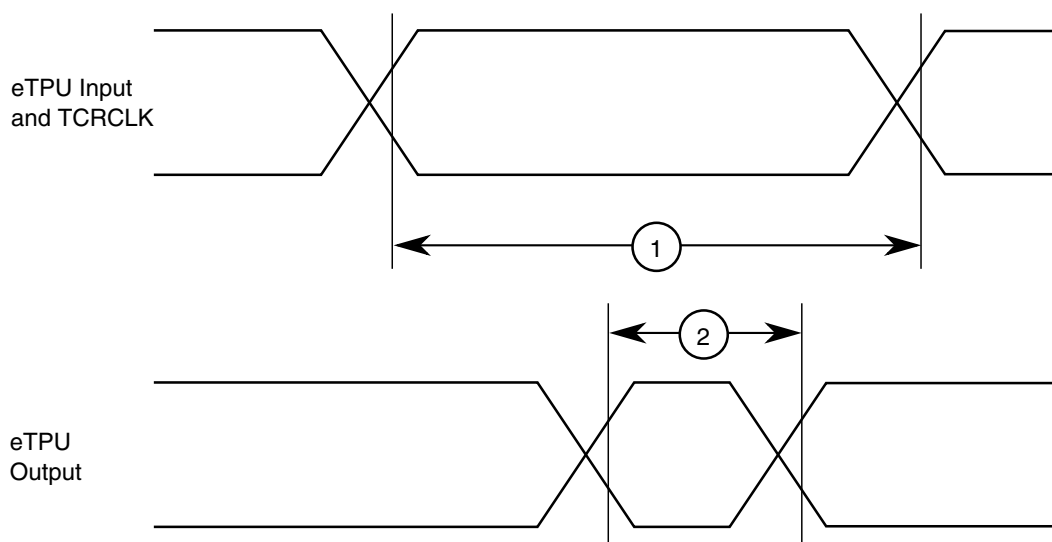


Figure 30. eTPU timing

### 3.13.8 eMIOS timing

Table 41. eMIOS timing<sup>1</sup>

| Spec | Characteristic           | Symbol     | Min            | Max | Unit                        |
|------|--------------------------|------------|----------------|-----|-----------------------------|
| 1    | eMIOS Input Pulse Width  | $t_{MIPW}$ | 4              | —   | $t_{CYC\_PER}$ <sup>2</sup> |
| 2    | eMIOS Output Pulse Width | $t_{MOPW}$ | 1 <sup>3</sup> | —   | $t_{CYC\_PER}$ <sup>2</sup> |

1. eMIOS timing specified at  $V_{DD} = 1.08\text{ V}$  to  $1.32\text{ V}$ ,  $V_{DDEH} = 3.0\text{ V}$  to  $5.5\text{ V}$ ,  $T_A = T_L$  to  $T_H$ , and  $C_L = 50\text{ pF}$  with  $SRC = 0b00$ .
2. For further information on  $t_{CYC\_PER}$ , see [Table 3](#).
3. This specification does not include the rise and fall times. When calculating the minimum eMIOS pulse width, include the rise and fall times defined in the slew rate control fields (SRC) of the pad configuration registers (PCR).

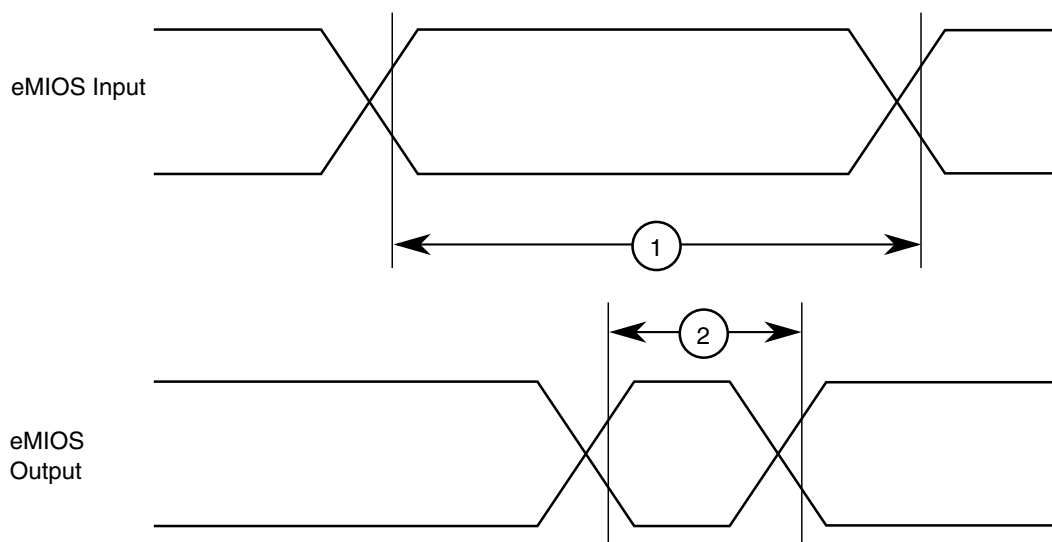


Figure 31. eMIOS timing

### 3.13.9 DSPI timing with CMOS and LVDS pads

#### NOTE

The DSPI in TSB mode with LVDS pads can be used to implement the Micro Second Channel (MSC) bus protocol.

DSPI channel frequency support is shown in [Table 42](#). Timing specifications are shown in [Table 43](#), [Table 44](#), [Table 45](#), [Table 46](#), and [Table 47](#).

**Table 42. DSPI channel frequency support**

| DSPI use mode      |                                                                                           | Max usable frequency (MHz) <sup>1, 2</sup> |
|--------------------|-------------------------------------------------------------------------------------------|--------------------------------------------|
| CMOS (Master mode) | Full duplex – Classic timing ( <a href="#">Table 43</a> )                                 | 17                                         |
|                    | Full duplex – Modified timing ( <a href="#">Table 44</a> )                                | 30                                         |
|                    | Output only mode (SCK/SOUT/PCS) ( <a href="#">Table 43</a> and <a href="#">Table 44</a> ) | 30                                         |
|                    | Output only mode TSB mode (SCK/SOUT/PCS) ( <a href="#">Table 47</a> )                     | 30                                         |
| LVDS (Master mode) | Full duplex – Modified timing ( <a href="#">Table 45</a> )                                | 30                                         |
|                    | Output only mode TSB mode (SCK/SOUT/PCS) ( <a href="#">Table 46</a> )                     | 40                                         |

1. Maximum usable frequency can be achieved if used with fastest configuration of the highest drive pads.
2. Maximum usable frequency does not take into account external device propagation delay.

#### 3.13.9.1 DSPI master mode full duplex timing with CMOS and LVDS pads

##### 3.13.9.1.1 DSPI CMOS Master Mode — Classic Timing

**Table 43. DSPI CMOS master classic timing (full duplex and output only) – MTFE = 0, CPHA = 0 or 1<sup>1</sup>**

| # | Symbol           | Characteristic   | Condition <sup>2</sup>                 |                        | Value <sup>3</sup>                                     |     | Unit |
|---|------------------|------------------|----------------------------------------|------------------------|--------------------------------------------------------|-----|------|
|   |                  |                  | Pad drive <sup>4</sup>                 | Load (C <sub>L</sub> ) | Min                                                    | Max |      |
| 1 | t <sub>SCK</sub> | SCK cycle time   | PCR[SRC]=11b                           | 25 pF                  | 33.0                                                   | —   | ns   |
|   |                  |                  | PCR[SRC]=10b                           | 50 pF                  | 80.0                                                   | —   |      |
|   |                  |                  | PCR[SRC]=01b                           | 50 pF                  | 200.0                                                  | —   |      |
| 2 | t <sub>CSC</sub> | PCS to SCK delay | PCR[SRC]=11b                           | 25 pF                  | (N <sup>5</sup> × t <sub>SYS</sub> <sup>6</sup> ) – 16 | —   | ns   |
|   |                  |                  | PCR[SRC]=10b                           | 50 pF                  | (N <sup>5</sup> × t <sub>SYS</sub> <sup>6</sup> ) – 16 | —   |      |
|   |                  |                  | PCR[SRC]=01b                           | 50 pF                  | (N <sup>5</sup> × t <sub>SYS</sub> <sup>6</sup> ) – 18 | —   |      |
|   |                  |                  | PCS: PCR[SRC]=01b<br>SCK: PCR[SRC]=10b | 50 pF                  | (N <sup>5</sup> × t <sub>SYS</sub> <sup>6</sup> ) – 45 | —   |      |

Table continues on the next page...

**Table 43. DSPI CMOS master classic timing (full duplex and output only) – MTFE = 0, CPHA = 0 or 1<sup>1</sup> (continued)**

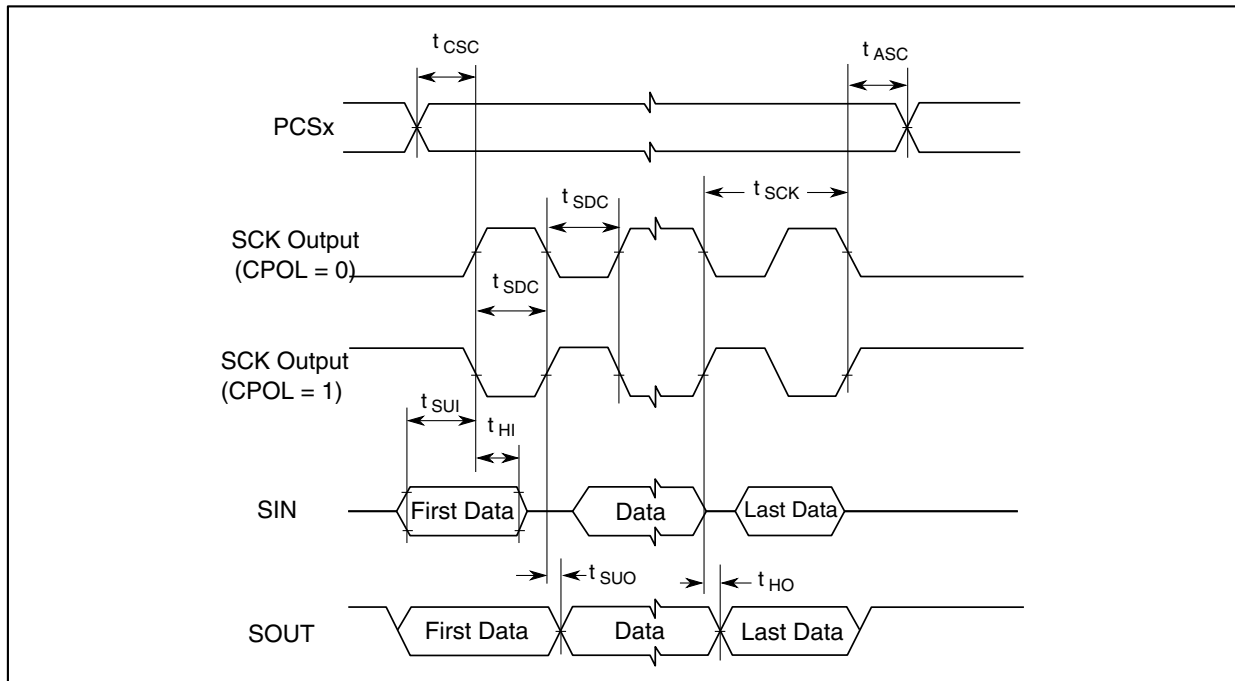
| #                                     | Symbol            | Characteristic                              | Condition <sup>2</sup>                 |                         | Value <sup>3</sup>                                     |                         | Unit |
|---------------------------------------|-------------------|---------------------------------------------|----------------------------------------|-------------------------|--------------------------------------------------------|-------------------------|------|
|                                       |                   |                                             | Pad drive <sup>4</sup>                 | Load (C <sub>L</sub> )  | Min                                                    | Max                     |      |
| 3                                     | t <sub>ASC</sub>  | After SCK delay                             | PCR[SRC]=11b                           | PCS: 0 pF<br>SCK: 50 pF | (M <sup>7</sup> × t <sub>sys</sub> <sup>6</sup> ) – 35 | —                       | ns   |
|                                       |                   |                                             | PCR[SRC]=10b                           | PCS: 0 pF<br>SCK: 50 pF | (M <sup>7</sup> × t <sub>sys</sub> <sup>6</sup> ) – 35 | —                       |      |
|                                       |                   |                                             | PCR[SRC]=01b                           | PCS: 0 pF<br>SCK: 50 pF | (M <sup>7</sup> × t <sub>sys</sub> <sup>6</sup> ) – 35 | —                       |      |
|                                       |                   |                                             | PCS: PCR[SRC]=01b<br>SCK: PCR[SRC]=10b | PCS: 0 pF<br>SCK: 50 pF | (M <sup>7</sup> × t <sub>sys</sub> <sup>6</sup> ) – 35 | —                       |      |
| 4                                     | t <sub>SDC</sub>  | SCK duty cycle <sup>8</sup>                 | PCR[SRC]=11b                           | 0 pF                    | 1/2t <sub>SCK</sub> – 2                                | 1/2t <sub>SCK</sub> + 2 | ns   |
|                                       |                   |                                             | PCR[SRC]=10b                           | 0 pF                    | 1/2t <sub>SCK</sub> – 2                                | 1/2t <sub>SCK</sub> + 2 |      |
|                                       |                   |                                             | PCR[SRC]=01b                           | 0 pF                    | 1/2t <sub>SCK</sub> – 5                                | 1/2t <sub>SCK</sub> + 5 |      |
| PCS strobe timing                     |                   |                                             |                                        |                         |                                                        |                         |      |
| 5                                     | t <sub>PCSC</sub> | PCSx to PCSS time <sup>9</sup>              | PCR[SRC]=10b                           | 25 pF                   | 13.0                                                   | —                       | ns   |
| 6                                     | t <sub>PASC</sub> | PCSS to PCSx time <sup>9</sup>              | PCR[SRC]=10b                           | 25 pF                   | 13.0                                                   | —                       | ns   |
| SIN setup time                        |                   |                                             |                                        |                         |                                                        |                         |      |
| 7                                     | t <sub>SUI</sub>  | SIN setup time to SCK <sup>10</sup>         | PCR[SRC]=11b                           | 25 pF                   | 29.0                                                   | —                       | ns   |
|                                       |                   |                                             | PCR[SRC]=10b                           | 50 pF                   | 31.0                                                   | —                       |      |
|                                       |                   |                                             | PCR[SRC]=01b                           | 50 pF                   | 62.0                                                   | —                       |      |
| SIN hold time                         |                   |                                             |                                        |                         |                                                        |                         |      |
| 8                                     | t <sub>HI</sub>   | SIN hold time from SCK <sup>10</sup>        | PCR[SRC]=11b                           | 0 pF                    | –1.0                                                   | —                       | ns   |
|                                       |                   |                                             | PCR[SRC]=10b                           | 0 pF                    | –1.0                                                   | —                       |      |
|                                       |                   |                                             | PCR[SRC]=01b                           | 0 pF                    | –1.0                                                   | —                       |      |
| SOUT data valid time (after SCK edge) |                   |                                             |                                        |                         |                                                        |                         |      |
| 9                                     | t <sub>SUO</sub>  | SOUT data valid time from SCK <sup>11</sup> | PCR[SRC]=11b                           | 25 pF                   | —                                                      | 7.0                     | ns   |
|                                       |                   |                                             | PCR[SRC]=10b                           | 50 pF                   | —                                                      | 8.0                     |      |
|                                       |                   |                                             | PCR[SRC]=01b                           | 50 pF                   | —                                                      | 18.0                    |      |
| SOUT data hold time (after SCK edge)  |                   |                                             |                                        |                         |                                                        |                         |      |
| 10                                    | t <sub>HO</sub>   | SOUT data hold time after SCK <sup>11</sup> | PCR[SRC]=11b                           | 25 pF                   | –9.0                                                   | —                       | ns   |
|                                       |                   |                                             | PCR[SRC]=10b                           | 50 pF                   | –10.0                                                  | —                       |      |
|                                       |                   |                                             | PCR[SRC]=01b                           | 50 pF                   | –21.0                                                  | —                       |      |

1. All output timing is worst case and includes the mismatching of rise and fall times of the output pads.
2. When a characteristic involves two signals, the pad drive and load conditions apply to each signal's pad, unless specified otherwise.
3. All timing values for output signals in this table are measured to 50% of the output voltage.
4. Pad drive is defined as the PCR[SRC] field setting in the SIU. Timing is guaranteed to same drive capabilities for all signals; mixing of pad drives may reduce operating speeds and may cause incorrect operation.
5. N is the number of clock cycles added to time between PCS assertion and SCK assertion and is software programmable using DSPI\_CTARx[PSSCK] and DSPI\_CTARx[CSSCK]. The minimum value is 2 cycles unless TSB mode or Continuous

## Electrical characteristics

SCK clock mode is selected, in which case, N is automatically set to 0 clock cycles (PCS and SCK are driven by the same edge of DSPI\_CLKn).

6.  $t_{SYS}$  is the period of DSPI\_CLKn clock, the input clock to the DSPI module. Maximum frequency is 100 MHz (min  $t_{SYS} = 10$  ns).
7. M is the number of clock cycles added to time between SCK negation and PCS negation and is software programmable using DSPI\_CTARx[PASC] and DSPI\_CTARx[ASC]. The minimum value is 2 cycles unless TSB mode or Continuous SCK clock mode is selected, in which case, M is automatically set to 0 clock cycles (PCS and SCK are driven by the same edge of DSPI\_CLKn).
8.  $t_{SDC}$  is only valid for even divide ratios. For odd divide ratios the fundamental duty cycle is not 50:50. For these odd divide ratios cases, the absolute spec number is applied as jitter/uncertainty to the nominal high time and low time.
9. PCSx and PCSS using same pad configuration.
10. Input timing assumes an input slew rate of 1 ns (10% – 90%) and uses TTL / Automotive voltage thresholds.
11. SOUT Data Valid and Data hold are independent of load capacitance if SCK and SOUT load capacitances are the same value.



**Figure 32. DSPI CMOS master mode – classic timing, CPHA = 0**

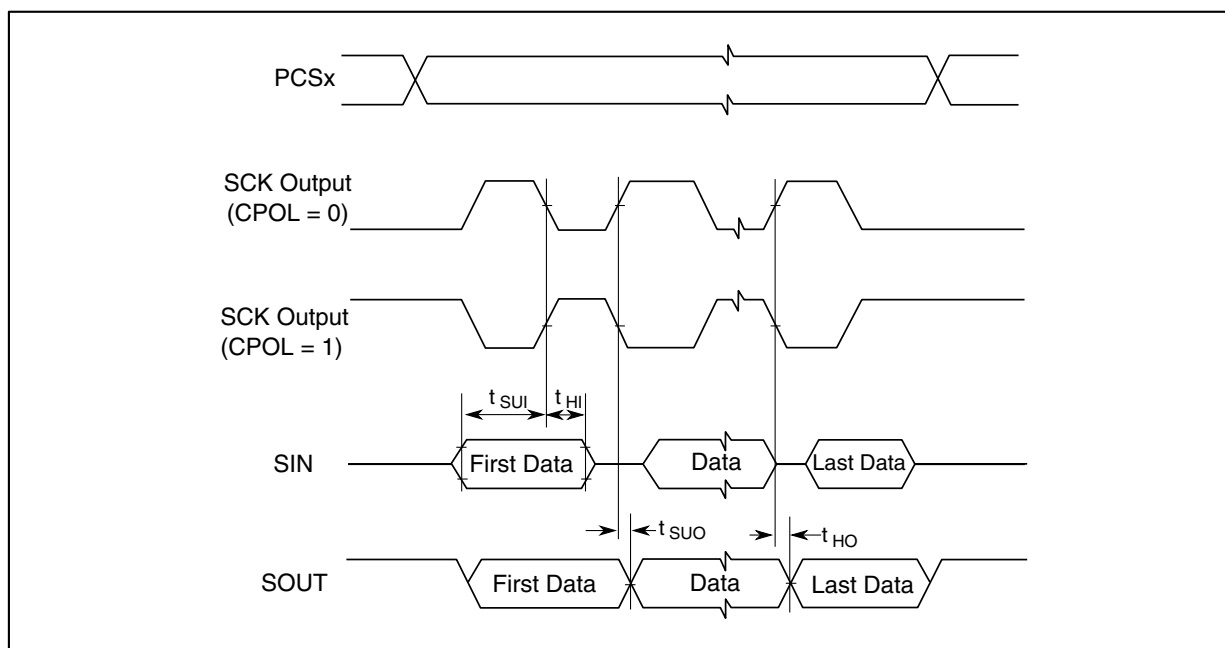


Figure 33. DSPI CMOS master mode – classic timing, CPHA = 1

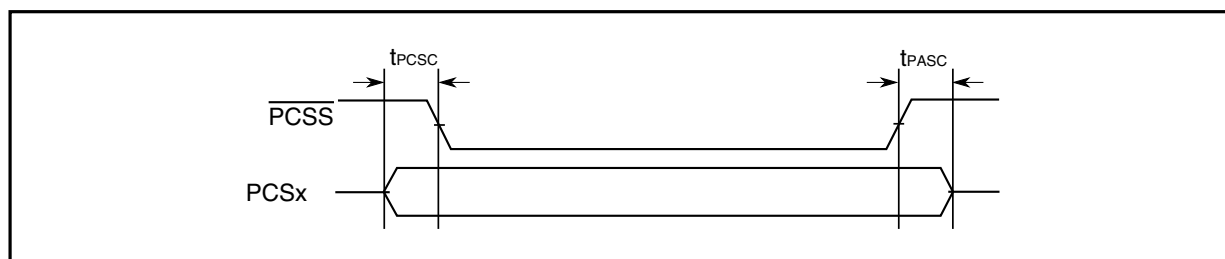


Figure 34. DSPI PCS strobe (PCSS) timing (master mode)

### 3.13.9.1.2 DSPI CMOS Master Mode – Modified Timing

Table 44. DSPI CMOS master modified timing (full duplex and output only) – MTFE = 1, CPHA = 0 or 1<sup>1</sup>

| # | Symbol           | Characteristic   | Condition <sup>2</sup>                 |                        | Value <sup>3</sup>                                      |     | Unit |
|---|------------------|------------------|----------------------------------------|------------------------|---------------------------------------------------------|-----|------|
|   |                  |                  | Pad drive <sup>4</sup>                 | Load (C <sub>L</sub> ) | Min                                                     | Max |      |
| 1 | t <sub>SCK</sub> | SCK cycle time   | PCR[SRC]=11b                           | 25 pF                  | 33.0                                                    | —   | ns   |
|   |                  |                  | PCR[SRC]=10b                           | 50 pF                  | 80.0                                                    | —   |      |
|   |                  |                  | PCR[SRC]=01b                           | 50 pF                  | 200.0                                                   | —   |      |
| 2 | t <sub>CSC</sub> | PCS to SCK delay | PCR[SRC]=11b                           | 25 pF                  | (N <sup>5</sup> × t <sub>sys'</sub> <sup>6</sup> ) – 16 | —   | ns   |
|   |                  |                  | PCR[SRC]=10b                           | 50 pF                  | (N <sup>5</sup> × t <sub>sys'</sub> <sup>6</sup> ) – 16 | —   |      |
|   |                  |                  | PCR[SRC]=01b                           | 50 pF                  | (N <sup>5</sup> × t <sub>sys'</sub> <sup>6</sup> ) – 18 | —   |      |
|   |                  |                  | PCS: PCR[SRC]=01b<br>SCK: PCR[SRC]=10b | 50 pF                  | (N <sup>5</sup> × t <sub>sys'</sub> <sup>6</sup> ) – 45 | —   |      |

Table continues on the next page...

**Table 44. DSPI CMOS master modified timing (full duplex and output only) – MTFE = 1, CPHA = 0 or 1<sup>1</sup> (continued)**

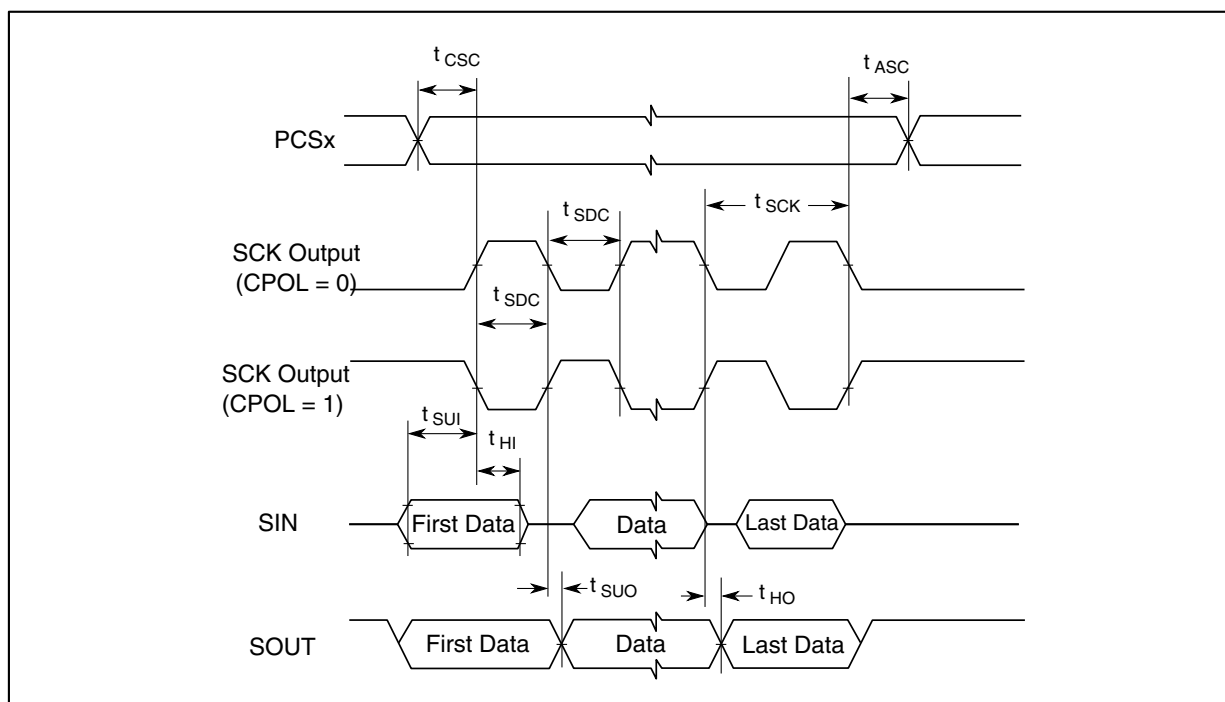
| #                                     | Symbol                        | Characteristic                                          | Condition <sup>2</sup>                 |                         | Value <sup>3</sup>                                      |                                      | Unit |
|---------------------------------------|-------------------------------|---------------------------------------------------------|----------------------------------------|-------------------------|---------------------------------------------------------|--------------------------------------|------|
|                                       |                               |                                                         | Pad drive <sup>4</sup>                 | Load (C <sub>L</sub> )  | Min                                                     | Max                                  |      |
| 3                                     | t <sub>ASC</sub>              | After SCK delay                                         | PCR[SRC]=11b                           | PCS: 0 pF<br>SCK: 50 pF | (M <sup>7</sup> × t <sub>sys</sub> <sup>6</sup> ) – 35  | —                                    | ns   |
|                                       |                               |                                                         | PCR[SRC]=10b                           | PCS: 0 pF<br>SCK: 50 pF | (M <sup>7</sup> × t <sub>sys</sub> <sup>6</sup> ) – 35  | —                                    |      |
|                                       |                               |                                                         | PCR[SRC]=01b                           | PCS: 0 pF<br>SCK: 50 pF | (M <sup>7</sup> × t <sub>sys</sub> <sup>6</sup> ) – 35  | —                                    |      |
|                                       |                               |                                                         | PCS: PCR[SRC]=01b<br>SCK: PCR[SRC]=10b | PCS: 0 pF<br>SCK: 50 pF | (M <sup>7</sup> × t <sub>sys</sub> <sup>6</sup> ) – 35  | —                                    |      |
| 4                                     | t <sub>SDC</sub>              | SCK duty cycle <sup>8</sup>                             | PCR[SRC]=11b                           | 0 pF                    | 1/2t <sub>SCK</sub> – 2                                 | 1/2t <sub>SCK</sub> + 2              | ns   |
|                                       |                               |                                                         | PCR[SRC]=10b                           | 0 pF                    | 1/2t <sub>SCK</sub> – 2                                 | 1/2t <sub>SCK</sub> + 2              |      |
|                                       |                               |                                                         | PCR[SRC]=01b                           | 0 pF                    | 1/2t <sub>SCK</sub> – 5                                 | 1/2t <sub>SCK</sub> + 5              |      |
| PCS strobe timing                     |                               |                                                         |                                        |                         |                                                         |                                      |      |
| 5                                     | t <sub>PCSC</sub>             | PCSx to PCSS time <sup>9</sup>                          | PCR[SRC]=10b                           | 25 pF                   | 13.0                                                    | —                                    | ns   |
| 6                                     | t <sub>PASC</sub>             | PCSS to PCSx time <sup>9</sup>                          | PCR[SRC]=10b                           | 25 pF                   | 13.0                                                    | —                                    | ns   |
| SIN setup time                        |                               |                                                         |                                        |                         |                                                         |                                      |      |
| 7                                     | t <sub>SUI</sub>              | SIN setup time to SCK<br>CPHA = 0 <sup>10</sup>         | PCR[SRC]=11b                           | 25 pF                   | 29 – (P <sup>11</sup> × t <sub>sys</sub> <sup>6</sup> ) | —                                    | ns   |
|                                       |                               |                                                         | PCR[SRC]=10b                           | 50 pF                   | 31 – (P <sup>11</sup> × t <sub>sys</sub> <sup>6</sup> ) | —                                    |      |
|                                       |                               |                                                         | PCR[SRC]=01b                           | 50 pF                   | 62 – (P <sup>11</sup> × t <sub>sys</sub> <sup>6</sup> ) | —                                    |      |
|                                       |                               | SIN setup time to SCK<br>CPHA = 1 <sup>10</sup>         | PCR[SRC]=11b                           | 25 pF                   | 29.0                                                    | —                                    | ns   |
|                                       |                               |                                                         | PCR[SRC]=10b                           | 50 pF                   | 31.0                                                    | —                                    |      |
|                                       |                               |                                                         | PCR[SRC]=01b                           | 50 pF                   | 62.0                                                    | —                                    |      |
| SIN hold time                         |                               |                                                         |                                        |                         |                                                         |                                      |      |
| 8                                     | t <sub>HI</sub> <sup>12</sup> | SIN hold time from SCK<br>CPHA = 0 <sup>10</sup>        | PCR[SRC]=11b                           | 0 pF                    | –1 + (P <sup>11</sup> × t <sub>sys</sub> <sup>6</sup> ) | —                                    | ns   |
|                                       |                               |                                                         | PCR[SRC]=10b                           | 0 pF                    | –1 + (P <sup>11</sup> × t <sub>sys</sub> <sup>6</sup> ) | —                                    |      |
|                                       |                               |                                                         | PCR[SRC]=01b                           | 0 pF                    | –1 + (P <sup>11</sup> × t <sub>sys</sub> <sup>6</sup> ) | —                                    |      |
|                                       |                               | SIN hold time from SCK<br>CPHA = 1 <sup>10</sup>        | PCR[SRC]=11b                           | 0 pF                    | –1.0                                                    | —                                    | ns   |
|                                       |                               |                                                         | PCR[SRC]=10b                           | 0 pF                    | –1.0                                                    | —                                    |      |
|                                       |                               |                                                         | PCR[SRC]=01b                           | 0 pF                    | –1.0                                                    | —                                    |      |
| SOUT data valid time (after SCK edge) |                               |                                                         |                                        |                         |                                                         |                                      |      |
| 9                                     | t <sub>SUO</sub>              | SOUT data valid time from SCK<br>CPHA = 0 <sup>13</sup> | PCR[SRC]=11b                           | 25 pF                   | —                                                       | 7.0 + t <sub>sys</sub> <sup>6</sup>  | ns   |
|                                       |                               |                                                         | PCR[SRC]=10b                           | 50 pF                   | —                                                       | 8.0 + t <sub>sys</sub> <sup>6</sup>  |      |
|                                       |                               |                                                         | PCR[SRC]=01b                           | 50 pF                   | —                                                       | 18.0 + t <sub>sys</sub> <sup>6</sup> |      |
|                                       |                               | SOUT data valid time from SCK<br>CPHA = 1 <sup>13</sup> | PCR[SRC]=11b                           | 25 pF                   | —                                                       | 7.0                                  | ns   |
|                                       |                               |                                                         | PCR[SRC]=10b                           | 50 pF                   | —                                                       | 8.0                                  |      |
|                                       |                               |                                                         | PCR[SRC]=01b                           | 50 pF                   | —                                                       | 18.0                                 |      |
| SOUT data hold time (after SCK edge)  |                               |                                                         |                                        |                         |                                                         |                                      |      |

Table continues on the next page...

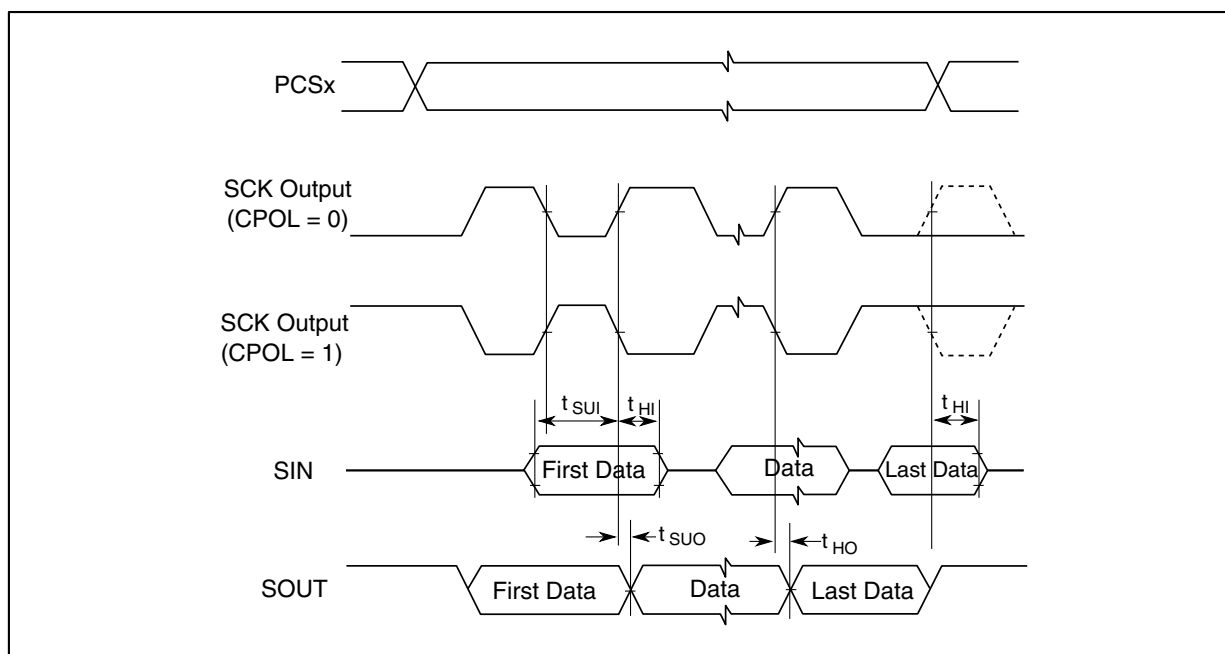
**Table 44. DSPI CMOS master modified timing (full duplex and output only) – MTFE = 1, CPHA = 0 or 1<sup>1</sup> (continued)**

| #  | Symbol          | Characteristic                                          | Condition <sup>2</sup> |                        | Value <sup>3</sup>                    |     | Unit |
|----|-----------------|---------------------------------------------------------|------------------------|------------------------|---------------------------------------|-----|------|
|    |                 |                                                         | Pad drive <sup>4</sup> | Load (C <sub>L</sub> ) | Min                                   | Max |      |
| 10 | t <sub>HO</sub> | SOUT data hold time after SCK<br>CPHA = 0 <sup>13</sup> | PCR[SRC]=11b           | 25 pF                  | -9.0 + t <sub>SYS</sub> <sup>6</sup>  | —   | ns   |
|    |                 |                                                         | PCR[SRC]=10b           | 50 pF                  | -10.0 + t <sub>SYS</sub> <sup>6</sup> | —   |      |
|    |                 |                                                         | PCR[SRC]=01b           | 50 pF                  | -21.0 + t <sub>SYS</sub> <sup>6</sup> | —   |      |
|    |                 | SOUT data hold time after SCK<br>CPHA = 1 <sup>13</sup> | PCR[SRC]=11b           | 25 pF                  | -9.0                                  | —   | ns   |
|    |                 |                                                         | PCR[SRC]=10b           | 50 pF                  | -10.0                                 | —   |      |
|    |                 |                                                         | PCR[SRC]=01b           | 50 pF                  | -21.0                                 | —   |      |

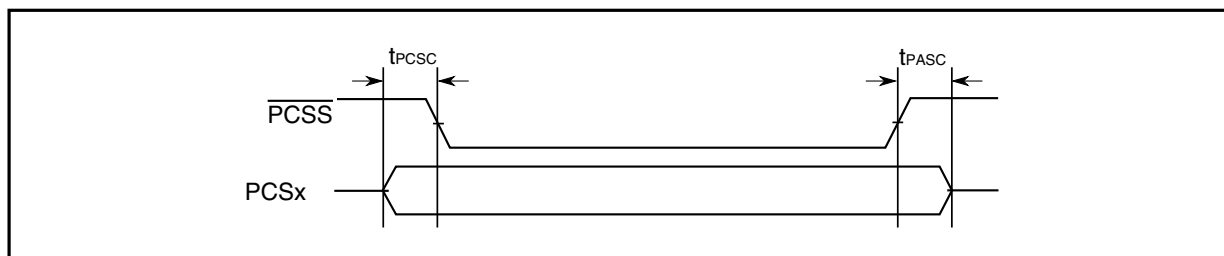
1. All output timing is worst case and includes the mismatching of rise and fall times of the output pads.
2. When a characteristic involves two signals, the pad drive and load conditions apply to each signal's pad, unless specified otherwise.
3. All timing values for output signals in this table are measured to 50% of the output voltage.
4. Pad drive is defined as the PCR[SRC] field setting in the SIU. Timing is guaranteed to same drive capabilities for all signals; mixing of pad drives may reduce operating speeds and may cause incorrect operation.
5. N is the number of clock cycles added to time between PCS assertion and SCK assertion and is software programmable using DSPI\_CTARx[PSSCK] and DSPI\_CTARx[CSSCK]. The minimum value is 2 cycles unless TSB mode or Continuous SCK clock mode is selected, in which case, N is automatically set to 0 clock cycles (PCS and SCK are driven by the same edge of DSPI\_CLKn).
6. t<sub>SYS</sub> is the period of DSPI\_CLKn clock, the input clock to the DSPI module. Maximum frequency is 100 MHz (min t<sub>SYS</sub> = 10 ns).
7. M is the number of clock cycles added to time between SCK negation and PCS negation and is software programmable using DSPI\_CTARx[PASC] and DSPI\_CTARx[ASC]. The minimum value is 2 cycles unless TSB mode or Continuous SCK clock mode is selected, in which case, M is automatically set to 0 clock cycles (PCS and SCK are driven by the same edge of DSPI\_CLKn).
8. t<sub>SDC</sub> is only valid for even divide ratios. For odd divide ratios the fundamental duty cycle is not 50:50. For these odd divide ratios cases, the absolute spec number is applied as jitter/uncertainty to the nominal high time and low time.
9. PCSx and PCSS using same pad configuration.
10. Input timing assumes an input slew rate of 1 ns (10% – 90%) and uses TTL / Automotive voltage thresholds.
11. P is the number of clock cycles added to delay the DSPI input sample point and is software programmable using DSPI\_MCR[SMPL\_PT]. The value must be 0, 1 or 2. If the baud rate divide ratio is /2 or /3, this value is automatically set to 1.
12. The 0 pF load condition given in the DSPI AC timing applies to theoretical worst-case hold timing. This guarantees worst-case operation, and additional margin can be achieved in the applications by applying a realistic load.
13. SOUT Data Valid and Data hold are independent of load capacitance if SCK and SOUT load capacitances are the same value.



**Figure 35. DSPI CMOS master mode – modified timing, CPHA = 0**



**Figure 36. DSPI CMOS master mode – modified timing, CPHA = 1**

Figure 37. DSPI PCS strobe ( $\overline{\text{PCSS}}$ ) timing (master mode)

## 3.13.9.1.3 DSPI LVDS Master Mode – Modified Timing

Table 45. DSPI LVDS master timing – full duplex – modified transfer format (MTFE = 1), CPHA = 0 or 1

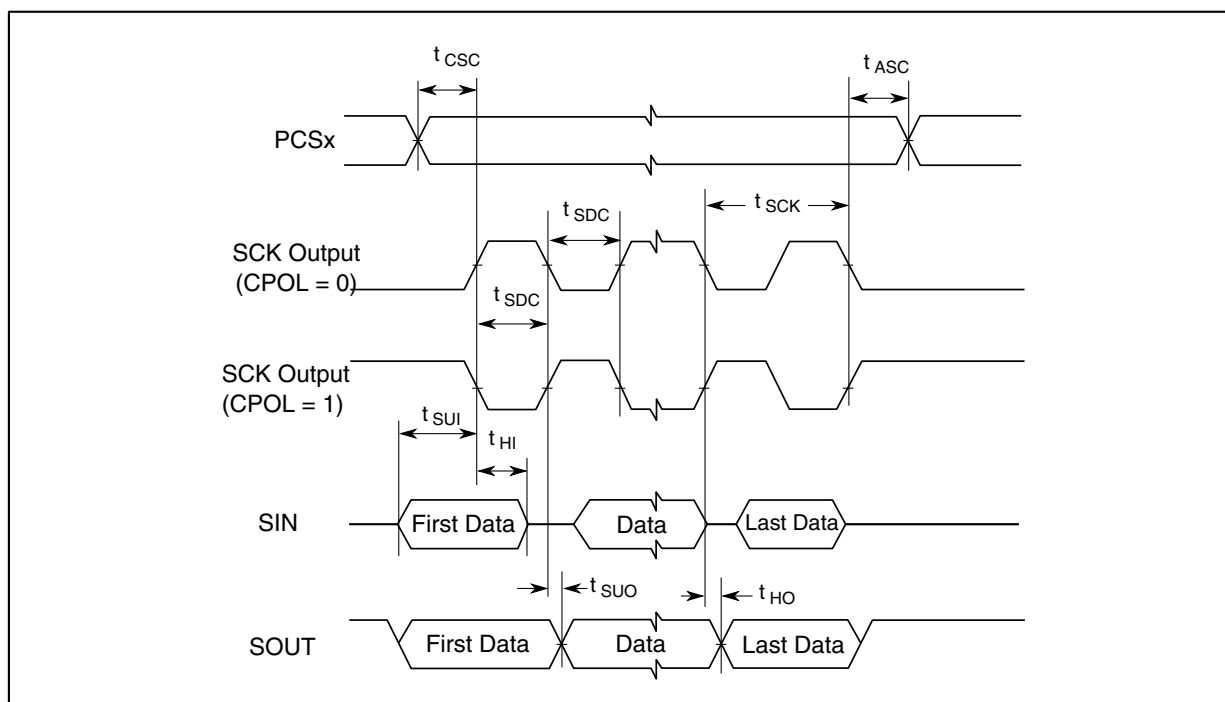
| # | Symbol           | Characteristic                                  | Condition <sup>1</sup> |                             | Value <sup>2</sup>                   |                         | Unit |
|---|------------------|-------------------------------------------------|------------------------|-----------------------------|--------------------------------------|-------------------------|------|
|   |                  |                                                 | Pad drive <sup>3</sup> | Load ( $C_L$ )              | Min                                  | Max                     |      |
| 1 | $t_{\text{SCK}}$ | SCK cycle time                                  | LVDS                   | 15 pF to 25 pF differential | 33.3                                 | —                       | ns   |
| 2 | $t_{\text{CSC}}$ | PCS to SCK delay (LVDS SCK)                     | PCS: PCR[SRC]=11b      | 25 pF                       | $(N^4 \times t_{\text{SYS}}^5) - 10$ | —                       | ns   |
|   |                  |                                                 | PCS: PCR[SRC]=10b      | 50 pF                       | $(N^4 \times t_{\text{SYS}}^5) - 10$ | —                       | ns   |
|   |                  |                                                 | PCS: PCR[SRC]=01b      | 50 pF                       | $(N^4 \times t_{\text{SYS}}^5) - 32$ | —                       | ns   |
| 3 | $t_{\text{ASC}}$ | After SCK delay (LVDS SCK)                      | PCS: PCR[SRC]=11b      | PCS: 0 pF<br>SCK: 25 pF     | $(M^6 \times t_{\text{SYS}}^5) - 8$  | —                       | ns   |
|   |                  |                                                 | PCS: PCR[SRC]=10b      | PCS: 0 pF<br>SCK: 25 pF     | $(M^6 \times t_{\text{SYS}}^5) - 8$  | —                       | ns   |
|   |                  |                                                 | PCS: PCR[SRC]=01b      | PCS: 0 pF<br>SCK: 25 pF     | $(M^6 \times t_{\text{SYS}}^5) - 8$  | —                       | ns   |
| 4 | $t_{\text{SDC}}$ | SCK duty cycle <sup>7</sup>                     | LVDS                   | 15 pF to 25 pF differential | $1/2t_{\text{SCK}} - 2$              | $1/2t_{\text{SCK}} + 2$ | ns   |
| 7 | $t_{\text{SUI}}$ | SIN setup time                                  |                        |                             |                                      |                         |      |
|   |                  | SIN setup time to SCK<br>CPHA = 0 <sup>8</sup>  | LVDS                   | 15 pF to 25 pF differential | $23 - (P^9 \times t_{\text{SYS}}^5)$ | —                       | ns   |
|   |                  | SIN setup time to SCK<br>CPHA = 1 <sup>8</sup>  | LVDS                   | 15 pF to 25 pF differential | 23                                   | —                       | ns   |
| 8 | $t_{\text{HI}}$  | SIN hold time                                   |                        |                             |                                      |                         |      |
|   |                  | SIN hold time from SCK<br>CPHA = 0 <sup>8</sup> | LVDS                   | 0 pF differential           | $-1 + (P^9 \times t_{\text{SYS}}^5)$ | —                       | ns   |
|   |                  | SIN hold time from SCK<br>CPHA = 1 <sup>8</sup> | LVDS                   | 0 pF differential           | -1                                   | —                       | ns   |

Table continues on the next page...

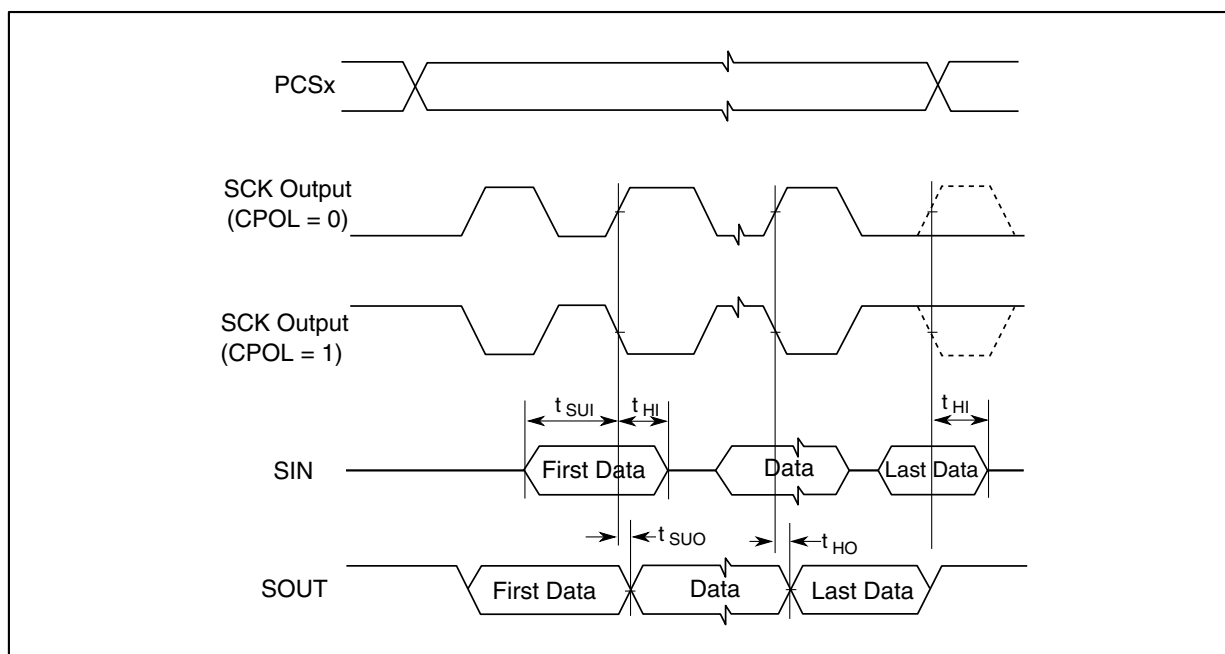
**Table 45. DSPI LVDS master timing – full duplex – modified transfer format (MTFE = 1), CPHA = 0 or 1 (continued)**

| #  | Symbol           | Characteristic                                          | Condition <sup>1</sup> |                             | Value <sup>2</sup>                   |                                     | Unit |
|----|------------------|---------------------------------------------------------|------------------------|-----------------------------|--------------------------------------|-------------------------------------|------|
|    |                  |                                                         | Pad drive <sup>3</sup> | Load (C <sub>L</sub> )      | Min                                  | Max                                 |      |
| 9  | t <sub>SUO</sub> | SOUT data valid time (after SCK edge)                   |                        |                             |                                      |                                     |      |
|    |                  | SOUT data valid time from SCK<br>CPHA = 0 <sup>10</sup> | LVDS                   | 15 pF to 25 pF differential | —                                    | 7.0 + t <sub>SYS</sub> <sup>5</sup> | ns   |
|    |                  | SOUT data valid time from SCK<br>CPHA = 1 <sup>10</sup> | LVDS                   | 15 pF to 25 pF differential | —                                    | 7.0                                 | ns   |
| 10 | t <sub>HO</sub>  | SOUT data hold time (after SCK edge)                    |                        |                             |                                      |                                     |      |
|    |                  | SOUT data hold time after SCK<br>CPHA = 0 <sup>10</sup> | LVDS                   | 15 pF to 25 pF differential | −7.5 + t <sub>SYS</sub> <sup>5</sup> | —                                   | ns   |
|    |                  | SOUT data hold time after SCK<br>CPHA = 1 <sup>10</sup> | LVDS                   | 15 pF to 25 pF differential | −7.5                                 | —                                   | ns   |

- When a characteristic involves two signals, the pad drive and load conditions apply to each signal's pad, unless specified otherwise.
- All timing values for output signals in this table are measured to 50% of the output voltage.
- Pad drive is defined as the PCR[Src] field setting in the SIU. Timing is guaranteed to same drive capabilities for all signals; mixing of pad drives may reduce operating speeds and may cause incorrect operation.
- N is the number of clock cycles added to time between PCS assertion and SCK assertion and is software programmable using DSPI\_CTARx[PSSCK] and DSPI\_CTARx[CSSCK]. The minimum value is 2 cycles unless TSB mode or Continuous SCK clock mode is selected, in which case, N is automatically set to 0 clock cycles (PCS and SCK are driven by the same edge of DSPI\_CLKn).
- t<sub>SYS</sub> is the period of DSPI\_CLKn clock, the input clock to the DSPI module. Maximum frequency is 100 MHz (min t<sub>SYS</sub> = 10 ns).
- M is the number of clock cycles added to time between SCK negation and PCS negation and is software programmable using DSPI\_CTARx[PASC] and DSPI\_CTARx[ASC]. The minimum value is 2 cycles unless TSB mode or Continuous SCK clock mode is selected, in which case, M is automatically set to 0 clock cycles (PCS and SCK are driven by the same edge of DSPI\_CLKn).
- t<sub>SDC</sub> is only valid for even divide ratios. For odd divide ratios the fundamental duty cycle is not 50:50. For these odd divide ratios cases, the absolute spec number is applied as jitter/uncertainty to the nominal high time and low time.
- Input timing assumes an input slew rate of 1 ns (10% – 90%) and LVDS differential voltage = ±100 mV.
- P is the number of clock cycles added to delay the DSPI input sample point and is software programmable using DSPI\_MCR[SMPL\_PT]. The value must be 0, 1 or 2. If the baud rate divide ratio is /2 or /3, this value is automatically set to 1.
- SOUT Data Valid and Data hold are independent of load capacitance if SCK and SOUT load capacitances are the same value.



**Figure 38. DSPI LVDS master mode – modified timing, CPHA = 0**



**Figure 39. DSPI LVDS master mode – modified timing, CPHA = 1**

**3.13.9.1.4 DSPI Master Mode – Output Only****Table 46. DSPI LVDS master timing — output only — timed serial bus mode**  
**TSB = 1 or ITSB = 1, CPOL = 0 or 1, continuous SCK clock<sup>1, 2</sup>**

| #                                            | Symbol           | Characteristic                                                              | Condition <sup>3</sup> |                             | Value <sup>4</sup>      |                         | Unit |
|----------------------------------------------|------------------|-----------------------------------------------------------------------------|------------------------|-----------------------------|-------------------------|-------------------------|------|
|                                              |                  |                                                                             | Pad drive <sup>5</sup> | Load (C <sub>L</sub> )      | Min                     | Max                     |      |
| 1                                            | t <sub>SCK</sub> | SCK cycle time                                                              | LVDS                   | 15 pF to 50 pF differential | 25                      | —                       | ns   |
| 2                                            | t <sub>CSV</sub> | PCS valid after SCK <sup>6</sup><br>(SCK with 50 pF differential load cap.) | PCR[SRC]=11b           | 25 pF                       | —                       | 8                       | ns   |
|                                              |                  |                                                                             | PCR[SRC]=10b           | 50 pF                       | —                       | 12                      | ns   |
| 3                                            | t <sub>CSH</sub> | PCS hold after SCK <sup>6</sup><br>(SCK with 50 pF differential load cap.)  | PCR[SRC]=11b           | 0 pF                        | –4.0                    | —                       | ns   |
|                                              |                  |                                                                             | PCR[SRC]=10b           | 0 pF                        | –4.0                    | —                       | ns   |
| 4                                            | t <sub>SDC</sub> | SCK duty cycle (SCK with 50 pF differential load cap.)                      | LVDS                   | 15 pF to 50 pF differential | 1/2t <sub>SCK</sub> – 2 | 1/2t <sub>SCK</sub> + 2 | ns   |
| <b>SOUT data valid time (after SCK edge)</b> |                  |                                                                             |                        |                             |                         |                         |      |
| 5                                            | t <sub>SUO</sub> | SOUT data valid time from SCK <sup>7</sup>                                  | LVDS                   | 15 pF to 50 pF differential | —                       | 6                       | ns   |
| <b>SOUT data hold time (after SCK edge)</b>  |                  |                                                                             |                        |                             |                         |                         |      |
| 6                                            | t <sub>HO</sub>  | SOUT data hold time after SCK <sup>7</sup>                                  | LVDS                   | 15 pF to 50 pF differential | –7.0                    | —                       | ns   |

1. All DSPI timing specifications apply to pins when using LVDS pads for SCK and SOUT and CMOS pad for PCS with pad driver strength as defined. Timing may degrade for weaker output drivers.
2. TSB = 1 or ITSB = 1 automatically selects MTFE = 1 and CPHA = 1.
3. When a characteristic involves two signals, the pad drive and load conditions apply to each signal's pad, unless specified otherwise.
4. All timing values for output signals in this table are measured to 50% of the output voltage.
5. Pad drive is defined as the PCR[SRC] field setting in the SIU. Timing is guaranteed to same drive capabilities for all signals; mixing of pad drives may reduce operating speeds and may cause incorrect operation.
6. With TSB mode or Continuous SCK clock mode selected, PCS and SCK are driven by the same edge of DSPI\_CLKn. This timing value is due to pad delays and signal propagation delays.
7. SOUT Data Valid and Data hold are independent of load capacitance if SCK and SOUT load capacitances are the same value.

**Table 47. DSPI CMOS master timing – output only – timed serial bus mode**  
**TSB = 1 or ITSB = 1, CPOL = 0 or 1, continuous SCK clock<sup>1, 2</sup>**

| # | Symbol           | Characteristic                   | Condition <sup>3</sup>                 |                        | Value <sup>4</sup> |     | Unit |
|---|------------------|----------------------------------|----------------------------------------|------------------------|--------------------|-----|------|
|   |                  |                                  | Pad drive <sup>5</sup>                 | Load (C <sub>L</sub> ) | Min                | Max |      |
| 1 | t <sub>SCK</sub> | SCK cycle time                   | PCR[SRC]=11b                           | 25 pF                  | 33.0               | —   | ns   |
|   |                  |                                  | PCR[SRC]=10b                           | 50 pF                  | 80.0               | —   | ns   |
|   |                  |                                  | PCR[SRC]=01b                           | 50 pF                  | 200.0              | —   | ns   |
| 2 | t <sub>CSV</sub> | PCS valid after SCK <sup>6</sup> | PCR[SRC]=11b                           | 25 pF                  | 7                  | —   | ns   |
|   |                  |                                  | PCR[SRC]=10b                           | 50 pF                  | 8                  | —   | ns   |
|   |                  |                                  | PCR[SRC]=01b                           | 50 pF                  | 18                 | —   | ns   |
|   |                  |                                  | PCS: PCR[SRC]=01b<br>SCK: PCR[SRC]=10b | 50 pF                  | 45                 | —   | ns   |

Table continues on the next page...

**Table 47. DSPI CMOS master timing – output only – timed serial bus mode TSB = 1 or ITSB = 1, CPOL = 0 or 1, continuous SCK clock <sup>1, 2</sup> (continued)**

| #                                     | Symbol           | Characteristic                                         | Condition <sup>3</sup>                 |                         | Value <sup>4</sup>      |                         | Unit |
|---------------------------------------|------------------|--------------------------------------------------------|----------------------------------------|-------------------------|-------------------------|-------------------------|------|
|                                       |                  |                                                        | Pad drive <sup>5</sup>                 | Load (C <sub>L</sub> )  | Min                     | Max                     |      |
| 3                                     | t <sub>CSH</sub> | PCS hold after SCK <sup>6</sup>                        | PCR[SRC]=11b                           | PCS: 0 pF<br>SCK: 50 pF | −14                     | —                       | ns   |
|                                       |                  |                                                        | PCR[SRC]=10b                           | PCS: 0 pF<br>SCK: 50 pF | −14                     | —                       | ns   |
|                                       |                  |                                                        | PCR[SRC]=01b                           | PCS: 0 pF<br>SCK: 50 pF | −33                     | —                       | ns   |
|                                       |                  |                                                        | PCS: PCR[SRC]=01b<br>SCK: PCR[SRC]=10b | PCS: 0 pF<br>SCK: 50 pF | −35                     | —                       | ns   |
| 4                                     | t <sub>SDC</sub> | SCK duty cycle <sup>7</sup>                            | PCR[SRC]=11b                           | 0 pF                    | 1/2t <sub>SCK</sub> − 2 | 1/2t <sub>SCK</sub> + 2 | ns   |
|                                       |                  |                                                        | PCR[SRC]=10b                           | 0 pF                    | 1/2t <sub>SCK</sub> − 2 | 1/2t <sub>SCK</sub> + 2 | ns   |
|                                       |                  |                                                        | PCR[SRC]=01b                           | 0 pF                    | 1/2t <sub>SCK</sub> − 5 | 1/2t <sub>SCK</sub> + 5 | ns   |
| SOUT data valid time (after SCK edge) |                  |                                                        |                                        |                         |                         |                         |      |
| 9                                     | t <sub>SUO</sub> | SOUT data valid time from SCK<br>CPHA = 1 <sup>8</sup> | PCR[SRC]=11b                           | 25 pF                   | —                       | 7.0                     | ns   |
|                                       |                  |                                                        | PCR[SRC]=10b                           | 50 pF                   | —                       | 8.0                     | ns   |
|                                       |                  |                                                        | PCR[SRC]=01b                           | 50 pF                   | —                       | 18.0                    | ns   |
| SOUT data hold time (after SCK edge)  |                  |                                                        |                                        |                         |                         |                         |      |
| 10                                    | t <sub>HO</sub>  | SOUT data hold time after SCK<br>CPHA = 1 <sup>8</sup> | PCR[SRC]=11b                           | 25 pF                   | −9.0                    | —                       | ns   |
|                                       |                  |                                                        | PCR[SRC]=10b                           | 50 pF                   | −10.0                   | —                       | ns   |
|                                       |                  |                                                        | PCR[SRC]=01b                           | 50 pF                   | −21.0                   | —                       | ns   |

1. TSB = 1 or ITSB = 1 automatically selects MTFE = 1 and CPHA = 1.
2. All output timing is worst case and includes the mismatching of rise and fall times of the output pads.
3. When a characteristic involves two signals, the pad drive and load conditions apply to each signal's pad, unless specified otherwise.
4. All timing values for output signals in this table are measured to 50% of the output voltage.
5. Pad drive is defined as the PCR[SRC] field setting in the SIU. Timing is guaranteed to same drive capabilities for all signals; mixing of pad drives may reduce operating speeds and may cause incorrect operation.
6. With TSB mode or Continuous SCK clock mode selected, PCS and SCK are driven by the same edge of DSPI\_CLKn. This timing value is due to pad delays and signal propagation delays.
7. t<sub>SDC</sub> is only valid for even divide ratios. For odd divide ratios the fundamental duty cycle is not 50:50. For these odd divide ratios cases, the absolute spec number is applied as jitter/uncertainty to the nominal high time and low time.
8. SOUT Data Valid and Data hold are independent of load capacitance if SCK and SOUT load capacitances are the same value.

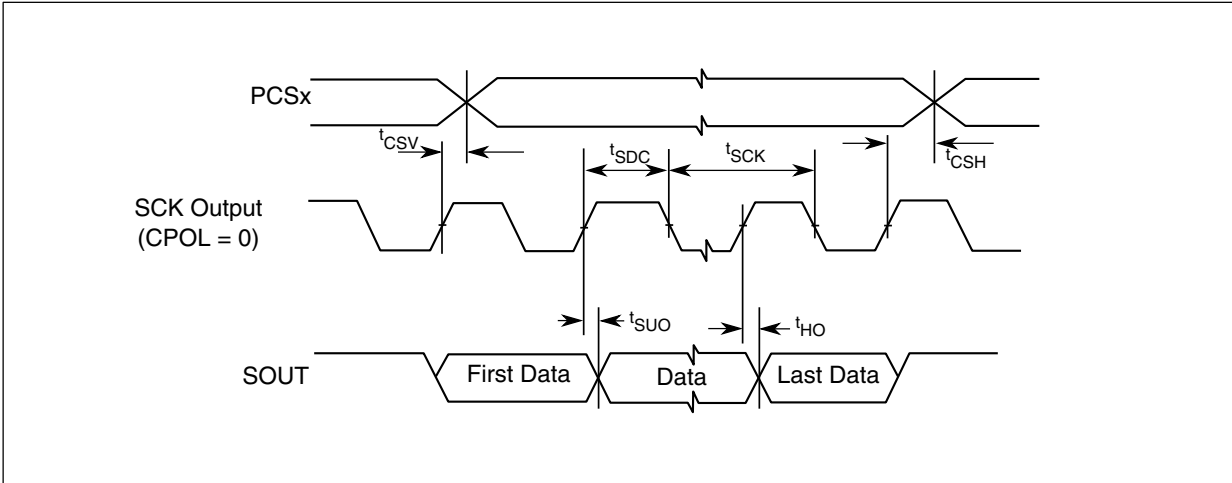


Figure 40. DSPI LVDS and CMOS master timing – output only – modified transfer format  
MTFE = 1, CHPA = 1

### 3.13.10 FEC timing

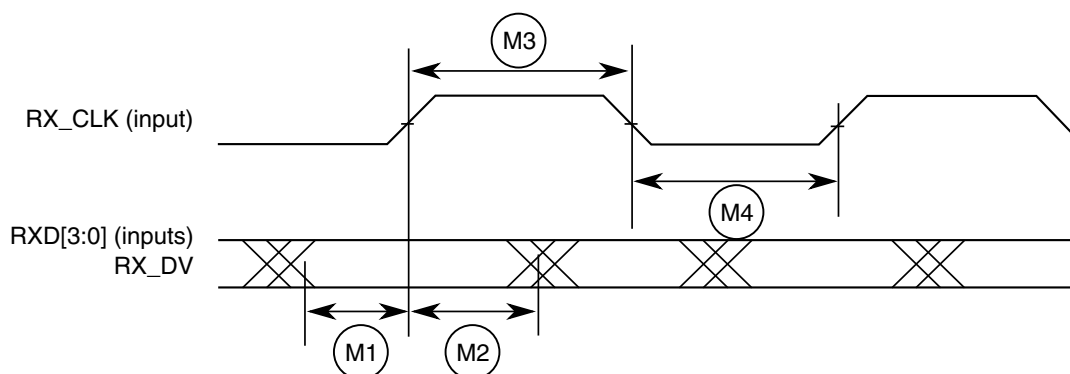
#### 3.13.10.1 MII receive signal timing (RXD[3:0], RX\_DV, and RX\_CLK)

The receiver functions correctly up to a RX\_CLK maximum frequency of 25 MHz +1%. There is no minimum frequency requirement. The system clock frequency must be at least equal to or greater than the RX\_CLK frequency.

Table 48. MII receive signal timing<sup>1</sup>

| Symbol | Characteristic                  | Value |     | Unit          |
|--------|---------------------------------|-------|-----|---------------|
|        |                                 | Min   | Max |               |
| M1     | RXD[3:0], RX_DV to RX_CLK setup | 5     | —   | ns            |
| M2     | RX_CLK to RXD[3:0], RX_DV hold  | 5     | —   | ns            |
| M3     | RX_CLK pulse width high         | 35%   | 65% | RX_CLK period |
| M4     | RX_CLK pulse width low          | 35%   | 65% | RX_CLK period |

1. All timing specifications valid to the pad input levels defined in [I/O pad current specifications](#).



**Figure 41. MII receive signal timing diagram**

### 3.13.10.2 MII transmit signal timing (TXD[3:0], TX\_EN, and TX\_CLK)

The transmitter functions correctly up to a TX\_CLK maximum frequency of 25 MHz +1%. There is no minimum frequency requirement. The system clock frequency must be at least equal to or greater than the TX\_CLK frequency.

The transmit outputs (TXD[3:0], TX\_EN) can be programmed to transition from either the rising or falling edge of TX\_CLK, and the timing is the same in either case. This options allows the use of noncompliant MII PHYs.

Refer to the *MPC5777C Microcontroller Reference Manual's* Fast Ethernet Controller (FEC) chapter for details of this option and how to enable it.

**Table 49. MII transmit signal timing<sup>1</sup>**

| Symbol | Characteristic                    | Value <sup>2</sup> |     | Unit          |
|--------|-----------------------------------|--------------------|-----|---------------|
|        |                                   | Min                | Max |               |
| M5     | TX_CLK to TXD[3:0], TX_EN invalid | 4.5                | —   | ns            |
| M6     | TX_CLK to TXD[3:0], TX_EN valid   | —                  | 25  | ns            |
| M7     | TX_CLK pulse width high           | 35%                | 65% | TX_CLK period |
| M8     | TX_CLK pulse width low            | 35%                | 65% | TX_CLK period |

1. All timing specifications valid to the pad input levels defined in [I/O pad specifications](#).

2. Output parameters are valid for  $C_L = 25$  pF, where  $C_L$  is the external load to the device. The internal package capacitance is accounted for, and does not need to be subtracted from the 25 pF value.

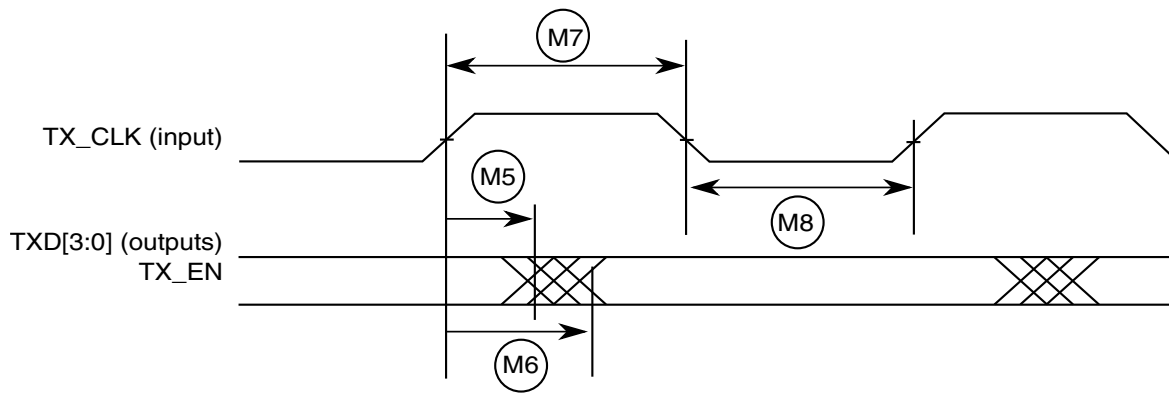


Figure 42. MII transmit signal timing diagram

### 3.13.10.3 MII async inputs signal timing (CRS)

Table 50. MII async inputs signal timing

| Symbol | Characteristic          | Value |     | Unit          |
|--------|-------------------------|-------|-----|---------------|
|        |                         | Min   | Max |               |
| M9     | CRS minimum pulse width | 1.5   | —   | TX_CLK period |



Figure 43. MII async inputs timing diagram

### 3.13.10.4 MII and RMI serial management channel timing (MDIO and MDC)

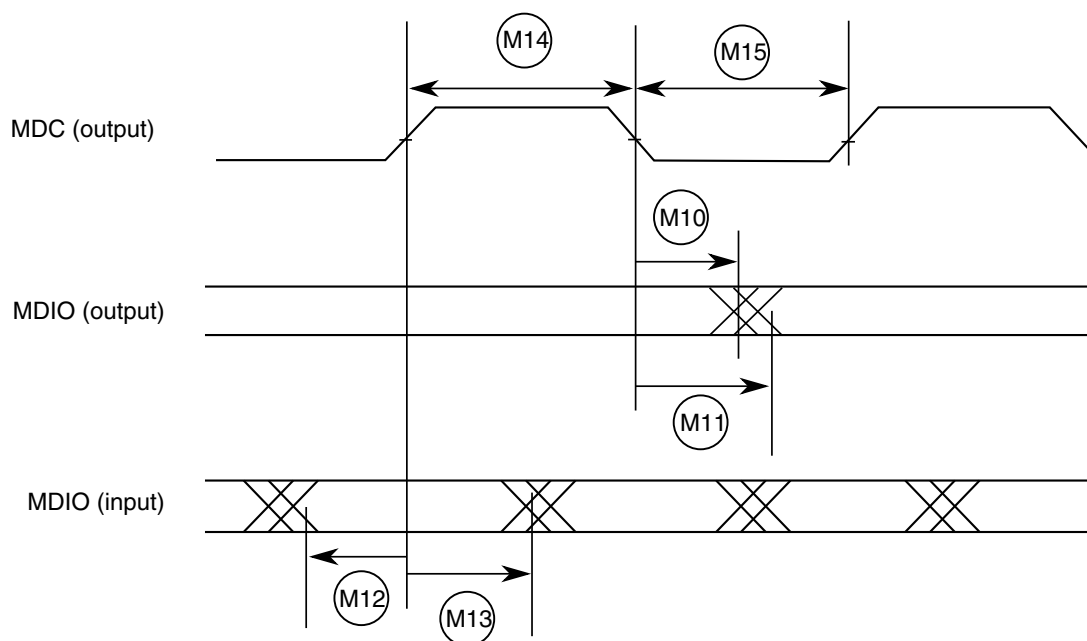
The FEC functions correctly with a maximum MDC frequency of 2.5 MHz.

Table 51. MII serial management channel timing<sup>1</sup>

| Symbol | Characteristic                                                      | Value <sup>2</sup> |     | Unit       |
|--------|---------------------------------------------------------------------|--------------------|-----|------------|
|        |                                                                     | Min                | Max |            |
| M10    | MDC falling edge to MDIO output invalid (minimum propagation delay) | 0                  | —   | ns         |
| M11    | MDC falling edge to MDIO output valid (max prop delay)              | —                  | 25  | ns         |
| M12    | MDIO (input) to MDC rising edge setup                               | 10                 | —   | ns         |
| M13    | MDIO (input) to MDC rising edge hold                                | 0                  | —   | ns         |
| M14    | MDC pulse width high                                                | 40%                | 60% | MDC period |
| M15    | MDC pulse width low                                                 | 40%                | 60% | MDC period |

1. All timing specifications valid to the pad input levels defined in [I/O pad specifications](#).

2. Output parameters are valid for  $C_L = 25$  pF, where  $C_L$  is the external load to the device. The internal package capacitance is accounted for, and does not need to be subtracted from the 25 pF value



**Figure 44. MII serial management channel timing diagram**

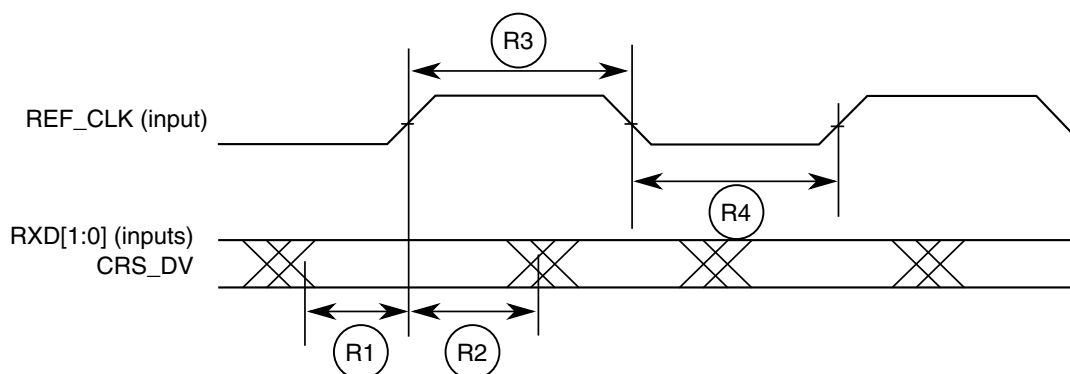
### 3.13.10.5 RMII receive signal timing (RXD[1:0], CRS\_DV)

The receiver functions correctly up to a REF\_CLK maximum frequency of 50 MHz +1%. There is no minimum frequency requirement. The system clock frequency must be at least equal to or greater than the RX\_CLK frequency, which is half that of the REF\_CLK frequency.

**Table 52. RMII receive signal timing<sup>1</sup>**

| Symbol | Characteristic                    | Value |     | Unit           |
|--------|-----------------------------------|-------|-----|----------------|
|        |                                   | Min   | Max |                |
| R1     | RXD[1:0], CRS_DV to REF_CLK setup | 4     | —   | ns             |
| R2     | REF_CLK to RXD[1:0], CRS_DV hold  | 2     | —   | ns             |
| R3     | REF_CLK pulse width high          | 35%   | 65% | REF_CLK period |
| R4     | REF_CLK pulse width low           | 35%   | 65% | REF_CLK period |

1. All timing specifications valid to the pad input levels defined in [I/O pad specifications](#).



**Figure 45. RMII receive signal timing diagram**

### 3.13.10.6 RMII transmit signal timing (TXD[1:0], TX\_EN)

The transmitter functions correctly up to a REF\_CLK maximum frequency of 50 MHz + 1%. There is no minimum frequency requirement. The system clock frequency must be at least equal to or greater than the TX\_CLK frequency, which is half that of the REF\_CLK frequency.

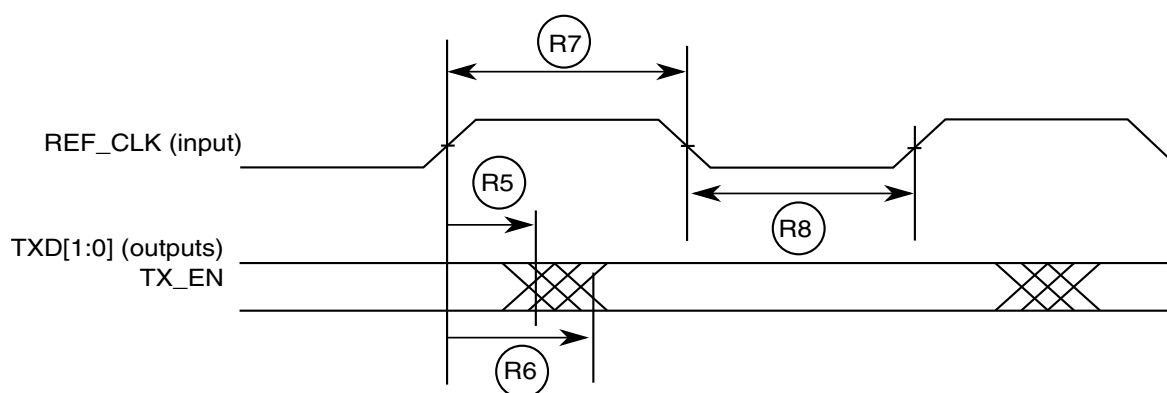
The transmit outputs (TXD[1:0], TX\_EN) can be programmed to transition from either the rising or falling edge of REF\_CLK, and the timing is the same in either case. This options allows the use of non-compliant RMII PHYs.

**Table 53. RMII transmit signal timing<sup>1</sup>**

| Symbol | Characteristic                     | Value <sup>2</sup> |     | Unit           |
|--------|------------------------------------|--------------------|-----|----------------|
|        |                                    | Min                | Max |                |
| R5     | REF_CLK to TXD[1:0], TX_EN invalid | 2                  | —   | ns             |
| R6     | REF_CLK to TXD[1:0], TX_EN valid   | —                  | 16  | ns             |
| R7     | REF_CLK pulse width high           | 35%                | 65% | REF_CLK period |
| R8     | REF_CLK pulse width low            | 35%                | 65% | REF_CLK period |

1. All timing specifications valid to the pad input levels defined in [I/O pad specifications](#).

2. Output parameters are valid for  $C_L = 25$  pF, where  $C_L$  is the external load to the device. The internal package capacitance is accounted for, and does not need to be subtracted from the 25 pF value.



**Figure 46. RMII transmit signal timing diagram**

## 4 Package information

To find the package drawing for each package, go to <http://www.nxp.com> and perform a keyword search for the drawing's document number:

| If you want the drawing for this package | Then use this document number |
|------------------------------------------|-------------------------------|
| 416-ball MAPBGA                          | 98ASA00562D                   |
| 516-ball MAPBGA                          | 98ASA00623D                   |

### 4.1 Thermal characteristics

**Table 54. Thermal characteristics, 416-ball MAPBGA package**

| Characteristic                                                                | Symbol           | Value | Unit |
|-------------------------------------------------------------------------------|------------------|-------|------|
| Junction to Ambient <sup>1,2</sup> Natural Convection (Single layer board)    | $R_{\theta JA}$  | 28.8  | °C/W |
| Junction to Ambient <sup>1,3</sup> Natural Convection (Four layer board 2s2p) | $R_{\theta JA}$  | 19.6  | °C/W |
| Junction to Ambient (@200 ft./min., Single layer board)                       | $R_{\theta JMA}$ | 21.3  | °C/W |
| Junction to Ambient (@200 ft./min., Four layer board 2s2p)                    | $R_{\theta JMA}$ | 15.1  | °C/W |
| Junction to Board <sup>4</sup>                                                | $R_{\theta JB}$  | 9.5   | °C/W |
| Junction to Case <sup>5</sup>                                                 | $R_{\theta JC}$  | 4.8   | °C/W |
| Junction to Package Top <sup>6</sup> Natural Convection                       | $\Psi_{JT}$      | 0.2   | °C/W |

1. Junction temperature is a function of on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
2. Per JEDEC JESD51-2 with the single layer board horizontal. Board meets JESD51-9 specification.
3. Per JEDEC JESD51-6 with the board horizontal.
4. Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
5. Indicates the average thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1) with the cold plate temperature used for the case temperature.

## Package information

- Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2.

**Table 55. Thermal characteristics, 516-ball MAPBGA package**

| Characteristic                                                                | Symbol           | Value | Unit |
|-------------------------------------------------------------------------------|------------------|-------|------|
| Junction to Ambient <sup>1,2</sup> Natural Convection (Single layer board)    | $R_{\Theta JA}$  | 28.5  | °C/W |
| Junction to Ambient <sup>1,3</sup> Natural Convection (Four layer board 2s2p) | $R_{\Theta JA}$  | 20.0  | °C/W |
| Junction to Ambient (@200 ft./min., Single layer board)                       | $R_{\Theta JMA}$ | 21.3  | °C/W |
| Junction to Ambient (@200 ft./min., Four layer board 2s2p)                    | $R_{\Theta JMA}$ | 15.5  | °C/W |
| Junction to Board <sup>4</sup>                                                | $R_{\Theta JB}$  | 8.8   | °C/W |
| Junction to Case <sup>5</sup>                                                 | $R_{\Theta JC}$  | 4.8   | °C/W |
| Junction to Package Top <sup>6</sup> Natural Convection                       | $\Psi_{JT}$      | 0.2   | °C/W |

- Junction temperature is a function of on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
- Per JEDEC JESD51-2 with the single layer board horizontal. Board meets JESD51-9 specification.
- Per JEDEC JESD51-6 with the board horizontal.
- Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
- Indicates the average thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1) with the cold plate temperature used for the case temperature.
- Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2.

### 4.1.1 General notes for thermal characteristics

An estimation of the chip junction temperature,  $T_J$ , can be obtained from the equation:

$$T_J = T_A + (R_{\Theta JA} * P_D)$$

where:

$T_A$  = ambient temperature for the package (°C)

$R_{\Theta JA}$  = junction-to-ambient thermal resistance (°C/W)

$P_D$  = power dissipation in the package (W)

The thermal resistance values used are based on the JEDEC JESD51 series of standards to provide consistent values for estimations and comparisons. The difference between the values determined for the single-layer (1s) board compared to a four-layer board that has two signal layers, a power and a ground plane (2s2p), demonstrate that the effective thermal resistance is not a constant. The thermal resistance depends on the:

- Construction of the application board (number of planes)
- Effective size of the board which cools the component

- Quality of the thermal and electrical connections to the planes
- Power dissipated by adjacent components

Connect all the ground and power balls to the respective planes with one via per ball. Using fewer vias to connect the package to the planes reduces the thermal performance. Thinner planes also reduce the thermal performance. When the clearance between the vias leave the planes virtually disconnected, the thermal performance is also greatly reduced.

As a general rule, the value obtained on a single-layer board is within the normal range for the tightly packed printed circuit board. The value obtained on a board with the internal planes is usually within the normal range if the application board has:

- One oz. (35 micron nominal thickness) internal planes
- Components are well separated
- Overall power dissipation on the board is less than 0.02 W/cm<sup>2</sup>

The thermal performance of any component depends on the power dissipation of the surrounding components. In addition, the ambient temperature varies widely within the application. For many natural convection and especially closed box applications, the board temperature at the perimeter (edge) of the package is approximately the same as the local air temperature near the device. Specifying the local ambient conditions explicitly as the board temperature provides a more precise description of the local ambient conditions that determine the temperature of the device.

At a known board temperature, the junction temperature is estimated using the following equation:

$$T_J = T_B + (R_{\theta JB} * P_D)$$

where:

$T_B$  = board temperature for the package perimeter (°C)

$R_{\theta JB}$  = junction-to-board thermal resistance (°C/W) per JESD51-8

$P_D$  = power dissipation in the package (W)

When the heat loss from the package case to the air does not factor into the calculation, the junction temperature is predictable if the application board is similar to the thermal test condition, with the component soldered to a board with internal planes.

The thermal resistance is expressed as the sum of a junction-to-case thermal resistance plus a case-to-ambient thermal resistance:

$$R_{\Theta JA} = R_{\Theta JC} + R_{\Theta CA}$$

where:

$R_{\Theta JA}$  = junction-to-ambient thermal resistance ( $^{\circ}\text{C}/\text{W}$ )

$R_{\Theta JC}$  = junction-to-case thermal resistance ( $^{\circ}\text{C}/\text{W}$ )

$R_{\Theta CA}$  = case to ambient thermal resistance ( $^{\circ}\text{C}/\text{W}$ )

$R_{\Theta JC}$  is device related and is not affected by other factors. The thermal environment can be controlled to change the case-to-ambient thermal resistance,  $R_{\Theta CA}$ . For example, change the air flow around the device, add a heat sink, change the mounting arrangement on the printed circuit board, or change the thermal dissipation on the printed circuit board surrounding the device. This description is most useful for packages with heat sinks where 90% of the heat flow is through the case to heat sink to ambient. For most packages, a better model is required.

A more accurate two-resistor thermal model can be constructed from the junction-to-board thermal resistance and the junction-to-case thermal resistance. The junction-to-case thermal resistance describes when using a heat sink or where a substantial amount of heat is dissipated from the top of the package. The junction-to-board thermal resistance describes the thermal performance when most of the heat is conducted to the printed circuit board. This model can be used to generate simple estimations and for computational fluid dynamics (CFD) thermal models. More accurate compact Flotherm models can be generated upon request.

To determine the junction temperature of the device in the application on a prototype board, use the thermal characterization parameter ( $\Psi_{JT}$ ) to determine the junction temperature by measuring the temperature at the top center of the package case using the following equation:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$

where:

$T_T$  = thermocouple temperature on top of the package ( $^{\circ}\text{C}$ )

$\Psi_{JT}$  = thermal characterization parameter ( $^{\circ}\text{C}/\text{W}$ )

$P_D$  = power dissipation in the package (W)

The thermal characterization parameter is measured in compliance with the JESD51-2 specification using a 40-gauge type T thermocouple epoxied to the top center of the package case. Position the thermocouple so that the thermocouple junction rests on the package. Place a small amount of epoxy on the thermocouple junction and approximately

1 mm of wire extending from the junction. Place the thermocouple wire flat against the package case to avoid measurement errors caused by the cooling effects of the thermocouple wire.

When board temperature is perfectly defined below the device, it is possible to use the thermal characterization parameter ( $\Psi_{JPB}$ ) to determine the junction temperature by measuring the temperature at the bottom center of the package case (exposed pad) using the following equation:

$$T_J = T_B + (\Psi_{JPB} \times P_D)$$

where:

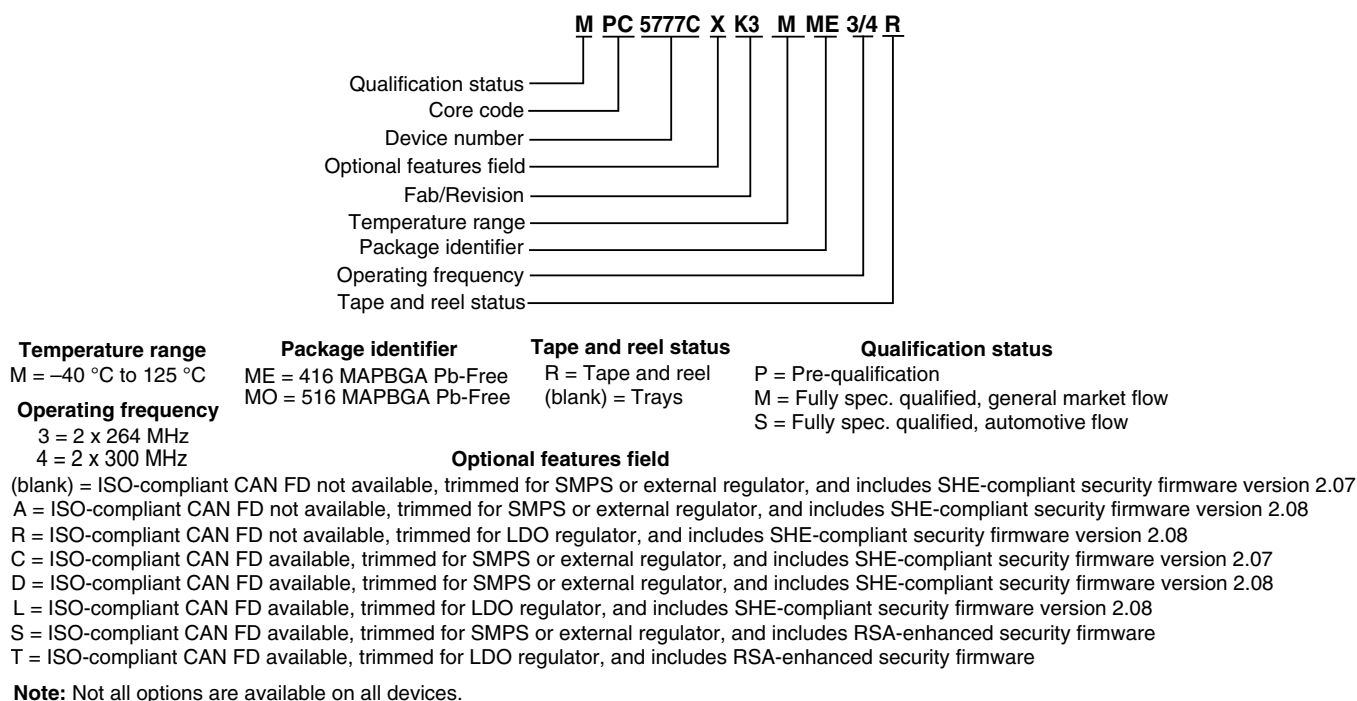
$T_T$  = thermocouple temperature on bottom of the package ( $^{\circ}\text{C}$ )

$\Psi_{JT}$  = thermal characterization parameter ( $^{\circ}\text{C}/\text{W}$ )

$P_D$  = power dissipation in the package (W)

## 5 Ordering information

Figure 47 and Table 56 describe orderable part numbers for the MPC5777C.



**Figure 47. MPC5777C Orderable part number description**

**Table 56. Example orderable part numbers**

| Part number <sup>1</sup> | Package description                         | Speed (MHz) <sup>2</sup> | Operating temperature <sup>3</sup> |                       |
|--------------------------|---------------------------------------------|--------------------------|------------------------------------|-----------------------|
|                          |                                             |                          | Min (T <sub>L</sub> )              | Max (T <sub>H</sub> ) |
| SPC5777CCK3MME3          | MPC5777C 416 package<br>Lead-free (Pb-free) | 264                      | –40 °C                             | 125 °C                |
| SPC5777CK3MME3           | MPC5777C 416 package<br>Lead-free (Pb-free) | 264                      | –40 °C                             | 125 °C                |
| SPC5777CCK3MMO3          | MPC5777C 516 package<br>Lead-free (Pb-free) | 264                      | –40 °C                             | 125 °C                |
| SPC5777CK3MMO3           | MPC5777C 516 package<br>Lead-free (Pb-free) | 264                      | –40 °C                             | 125 °C                |

1. All packaged devices are PPC5777C, rather than MPC5777C or SPC5777C, until product qualifications are complete. The unpackaged device prefix is PCC, rather than SCC, until product qualification is complete.

Not all configurations are available in the PPC parts.

2. For the operating mode frequency of various blocks on the device, see [Table 3](#).
3. The lowest ambient operating temperature is referenced by T<sub>L</sub>; the highest ambient operating temperature is referenced by T<sub>H</sub>.

## 6 Document revision history

The following table summarizes revisions to this document since the previous release.

**Table 57. Revision history**

| Revision | Date    | Description of changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
|----------|---------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 14       | 01/2020 | In <a href="#">Table 17</a> , updated the footnote from "TUE does not apply to differential conversions" to "TUE, Gain, and Offset specifications do not apply to differential conversions".<br>In <a href="#">Table 4</a> added Max value 120 µA for 40°C and 360 µA for 85°C for I <sub>STBY</sub> .                                                                                                                                                                                                                                                                                                                                                                                  |
| 13       | 08/2018 | In <a href="#">Table 3</a> , added information for 300 MHz frequency: <ul style="list-style-type: none"> <li>• f<sub>SYS</sub></li> <li>• f<sub>PLATF</sub></li> <li>• f<sub>ETPU</sub></li> <li>• f<sub>PER</sub></li> <li>• f<sub>FM_PER</sub></li> </ul> In <a href="#">Table 12</a> added Max value 240 MHz for f <sub>PLL0PHI</sub> and <a href="#">Table 13</a> added Max value 300 MHz for f <sub>PLL1PHI</sub> .<br>In <a href="#">Table 34</a> updated the row from "100 MHz > f <sub>PLATF</sub> ≤ 133 MHz" to "100 MHz > f <sub>PLATF</sub> ≤ 150 MHz" under "Flash memory frequency" column.<br>In <a href="#">Figure 47</a> added 300 MHz frequency orderable part number. |

*Table continues on the next page...*

**Table 57. Revision history (continued)**

| Revision | Date    | Description of changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                            |
|----------|---------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 12       | 08/2018 | <p>In <a href="#">Table 12 of PLL electrical specifications</a>, changed text of footnote 1:</p> <ul style="list-style-type: none"> <li>from: "f<sub>PLL0IN</sub> frequency must be scaled down using PLLDIG_PLL0DV[PREDIV] to ensure PFD input signal is in the range 8 MHz to 20 MHz."</li> <li>to: "Ensure that the f<sub>PLL0IN</sub> frequency divided by PLLDIG_PLL0DV[PREDIV] is in the range 8 MHz to 20 MHz."</li> </ul> <p>In <a href="#">Table 17 of Enhanced Queued Analog-to-Digital Converter (eQADC)</a>, added footnote about Max value of Conversion Cycles (CC): "128 sampling cycles (LST=128), differential conversion, pregain of x4"</p> <p>In <a href="#">Table 38 of External Bus Interface (EBI) timing</a>, changed text of footnote 1:</p> <ul style="list-style-type: none"> <li>from: "EBI timing specified at V<sub>DD</sub> = 1.08 V to 1.32 V, V<sub>DDE</sub> = 3.0 V to 3.6 V, T<sub>A</sub> = T<sub>L</sub> to T<sub>H</sub>, and C<sub>L</sub> = 30 pF with SIU_PCR[DSC] = 10b for ADDR/CTRL and SIU_PCR[DSC] = 11b for CLKOUT/DATA."</li> <li>to: "EBI timing specified at V<sub>DD</sub> = 1.08 V to 1.32 V, V<sub>DDE</sub> = 3.0 V to 3.6 V, T<sub>A</sub> = T<sub>L</sub> to T<sub>H</sub>, and C<sub>L</sub> = 30 pF with SIU_PCR[DSC] = 11b for ADDR/CTRL and SIU_PCR[SRC] = 11b for DATA/ALE."</li> </ul> <p>In <a href="#">I/O pad current specifications</a> added the text "The EBI power segments have.....segment does not exceed the spec".</p> |

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- Техническая поддержка проекта;
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#### Как с нами связаться

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